CHIP MONOLITHIC CERAMIC CAPACITOR

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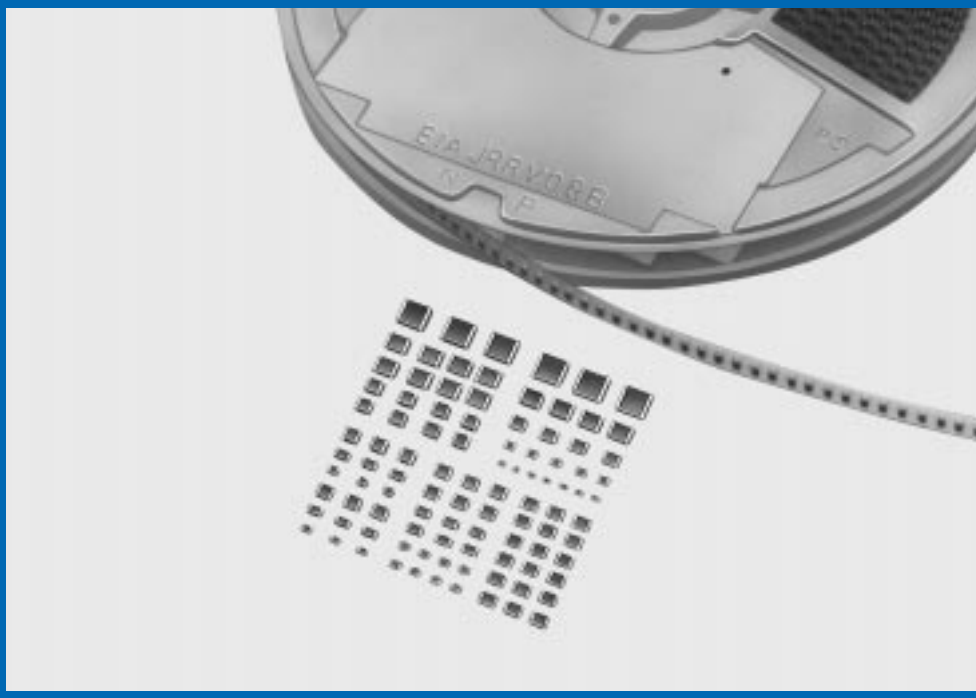


Innovator in Electronics

Murata
Manufacturing Co., Ltd.

Cat.No.C02E-6

CONTENTS

● Please refer to "Specifications and Test Methods" at the end of each chapter of 5 – 16 except for GRM series.

Part Numbering

(Please specify the part number when ordering.)

(Ex.) GRM40 C0G 151 J 50 [ ] PT — Murata's control no.

GHM3045 X7R 101 K - GC

Type ❶ ❷ ❸ ❹ ❺ Type ❶ ❷ ❸ ❻

❶Temperature Characteristic

• Temperature compensating type

Code	C0G	C0H	P2H	R2H	S2H	T2H	U2J	SL
Temp. range	−55 to 125℃		−55 to 85℃					
Temp. coeff. (ppm/ ℃)	0±30	0±60	−150±60	−220±60	−330±60	−470±60	−750±120	+350 to −1000

• High dielectric constant

Code	X7R	X5R	Z5U	Y5V	B	R
Temp. range	−55 to 125℃	−55 to 85℃	10 to 85℃	−30 to 85℃	−25 to 85℃	
Cap. change (%)	±15	±15	+22 −56	+22 −82	±10	±15

• High-Voltage/AC250V type/Safety std. Recognition

Code	SL	R/X7R	B
Temp. range	20 to 85℃	−55 to 125℃	−25 to 85℃
Cap. change	+350 to −1000ppm/℃	±15%	±10%

• For ultrasonic

code	ZLM	
Temp.range	−25 to 20℃	20 to 85℃
Temp. coeff. (ppm/℃)	−4700 +1000 −2500	−4700 +500 −1000

❷Capacitance

(Ex.)

Code	Capacitance (pF)
0R5	0.5
R75	0.75
010	1
100	10
101	100
103	10000

❸Capacitance Tolerance

Type	Temperature Characteristic	Code	Capacitance Tolerance		Capacitance Step
Temperature compensating type	C0G to U2J (NP0) (N750) and SL	C	≦10 pF	±0.25pF	0.5, 1, 1.5, 2, 3, 4, 5 (pF)
		D		±0.5pF	6, 7, 8, 9, 10 (pF)
		J	>10 pF	±5%	E12 series
High dielectric constant	X7R, X5R, B, R	K	±10%		E6 series
	Z5U	M	±20%		E6 series
	Z5U, Y5V	Z	+80, −20%		E3 series
High-Voltage/AC250V type/ Safety Standard Recognition	SL	D	≦10 pF	±0.5pF	10 (pF)
		J	> 10 pF	±5%	E12 series
	X7R, B, R	K	±10%		E6 series
	B	M	±20%		E3 series

❹Rated Voltage

Code	Rated voltage	Code	Rated voltage	Code	Rated voltage
6.3	DC6.3V	50	DC50V	3K	DC3.15kV
10	DC10V	250	DC250V	AC250	AC250V(r.m.s.)
16	DC16V	630	DC630V		
25	DC25V	2K	DC2kV		

Not apply to GHM3000 Series [Rated voltage : AC250V (r.m.s.)]

❺Packing Code (only for chip type)

Code	Packaging
PB	Bulk packaging in a bag
PT	Tape carrier packaging
PC	Bulk case packaging
PM	Bulk packaging in a tray

❻Type Designation (Apply to GHM3000 Series.)

Code	Type Designation
-GB	Type GB
-GC	Type GC

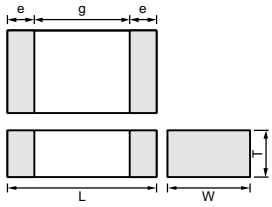
CHIP MONOLITHIC CERAMIC CAPACITOR

muRata

for Flow/Reflow Soldering GRM Series

■ Features

1. Terminations are made of metal highly resistant to migration.
2. The GRM series is a complete line of chip ceramic capacitors in 10V,16V,25V,50V,100V,200V and 500V ratings. These capacitors have temperature characteristics ranging from C0G to Y5V.
3. A wide selection of sizes is available, from the miniature GRM36(LxWxT:1.0x0.5x0.5mm) to GRM42-6 (LxWxT:3.2x1.6x1.25mm).
   GRM39, 40 and GRM42-6 types are suited to flow and reflow soldering.
   GRM36 types is applied to only reflow soldering.
4. Stringent dimensional tolerances allow highly reliable, high speed automatic chip placement on PCBs.
5. The GRM series is available in paper or plastic embossed tape and reel packaging for automatic placement. Bulk case packaging is also available for GRM36,GRM39,GRM40(T:0.6,1.25).



Part Number	Dimensions (mm)				
	L	W	T	e	g min.
GRM36	1.0 ±0.05	0.5 ±0.05	0.5 ±0.05	0.15 to 0.3	0.4
GRM39*	1.6 ±0.1	0.8 ±0.1	0.8 ±0.1	0.2 to 0.5	0.5
GRM40	2.0 ±0.1	1.25 ±0.1	0.6 ±0.1	0.2 to 0.7	0.7
			0.85 ±0.1		
			1.25 ±0.1		
GRM42-6	3.2 ±0.15	1.6 ±0.15	0.85 ±0.1	0.3 to 0.8	1.5
			1.15 ±0.1		
	3.2 ±0.2	1.6 ±0.2	1.6 ±0.2		

* Bulk Case : 1.6 ±0.07(L)×0.8 ±0.07(W)×0.8 ±0.07(T)

■ Application

General electronic equipment.

Temperature Compensating Type GRM36 Series

Part Number	GRM36								
L x W(mm)	1.00x0.50								
TC Code	C0G	C0H	P2H	R2H	S2H	SL		T2H	U2J
Rated Volt.(Vdc)	50	25	50	50	50	25	50	50	50
Capacitance and T(mm)									
0.5pF	0.50								
0.75pF	0.50								
1.0pF	0.50								
2.0pF	0.50								
3.0pF	0.50		0.50	0.50	0.50			0.50	0.50
4.0pF	0.50		0.50	0.50	0.50			0.50	0.50
5.0pF	0.50		0.50	0.50	0.50			0.50	0.50
6.0pF	0.50		0.50	0.50	0.50			0.50	0.50
7.0pF	0.50		0.50	0.50	0.50			0.50	0.50
8.0pF	0.50		0.50	0.50	0.50			0.50	0.50
9.0pF	0.50		0.50	0.50	0.50			0.50	0.50
10.0pF	0.50		0.50	0.50	0.50			0.50	0.50
12.0pF	0.50		0.50	0.50	0.50			0.50	0.50
15.0pF	0.50		0.50	0.50	0.50			0.50	0.50
18.0pF	0.50		0.50	0.50	0.50			0.50	0.50
22.0pF	0.50		0.50	0.50	0.50			0.50	0.50
27.0pF	0.50		0.50	0.50	0.50			0.50	0.50
33.0pF	0.50			0.50	0.50			0.50	0.50
39.0pF	0.50				0.50			0.50	0.50
47pF	0.50						0.50	0.50	0.50
56pF	0.50						0.50	0.50	0.50

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Part Number	GRM36								
L x W(mm)	1.00x0.50								
TC Code	C0G	C0H	P2H	R2H	S2H	SL		T2H	U2J
Rated Volt.(Vdc)	50	25	50	50	50	25	50	50	50
Capacitance and T(mm)									
68pF	0.50						0.50	0.50	0.50
82pF	0.50						0.50	0.50	0.50
100pF	0.50						0.50	0.50	0.50
120pF	0.50						0.50		0.50
150pF	0.50						0.50		0.50
180pF		0.50					0.50		0.50
220pF		0.50				0.50			
270pF		0.50				0.50			
330pF						0.50			
390pF						0.50			

Temperature Compensating Type GRM39 Series

Part Number	GRM39												
L x W(mm)	1.60x0.80												
TC Code	C0G			C0H	P2H	R2H	S2H	SL				T2H	U2J
Rated Volt.(Vdc)	50	100	200	25	50	50	50	25	50	100	200	50	50
Capacitance and T(mm)													
0.5pF	0.80												
1.0pF	0.80		0.80										
2.0pF	0.80		0.80										
3.0pF	0.80		0.80		0.80	0.80	0.80					0.80	0.80
4.0pF	0.80		0.80		0.80	0.80	0.80					0.80	0.80
5.0pF	0.80		0.80		0.80	0.80	0.80					0.80	0.80
6.0pF	0.80		0.80		0.80	0.80	0.80					0.80	0.80
7.0pF	0.80		0.80		0.80	0.80	0.80					0.80	0.80
8.0pF	0.80		0.80		0.80	0.80	0.80					0.80	0.80
9.0pF	0.80		0.80		0.80	0.80	0.80					0.80	0.80
10.0pF	0.80		0.80		0.80	0.80	0.80					0.80	0.80
12pF	0.80	0.80			0.80	0.80	0.80				0.80	0.80	0.80
15pF	0.80	0.80			0.80	0.80	0.80				0.80	0.80	0.80
18pF	0.80	0.80			0.80	0.80	0.80				0.80	0.80	0.80
22pF	0.80	0.80			0.80	0.80	0.80				0.80	0.80	0.80
27pF	0.80	0.80			0.80	0.80	0.80				0.80	0.80	0.80
33pF	0.80	0.80			0.80	0.80	0.80				0.80	0.80	0.80
39pF	0.80	0.80			0.80	0.80	0.80				0.80	0.80	0.80
47pF	0.80	0.80			0.80	0.80	0.80				0.80	0.80	0.80
56pF	0.80	0.80			0.80	0.80	0.80				0.80	0.80	0.80
68pF	0.80	0.80			0.80	0.80	0.80		0.80		0.80	0.80	0.80
82pF	0.80	0.80			0.80	0.80	0.80		0.80		0.80	0.80	0.80
100pF	0.80	0.80			0.80	0.80	0.80		0.80		0.80	0.80	0.80
120pF	0.80	0.80			0.80	0.80	0.80		0.80	0.80		0.80	0.80
150pF	0.80	0.80			0.80	0.80	0.80		0.80	0.80		0.80	0.80
180pF	0.80					0.80	0.80		0.80	0.80		0.80	0.80
220pF	0.80						0.80		0.80	0.80		0.80	0.80
270pF	0.80								0.80	0.80		0.80	0.80
330pF	0.80								0.80	0.80		0.80	0.80
390pF	0.80								0.80	0.80		0.80	0.80
470pF	0.80								0.80				0.80
560pF	0.80			0.80					0.80				0.80
680pF				0.80					0.80				0.80
820pF				0.80				0.80					
1000pF				0.80				0.80					

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Part Number	GRM39												
L x W(mm)	1.60x0.80												
TC Code	C0G			C0H	P2H	R2H	S2H	SL				T2H	U2J
Rated Volt.(Vdc)	50	100	200	25	50	50	50	25	50	100	200	50	50
Capacitance and T(mm)													
1200pF								0.80					
1500pF								0.80					

Temperature Compensating Type GRM40 Series

Part Number	GRM40												
L x W(mm)	2.00x1.25												
TC Code	C0G			C0H	P2H	R2H	S2H	SL				T2H	U2J
Rated Volt.(Vdc)	50	100	200	25	50	50	50	25	50	100	200	50	50
Capacitance and T(mm)													
12pF			0.85										
15pF			0.85										
18pF			0.85										
22pF			0.85										
27pF			0.85										
33pF			0.85										
39pF			0.85										
47pF			0.85										
56pF			0.85										
68pF		0.85	1.25										
82pF		0.85	1.25										
100pF		0.85	1.25										
120pF		0.85	1.25								0.85		
150pF		0.85	1.25								1.25		
180pF		0.85	1.25		0.85						1.25		
220pF		0.85	1.25		0.85	0.85					1.25		
270pF		0.85			0.85	0.85	0.85				1.25		
330pF		0.85			0.85	0.85	0.85				1.25		
390pF		1.25			1.25	0.85	0.85				1.25		
470pF		1.25			1.25	0.85	0.85			0.85	1.25		
560pF	0.60	1.25			1.25	1.25	1.25			0.85		1.25	
680pF	0.85	1.25				1.25	1.25			0.85		1.25	
820pF	0.85	1.25					1.25		0.60	1.25		1.25	0.60
1000pF	0.85	1.25							0.60	1.25		1.25	0.60
1200pF	0.85								0.60	1.25		1.25	0.60
1500pF	0.85								0.85	1.25		1.25	0.85
1800pF	1.25								0.85	1.25		1.25	0.85
2200pF	1.25								0.85				0.85
2700pF				1.25					1.25				1.25
3300pF				1.25					1.25				1.25
3900pF				1.25				0.85					
4700pF								0.85					
5600pF								1.25					
6800pF								1.25					

Temperature Compensating Type GRM42-6 Series

Part Number	GRM42-6														
L x W(mm)	3.20x1.60														
TC Code	C0G				C0H	P2H	R2H	S2H	SL					T2H	U2J
Rated Volt.(Vdc)	50	100	200	500	25	50	50	50	25	50	100	200	500	50	50
Capacitance and T(mm)															
1.0pF				1.15											
2.0pF				1.15											
3.0pF				1.15											
4.0pF				1.15											
5.0pF				1.15											
6.0pF				1.15											
7.0pF				1.15											
8.0pF				1.15											
9.0pF				1.15											
10.0pF				1.15											
12pF				1.15											
15pF				1.15											
18pF				1.15											
22pF				1.15											
27pF				1.15											
33pF				1.15											
39pF				1.15											
47pF				1.15											
56pF				1.15											
68pF				1.15											
82pF				1.15											
100pF				1.15											
120pF				1.15											
150pF													1.15		
180pF													1.15		
220pF													1.15		
270pF			1.15										1.15		
330pF			1.15												
390pF			1.15												
470pF			1.15												
560pF												1.15			
680pF						0.85						1.15			
820pF						0.85	0.85					1.15			
1000pF						1.15	1.15	0.85				1.15			
1200pF		1.15				1.15	1.15	1.15				1.15			
1500pF		1.15				1.15	1.15	1.15							
1800pF		1.15						1.15							
2200pF		1.15									1.15			1.15	
2700pF	0.85										1.15			1.15	
3300pF	0.85										1.15			1.15	
3900pF	1.15									0.85	1.15			1.15	0.85
4700pF	1.15									0.85	1.15				0.85
5600pF	1.15									0.85					0.85
6800pF					0.85					1.15					1.15
8200pF					1.15					1.15					1.15
10000pF					1.15				1.15						
12000pF									1.15						
15000pF									1.15						

High Dielectric Constant Type X5R GRM36/40/42-6 Series

TC Code	X5R						
Part Number	GRM36	GRM39	GRM40		GRM42-6		
L x W(mm)	1.00x0.50	1.60x0.80	2.00x1.25		3.20x1.60		
Rated Volt.(Vdc)	10	6.3	6.3	10	6.3	10	16
Capacitance and T(mm)							
33000pF	0.50						
47000pF	0.50						
68000pF	0.50						
0.1µF	0.50						
0.47µF		0.80					
1.0µF		0.80		0.85			
2.20µF			1.25				1.15
3.3µF						1.30	
4.7µF			1.25		1.60	1.60	
10.0µF					1.60		

4.7µF for 6.3V is replaced with GRM40-034 series of L:2±0.15, W:1.25±0.15, T:1.25±0.15.
T:1.25±0.1mm is also available for GRM40 10V 1.0µF type.
3.3µF for 10V rated is replaced with GRM42-631series of L:3.2±0.2, W:1.6±0.2, T:1.3+0/-.3mm.
T:1.15mm is also available for GRM42-6 16V 1.0µF type.
The torelance will be changed to L:3.2±0.2, W:1.6±0.2, T:1.15±0.15 for GRM42-6 16V 2.2µF type.

High Dielectric Constant Type X7R GRM36/39/40/42-6 Series

TC Code	X7R																
Part Number	GRM36				GRM39						GRM40			GRM42-6			
L x W(mm)	1.00x0.50				1.60x0.80						2.00x1.25			3.20x1.60			
Rated Volt.(Vdc)	10	16	25	50	10	16	25	50	100	200	16	25	50	10	16	25	50
Capacitance and T(mm)																	
220pF				0.50				0.80		0.80							
330pF				0.50				0.80		0.80							
470pF				0.50				0.80		0.80							
680pF				0.50				0.80		0.80							
1000pF				0.50				0.80		0.80							
1500pF				0.50				0.80		0.80							
2200pF				0.50				0.80	0.80								
3300pF				0.50				0.80	0.80								
4700pF				0.50				0.80									
6800pF			0.50					0.80									
10000pF			0.50					0.80									
15000pF		0.50						0.80									
22000pF		0.50						0.80									
33000pF	0.50						0.80						0.85				
47000pF	0.50						0.80						1.25				
68000pF							0.80										
0.10µF						0.80	0.80					1.25	1.25				
0.15µF					0.80							1.25	1.25				
0.22µF					0.80							0.85	1.25				1.15
0.33µF												1.25					0.85
0.47µF											0.85	1.25					1.15
0.68µF											0.85					0.85	
1.00µF											1.25			0.85	0.85	1.15	
1.5µF															1.15		
2.2µF														1.15	1.15		

0.10µF, 50V rated are GRM40-034 series of L:2±0.15, W:1.25±0.15, T:1.25±0.15.
T:1.25±0.1mm is also available for GRM42-6 1.0µF for 16V.
The torelance will be changed to L:3.2±0.2, W:1.6±0.2, T:1.15±0.15 for GRM42-6 16V 2.2µF type.

High Dielectric Constant Type Y5V GRM36/39/40/42-6 Series

TC Code	Y5V															
Part Number	GRM36			GRM39					GRM40				GRM42-6			
L x W(mm)	1.00x0.50			1.60x0.80					2.00x1.25				3.20x1.60			
Rated Volt.(Vdc)	16	25	50	10	16	25	50	100	10	16	25	50	6.3	10	16	25
Capacitance and T(mm)																
2200pF			0.50													
4700pF			0.50					0.80								
10000pF			0.50				0.80									
22000pF		0.50					0.80									
47000pF	0.50						0.80									
0.10µF	0.50					0.80						0.85				
0.22µF					0.80						0.85	1.25				
0.47µF				0.80	0.80						1.25					
1.0µF				0.80					0.85	0.85	0.85				0.85	1.15
1.5µF										1.25	1.25					
2.2µF									1.25	1.25	1.25			0.85	1.15	
4.7µF									1.25					1.15	1.15	
10.0µF													1.15	1.15		

T:1.25±0.1mm is also available for GRM40 16V 1.0µF type.

High Dielectric Constant Type Z5U GRM39/40/42-6 Series

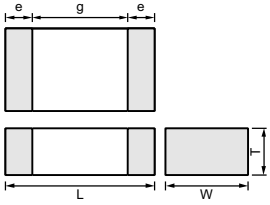
TC Code	Z5U							
Part Number	GRM39		GRM40			GRM42-6		
L x W(mm)	1.60x0.80		2.00x1.25			3.20x1.60		
Rated Volt.(Vdc)	50	100	50	100	200	50	100	200
Capacitance and T(mm)								
2200pF	0.80	0.80			1.25			
4700pF	0.80			0.85				1.15
10000pF	0.80			1.25				
22000pF			0.60				0.85	
47000pF			0.60					
0.10µF			0.85					
0.22µF						0.85		

CHIP MONOLITHIC CERAMIC CAPACITOR

for Reflow Soldering GRM Series

■ Features

1. Terminations are made of metal highly resistant to migration.
2. The GRM series is a complete line of chip ceramic capacitors in 25V,50V,100V,200V and 500V rated. These capacitors have temperature characteristics ranging from C0G to Y5V.
3. This series consists of type GRM42-2(LxWxT:3.2x2.5x 0.85mm) to type GRM44-1(LxWxT:5.7x5.0x2.0mm). These are suited to only reflow soldering.
4. Stringent dimensional tolerances allow highly reliable, high speed automatic chip placements on PCBs.
5. The GRM series is available in plastic embossed tape or paper taping and reel packaging for automatic placement.



Part Number	Dimensions (mm)				
	L	W	T	e min.	g min.
GRM42-2	3.2 ±0.3	2.5 ±0.2	0.85 ±0.1	0.3	1.0
			1.15 ±0.1		
			1.35 ±0.15		
			1.8 ±0.2		
			2.5 ±0.2		
GRM43-2	4.5 ±0.4	3.2 ±0.3	2.0 max.	0.3	2.0
GRM44-1	5.7 ±0.4	5.0 ±0.4	2.0 max.	0.3	2.0

■ Application

General electronic equipment.

Temperature Compensating Type GRM42-2 Series

Part Number	GRM42-2							
L x W(mm)	3.20x2.50							
TC Code	C0G				SL			
Rated Volt.(Vdc)	50	100	200	500	50	100	200	500
Capacitance and T(mm)								
150pF				1.35				
180pF				1.35				
330pF								1.15
390pF								1.15
470pF								1.35
560pF			1.35					
680pF			1.35					
820pF			1.35					
1000pF			1.35					
1500pF							1.35	
2700pF		1.35						
3300pF		1.35						
3900pF		1.35						
5600pF						1.35		
6800pF	1.35					1.35		
10000pF					1.35			
12000pF					1.35			

Temperature Compensating Type GRM43-2 Series

Part Number	GRM43-2							
L x W(mm)	4.50x3.20							
TC Code	C0G				SL			
Rated Volt.(Vdc)	50	100	200	500	50	100	200	500
Capacitance and T(mm)								
220pF				2.00				
270pF				2.00				
330pF				2.00				
390pF				2.00				
470pF				2.00				
560pF								2.00
680pF								2.00
820pF								2.00
1000pF								2.00
1200pF			2.00					2.00
1500pF			2.00					
1800pF			2.00				2.00	
2200pF			2.00				2.00	
2700pF			2.00				2.00	
3300pF							2.00	
3900pF							2.00	
4700pF		2.00						
5600pF		2.00						
6800pF		2.00						
8200pF	2.00	2.00				2.00		
10000pF	2.00	2.00				2.00		
12000pF	2.00	2.00				2.00		
15000pF					2.00	2.00		

Temperature Compensating Type GRM44-1 Series

Part Number	GRM44-1						
L x W(mm)	5.70x5.00						
TC Code	C0G				SL		
Rated Volt.(Vdc)	50	100	200	500	50	100	200
Capacitance and T(mm)							
560pF				2.00			
680pF				2.00			
820pF				2.00			
1000pF				2.00			
3300pF			2.00				
3900pF			2.00				
4700pF			2.00				2.00
5600pF			2.00				2.00
6800pF							2.00
8200pF							2.00
15000pF	2.00	2.00					
18000pF	2.00	2.00			2.00	2.00	
22000pF	2.00	2.00			2.00	2.00	
27000pF	2.00	2.00			2.00	2.00	
33000pF	2.00				2.00	2.00	
39000pF	2.00				2.00	2.00	

High Dielectric Constant Type GRM42-2 Series

Part Number	GRM42-2									
L x W(mm)	3.20x2.50									
TC Code	X5R	X7R					Y5V	Z5U		
Rated Volt.(Vdc)	10	16	25	50	100	200	50	50	100	200
Capacitance and T(mm)										
10000pF										1.15
15000pF										1.35
22000pF										1.35
33000pF						1.35				
47000pF						1.35			1.35	
68000pF					1.35				1.35	
0.10µF					1.35				1.35	
0.33µF								1.15		
0.47µF				1.15						
0.68µF				1.35						
1.00µF				1.80			1.8	1.80		
2.2µF		1.15	1.80							
3.3µF		1.35								
4.7µF		1.80								
10.0µF	2.50									

High Dielectric Constant Type GRM43-2 Series

Part Number	GRM43-2					
L x W(mm)	4.50x3.20					
TC Code	X7R			Z5U		
Rated Volt.(Vdc)	50	100	200	50	100	200
Capacitance and T(mm)						
33000pF						2.00
47000pF						2.00
68000pF			2.00			2.00
100000pF			2.00			2.00
0.15µF		2.00			2.00	
0.22µF		2.00			2.00	
0.33µF	2.00					
0.47µF	2.00			1.50		
0.68µF				1.50		
1.0µF				2.00		

High Dielectric Constant Type GRM44-1 Series

Part Number	GRM44-1					
L x W(mm)	5.70x5.00					
TC Code	X7R			Z5U		
Rated Volt.(Vdc)	50	100	200	50	100	200
Capacitance and T(mm)						
0.15µF			2.00			2.00
0.22µF			2.00			2.00
0.33µF		2.00			2.00	
0.47µF		2.00			2.00	
0.68µF	2.00				2.00	
1.0µF	2.00					
1.5µF	2.00			2.00		

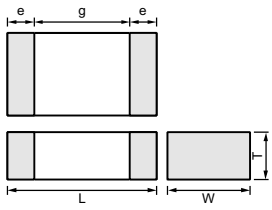
CHIP MONOLITHIC CERAMIC CAPACITOR

muRata

Ultra-small Type GRM33 Series

■ Features

1. Small chip size (LXWXT : 0.6X0.3X0.3mm).
2. Terminations are made of metal highly resistant to migration.
3. GRM33 type is suited to only reflow soldering.
4. Stringent dimensional tolerances are allow highly reliable, high speed autom atic chip placements on PCBs.
5. GRM33 series are suited to miniature micro wave module, portable equipment and high-frequency circuit.



Part Number	Dimensions (mm)				
	L	W	T	e	g min.
GRM33	0.6 ±0.03	0.3 ±0.03	0.3 ±0.03	0.1 to 0.2	0.2

■ Application

•Miniature micro wave module.
•Portable equipment.
•High-frequency circuit.

Part Number	GRM33		
L x W(mm)	0.6x0.3		
TC Code	C0G	X7R	Y5V
Rated Volt.(Vdc)	25	16	10
Capacitance and T(mm)			
0.5pF	0.3		
1pF	0.3		
2pF	0.3		
3pF	0.3		
4pF	0.3		
5pF	0.3		
6pF	0.3		
7pF	0.3		
8pF	0.3		
9pF	0.3		
10pF	0.3		
12pF	0.3		
15pF	0.3		
18pF	0.3		
22pF	0.3		
27pF	0.3		
33pF	0.3		
39pF	0.3		
47pF	0.3		
56pF	0.3		
68pF	0.3		
82pF	0.3		
100pF	0.3	0.3	
150pF		0.3	
220pF		0.3	
330pF		0.3	
470pF		0.3	
680pF		0.3	
1000pF		0.3	
2200pF			0.3

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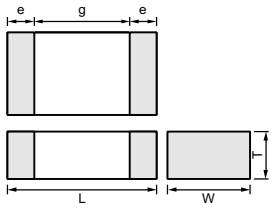
Part Number	GRM33		
L x W(mm)	0.6x0.3		
TC Code	C0G	X7R	Y5V
Rated Volt.(Vdc)	25	16	10
Capacitance and T(mm)			
4700pF			0.3
10000pF			0.3

CHIP MONOLITHIC CERAMIC CAPACITOR

Thin Type for Flow/Reflow GRM Series

■ Features

1. This series is suited to flow and reflow soldering. Capacitor terminations are made of metal highly resistant to migration.
2. Large capacitance values enable excellent bypass effects to be realized.
3. Its thin package makes this series ideally suited for the production of small electronic products and for mounting underneath ICs.



Part Number	Dimensions (mm)				
	L	W	T	e	g min.
GRM36-019	1.0 ±0.05	0.5 ±0.05	0.25 ±0.05	0.15 to 0.3	0.4

■ Application

Thin equipment such as IC cards.

Part Number	GRM36-019	
L x W(mm)	1.00x0.50	
TC Code	C0G	
Rated Volt.(Vdc)	25	50
Capacitance and T(mm)		
1pF		0.25
2pF		0.25
3pF		0.25
4pF		0.25
5pF		0.25
6pF		0.25
7pF		0.25
8pF		0.25
9pF		0.25
10pF		0.25
12pF		0.25
15pF		0.25
18pF		0.25
22pF		0.25
27pF		0.25
33pF		0.25
39pF		0.25
47pF		0.25
56pF		0.25
68pF		0.25
82pF		0.25
100pF		0.25
120pF	0.25	
150pF	0.25	
180pF	0.25	
220pF	0.25	

GRM Series Specifications and Test Methods

No.	Item		Specification		Test Method
			Temperature Compensating Type	High Dielectric Type	
1	Operating Temperature		−55 to +125℃	X5R : −55 to +85℃ X7R : −55 to +125℃ Z5U : +10 to +85℃ Y5V : −30 to +85℃	
2	Rated Voltage		See the previous page.		The rated voltage is defined as the maximum voltage which may be applied continuously to the capacitor. When AC voltage is superimposed on DC voltage, V^{P-P} or V^{O-P}, whichever is larger, shall be maintained within the rated voltage range.
3	Appearance		No defects or abnormalities.		Visual inspection.
4	Dimensions		Within the specified dimensions.		Using calipers on micrometer.
5	Dielectric Strength		No defects or abnormalities.		No failure shall be observed when *300% of the rated voltage (C0Δ to U2J and SL) or *250% of the rated voltage (X5R, X7R, Z5U and Y5V) is applied between the terminations for 1 to 5 seconds, provided the charge/discharge current is less than 50mA. *200% for 500V
6	Insulation Resistance		More than 10,000MΩ or 500Ω • F (Whichever is smaller)		The insulation resistance shall be measured with a DC voltage not exceeding the rated voltage at 25℃ and 75%RH max. and within 2 minutes of charging.
7	Capacitance		Within the specified tolerance.		The capacitance/Q/D.F. shall be measured at 25℃ at the frequency and voltage shown in the table.
8	Q/ Dissipation Factor (D.F.)		30pFmin. : Q≧1000 30pFmax. : Q≧400+20C C : Nominal Capacitance (pF)	[X5R,X7R] W.V. : 25Vmin. : 0.025max. W.V. : 16/10V : 0.035max. W.V. : 6.3V 0.05max.(C<3.3μF) 0.1max.(C≧3.3μF) [Z5U] W.V. : 25Vmin. : 0.025max. [Y5V] W.V. : 25Vmin. : 0.05max.(C<10μF) : 0.09max.(C≧1.0μF) W.V. : 16V : 0.07max.(C<1.0μF) : 0.09max.(C≧1.0μF) W.V. : 10Vmax. : 0.125max.	
9	Capacitance Temperature Characteristics	Capacitance Change	Within the specified tolerance. (Table A)	X5R : Within±15% (−55 to +85℃) X7R : Within±15% (−55 to +125℃) Z5U : Within +22/−56% (+10 to +85℃) Y5V : Within +22/−82% (−30 to +85℃)	The capacitance change shall be measured after 5 Min. at each specified temperature stage. (1) Temperature Compensating Type The temperature coefficient is determined using the Capacitance measured in step 3 as a reference. When cycling the temperature sequentially from step 1 through 5 (C0Δ : +25℃ to +125℃ : other temp. coeffs. : +25℃ to +85℃) the capacitance shall be within the specified tolerance for the temperature coefficient and capacitance change as Table A. The capacitance drift is caluculated by dividing the differences between the maximum and minimum measured values in the step 1,3 and 5 by the cap value in step 3.
		Temperature Coefficient	Within the specified tolerance. (Table A)	——	
		Capacitance Drift	Within ±0.2% or ±0.05pF (Whichever is larger.) *Not apply to SL/25V	——	

Item \ Char.	Frequency	Voltage
C0Δ toU2J,SL (1000pF and below)	1±0.1MHz	0.5 to 5Vrms
C0Δ toU2J,SL (more than 1000pF)	1±0.1kHz	1±0.2Vrms
X5R,X7R,Y5V (10μF and below)	1±0.1kHz	1±0.2Vrms
X5R,X7R,Y5V (more than 10μF)	120±24Hz	0.5±0.1Vrms
Z5U	1±0.1kHz	0.5±0.05Vrms

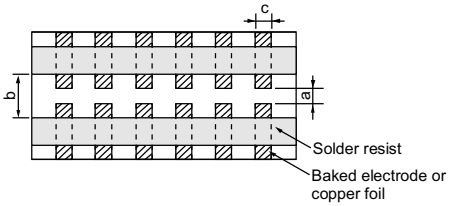
Step	Temperature(℃)
1	25±2
2	−55±3 (for CΔ to U2J/SL/X5R/X7R) −30±3 (for Y5V) 10±3 (for Z5U)
3	25±2
4	125±3 (for CΔ/X7R) 85±3 (for other TC)
5	25±2

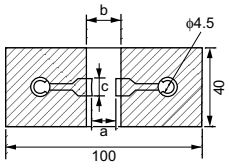
(2) High Dielectric Constant Type
The ranges of capacitance change compared with the above 25℃ value over the temperature ranges shown in the table shall be within the specified ranges.

Continued on the following page.

GRM Series Specifications and Test Methods

Continued from the preceding page.

<table>
<tr><th rowspan="2">No.</th><th rowspan="2" colspan="2">Item</th><th colspan="2">Specification</th><th rowspan="2">Test Method</th></tr>
<tr><th>Temperature Compensating Type</th><th>High Dielectric Type</th></tr>
<tr><td>10</td><td colspan="2">Adhesive Strength of Termination</td><td colspan="2">No removal of the terminations or other defect shall occur.</td><td>Solder the capacitor to the test jig (glass epoxy board) shown in Fig.1 using a eutectic solder. Then apply 10N* force in parallel with the test jig for 10±1sec. The soldering shall be done either with an iron or using the reflow method and shall be conducted with care so that the soldering is uniform and gree of defects such as heat shock. *2N (GRM33) 5N (GRM36,GRM39)
 

<table>
<tr><th>Type</th><th>a</th><th>b</th><th>c</th></tr>
<tr><td>GRM33</td><td>0.3</td><td>0.9</td><td>0.3</td></tr>
<tr><td>GRM36</td><td>0.4</td><td>1.5</td><td>0.5</td></tr>
<tr><td>GRM39</td><td>1.0</td><td>3.0</td><td>1.2</td></tr>
<tr><td>GRM40</td><td>1.2</td><td>4.0</td><td>1.65</td></tr>
<tr><td>GRM42-6</td><td>2.2</td><td>5.0</td><td>2.0</td></tr>
<tr><td>GRM42-2</td><td>2.2</td><td>5.0</td><td>2.9</td></tr>
<tr><td>GRM43-2</td><td>3.5</td><td>7.0</td><td>3.7</td></tr>
<tr><td>GRM44-1</td><td>4.5</td><td>8.0</td><td>5.6</td></tr>
</table>
(in mm)
Fig.1</td></tr>
<tr><td rowspan="3">11</td><td rowspan="3">Vibration Resistance</td><td>Appearance</td><td colspan="2">No defects or abnormalities.</td><td rowspan="3">Solder the capacitor to the test jig (glass epoxy board) in the same manner and under the same conditions as (10). The capacitor shall be subjected to a simple harmonic motion having a total amplitude of 1.5mm, the frequency being varied uniformly between the approximate limits of 10 and 55Hz. The frequency range, from 10 to 55Hz and return to 10Hz, shall be traversed in approximately 1 minute. This motion shall be applied for a period of 2 hours in each 3 mutually perpendicular directions (total of 6 hours).</td></tr>
<tr><td>Capacitance</td><td colspan="2">Within the specified tolerance.</td></tr>
<tr><td>Q/D.F.</td><td>30pFmin. : Q≧1000
30pFmax. : Q≧400+20C
C : Nominal Capacitance (pF)</td><td>[X5R,X7R]
W.V. : 25Vmin. : 0.025max.
W.V. : 16/10V : 0.035max.
W.V. : 6.3V :
0.05max. (C<3.3μF)
0.1max. (C≧3.3μF)
[Z5U]
W.V. : 25Vmin. : 0.025max.
[Y5V]
W.V. : 25Vmin.
: 0.05max. (C<1.0μF)
: 0.09max. (C≧1.0μF)
W.V. : 16V
: 0.07max. (C<1.0μF)
: 0.09max. (C≧1.0μF)
W.V. : 10Vmax.:0.125max.</td></tr>
<tr><td>12</td><td colspan="2">Deflection</td><td colspan="2">No crack or marked defect shall occur.
 

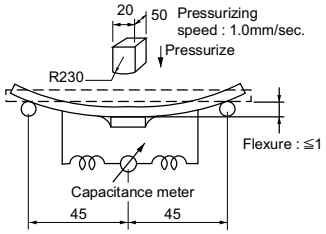
t : 1.6mm (GRM33/36 : 0.8mm)
<table>
<tr><th>Type</th><th>a</th><th>b</th><th>c</th></tr>
<tr><td>GRM33</td><td>0.3</td><td>0.9</td><td>0.3</td></tr>
<tr><td>GRM36</td><td>0.4</td><td>1.5</td><td>0.5</td></tr>
<tr><td>GRM39</td><td>1.0</td><td>3.0</td><td>1.2</td></tr>
<tr><td>GRM40</td><td>1.2</td><td>4.0</td><td>1.65</td></tr>
<tr><td>GRM42-6</td><td>2.2</td><td>5.0</td><td>2.0</td></tr>
<tr><td>GRM42-2</td><td>2.2</td><td>5.0</td><td>2.9</td></tr>
<tr><td>GRM43-2</td><td>3.5</td><td>7.0</td><td>3.7</td></tr>
<tr><td>GRM44-1</td><td>4.5</td><td>8.0</td><td>5.6</td></tr>
</table>
(in mm)
Fig.2</td><td>Solder the capacitor on the test jig (glass epoxy board) shown in Fig.2 using a eutectic solder. Then apply a force in the direction shown in Fig. 3. The soldering shall be done either with an iron or using the reflow method and shall be conducted with care so that the soldering is uniform and free of defects such as heat shock.
 

Fig.3</td></tr>
</table>

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GRM Series Specifications and Test Methods

Continued from the preceding page.

No.	Item		Specification: Temperature Compensating Type	Specification: High Dielectric Type	Test Method
13	Solderability of Termination		75% of the terminations is to be soldered evenly and continuously.		Immerse the capacitor in a solution of ethanol (JIS-K-8101) and rosin (JIS-K-5902) (25% rosin in weight propotion). Preheat at 80 to 120℃ for 10 to 30 seconds. After preheating, immerse in eutectic solder solution for 2±0.5 seconds at 230±5℃.
14	Resistance to Soldering Heat		The measured and observed characteristics shall satisfy the specifications in the following table.		Preheat the capacitor at 120 to 150℃ for 1 minute. Immerse the capacitor in a eutectic solder solution at 270±5℃ for 10±0.5 seconds. Let sit at room temperature for 24±2 hours (temperature compensating type) or 48±4 hours (high dielectric constant type), then measure. •Initial measurement for high dielectric constant type Perform a heat treatment at 150 $^{+0}_{-10}$℃ for one hour and then let sit for 48±4 hours at room temperature. Perform the initial measurement. *Preheating for GRM42-2/43-2/44-1 Step 1: 100℃ to 120℃, 1 min. Step 2: 170℃ to 200℃, 1 min.
		Appearance	No marking defects.		
		Capacitance Change	Within ±2.5% or ±0.25pF (Whichever is larger)	X5R,X7R : Within ±7.5% Z5U,Y5V : Within ±20%	
		Q/D.F.	30pFmin. : Q≧1000 30pFmax. : Q≧400+20C C : Nominal Capacitance (pF)	[X5R,X7R] W.V. : 25Vmin. : 0.025max. W.V. : 16/10V : 0.035max. W.V. : 6.3V : 0.05max. (C<3.3μF) 0.1max. (C≧3.3μF) [Z5U] W.V. : 25Vmin. : 0.025max. [Y5V] W.V. : 25Vmin. : 0.05max. (C<1.0μF) : 0.09max. (C≧1.0μF) W.V.:16V : 0.07max. (C<1.0μF) : 0.09max. (C≧1.0μF) W.V. : 10Vmax. : 0.125max.	
		I.R.	More than 10,000MΩ or 500Ω • F (Whichever is smaller)		
		Dielectric Strength	No failure		
15	Temperature Cycle		The measured and observed characteristics shall safisfy the specifications in the following table.		Fix the capacitor to the supporting jig in the same manner and under the same conditions as (10). Perform the five cycles according to the four heat treatments listed in the following table. Let sit for 24±2 hours (temperature compensating type) or 48±4 hour (high dielectric constant type) at room temperature, then measure. Step 1: Min. Operating Temp.+0/−3, 30±3 Step 2: Room Temp., 2 to 3 Step 3: Max. Operating Temp.+3/−0, 30±3 Step 4: Room Temp., 2 to 3 •Initial measurement for high dielectric constant type Perform a heat treatment at 150 $^{+0}_{-10}$℃ for one hour and then let sit for 48±4 hours at room temperature. Perform the initial measurement.
		Appearance	No marking defects.		
		Capacitance Change	Within ±2.5% or ±0.25pF (Whichever is larger)	X5R,X7R : Within ±7.5% Z5U,Y5V : Within ±20%	
		Q/D.F.	30pFmin. : Q≧1000 30pFmax. : Q≧400+20C C : Nominal Capacitance (pF)	[X5R,X7R] W.V. : 25Vmin. : 0.025max. W.V. : 16/10V : 0.035max. W.V. : 6.3V 0.05max. (C<3.3μF) 0.1max. (C≧3.3μF) [Z5U] W.V. : 2.5Vmin. : 0.025max. [Y5V] W.V. : 25Vmin. : 0.05max. (C<1.0μF) : 0.09max. (C≧1.0μF) W.V. : 16V : 0.07max. (C<1.0μF) : 0.09max. (C≧1.0μF) W.V. : 10Vmax. : 0.125max.	
		I.R.	More than 10,000MΩ or 500Ω • F (Whichever is smaller)		
		Dielectric Strength	No failure		

Continued on the following page.

GRM Series Specifications and Test Methods

Continued from the preceding page.

No.	Item		Specification		Test Method
			Temperature Compensating Type	High Dielectric Type	
16	Humidity Steady State		The measured and observed characteristics shall satisfy the specifications in the following table.		Sit the capacitor at 40±2℃ and 90 to 95% humiduty for 500±12 hours. Remove and let sit for 24±2 hours (temperature compensating type) or 48±4 hours (high dielectric constant type) at room temperature, then measure.
		Appearance	No marking defects.		
		Capacitance Change	Within ±5% or ±0.5pF (Whichever is larger)	X5R,X7R : Within ±12.5% Z5U,Y5V : Within ±30%	
		Q/D.F.	30pF and over : Q≧350 10pF and over 30pF and below : Q≧275+5C/2 10pF and below : Q≧200+10C C : Nominal Capacitance (pF)	[X5R,X7R] W.V. : 25Vmin. : 0.05max. W.V. : 16/10V : 0.05max. W.V. : 6.3V 0.075max. (C<3.3μF) 0.125max. (C≧3.3μF) [Z5U] W.V. : 25Vmin. : 0.05max. [Y5V] W.V. : 25Vmin. : 0.075max. (C<1.0μF) : 0.0125max.(C≧1.0μF) W.V. : 16V : 0.1max. (C<1.0μF) : 0.125max. (C≧1.0μF) W.V. : 10Vmax. : 0.15max.	
		I.R.	More than 1,000MΩ or 50Ω • F(Whichever is smaller)		
		Dielectric Strength	No failure		
17	Humidity Load		The measured and observed characteristics shall satisfy the specifications in the following table.		Apply the rated voltage at 40±2℃ and 90 to 95% humidity for 500±12 hours. Remove and let sit for 24±2 hours (temperature compensating type) or 48±4 hours (high dielectric constant type) at room temperature, then muasure.The charge/discharge current is less than 50mA. •Initial measurement for Y5V/10Vmax. Apply the rated DC voltage for 1 hour at 40±2℃. Remove and let sit for 48±4 hours at room temperature. Perform initial measurement.
		Appearance	No marking defects.		
		Capacitance Change	Within ±7.5% or ±0.75pF (Whichever is larger)	X5R,X7R : Within ±12.5% Z5U : Within ±30% Y5V : Within ±30% [W.V. : 10Vmax.] Y5V : Within +30/−40%	
		Q/D.F.	30pF and over : Q≧200 30pF and below : Q≧100±10C/3 C : Nominal Capacitance (pF)	[X5R,X7R] W.V. : 25Vmin. : 0.05max. W.V. : 16/10V : 0.05max. W.V. : 6.3V 0.075max. (C<3.3μF) 0.125max. (C≧3.3μF) [Z5U] W.V. : 25Vmin. : 0.05max. [Y5V] W.V. : 25Vmin. : 0.075max. (C<1.0μF) : 0.0125max. (C≧1.0μF) W.V. : 16V : 0.1max. (C<1.0μF) : 0.125max. (C≧1.0μF) W.V. : 10Vmax. : 0.15max.	
		I.R.	More than 500MΩ or 25Ω • F(Whichever is smaller)		
		Dielectric Strength	No failure		

Continued on the following page.

GRM Series Specifications and Test Methods

Continued from the preceding page.

No.	Item		Specification		Test Method
			Temperature Compensating Type	High Dielectric Type	
18	High Temperature Load		The measured and observed characteristics shall satisfy the specifications in the following table.		Apply 200% of the rated voltage for 1000±12 hours at the maximun operating temperature ±3℃. Let sit for 24±2 hours (temperature compensating type) or 48±4 hours (high dielectric constant type) at room temperature, then measure. The charge/discharge current is less than 50mA. •Initial measurement for high dielectric constant type. Apply 200% of the rated DC voltage for one hour at the maximun operating temperature ±3℃. Remove and let sit for 48±4 hours at room temperature. Perform initial measurement. ∗150% for 500V and C≧10μF
		Appearance	No marking defects.		
		Capacitance Change	Within ±3% or ±0.3pF (Whichever is larger)	X5R,X7R : Within ±12.5% Z5U : Within ±30% Y5V : Within ±30% (Cap<1.0μF) Y5V : Within +30/−40%(Cap≧1.0μF)	
		Q/D.F.	30pF and over : Q≧350 10pF and over 30pF and below : Q≧275±5C/2 10pF and below : Q≧200±10C C : Nominal Capacitance (pF)	[X5R,X7R] W.V. : 25Vmin. : 0.05max. W.V. : 16/10V : 0.05max. W.V. : 6.3V 0.075max. (C<3.3μF) 0.125max. (C≧3.3μF) [Z5U] W.V. : 25Vmin. : 0.05max [Y5V] W.V. : 25Vmin. : 0.075max. (C<1.0μF) : 0.0125max.(C≧1.0μF) W.V. : 16V : 0.1max. (C<1.0μF) : 0.125max. (C≧1.0μF) W.V. : 10Vmax. : 0.15max.	
		I.R.	More than 1,000MΩ or 50Ω•F(Whichever is smaller)		
		Dielectric Strength	No failure		
19	Notice		When mounting capacitor of 500V rated voltage, perform the epoxy resin coating(min.1.0mm thickness)		

Table A

Char.	Nominal Values (ppm/℃)*	Capacitance Change from 25℃ (%)					
		−55		−30		−10	
		Max.	Min.	Max.	Min.	Max.	Min.
C0G	0± 30	0.58	−0.24	0.40	−0.17	0.25	−0.11
C0H	0± 60	0.87	−0.48	0.59	−0.33	0.38	−0.21
P2H	−150± 60	2.33	0.72	1.61	0.50	1.02	0.32
R2H	−220± 60	3.02	1.28	2.08	0.88	1.32	0.56
S2H	−330± 60	4.09	2.16	2.81	1.49	1.79	0.95
T2H	−470± 60	5.46	3.28	3.75	2.26	2.39	1.44
U2J	−750±120	8.78	5.04	6.04	3.47	3.84	2.21
SL	+350 to −1000	—	—	—	—	—	—

∗Nominal values denote the temperature coefficient within a range of 25℃ to 125℃ (for CoΔ)/85℃ (for other TC).

CHIP MONOLITHIC CERAMIC CAPACITOR

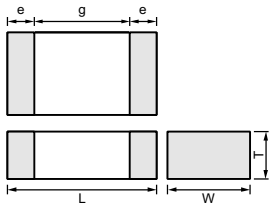
High-power Type GRM600 Series

■ Features

1. Mobile Telecommunication and RF module, mainly.
2. Quality improvement of telephone call, Low power Consumption, yield ratio improvement.

■ Application

VCO, PA, Mobile Telecommunication



Part Number	Dimensions (mm)				
	L	W	T	e	g min.
GRM615	1.0 ±0.05	0.5 ±0.05	0.5 ±0.05	0.15 to 0.3	0.4

5

Part Number	Rated Voltage (Vdc)	TC Code	Capacitance (pF)	Length L (mm)	Width W (mm)	Thickness T (mm)
GRM615C0G010B50	50	C0G	1.0 –0.1pF	1.00	0.50	0.50
GRM615C0G010C50	50	C0G	1.0 –0.25pF	1.00	0.50	0.50
GRM615C0G020B50	50	C0G	2.0 –0.1pF	1.00	0.50	0.50
GRM615C0G020C50	50	C0G	2.0 –0.25pF	1.00	0.50	0.50
GRM615C0G030B50	50	C0G	3.0 –0.1pF	1.00	0.50	0.50
GRM615C0G030C50	50	C0G	3.0 –0.25pF	1.00	0.50	0.50
GRM615C0G040B50	50	C0G	4.0 –0.1pF	1.00	0.50	0.50
GRM615C0G040C50	50	C0G	4.0 –0.25pF	1.00	0.50	0.50
GRM615C0G050B50	50	C0G	5.0 –0.1pF	1.00	0.50	0.50
GRM615C0G050C50	50	C0G	5.0 –0.25pF	1.00	0.50	0.50
GRM615C0G060C50	50	C0G	6.0 –0.25pF	1.00	0.50	0.50
GRM615C0G060D50	50	C0G	6.0 –0.5pF	1.00	0.50	0.50
GRM615C0G070C50	50	C0G	7.0 –0.25pF	1.00	0.50	0.50
GRM615C0G070D50	50	C0G	7.0 –0.5pF	1.00	0.50	0.50
GRM615C0G080C50	50	C0G	8.0 –0.25pF	1.00	0.50	0.50
GRM615C0G080D50	50	C0G	8.0 –0.5pF	1.00	0.50	0.50
GRM615C0G090C50	50	C0G	9.0 –0.25pF	1.00	0.50	0.50
GRM615C0G090D50	50	C0G	9.0 –0.5pF	1.00	0.50	0.50
GRM615C0G0R5B50	50	C0G	0.5 –0.1pF	1.00	0.50	0.50
GRM615C0G0R5C50	50	C0G	0.50 –0.25pF	1.00	0.50	0.50
GRM615C0G100C50	50	C0G	10 –0.25pF	1.00	0.50	0.50
GRM615C0G100D50	50	C0G	10.0 –0.5pF	1.00	0.50	0.50
GRM615C0G110G50	50	C0G	11 –2%	1.00	0.50	0.50
GRM615C0G120G50	50	C0G	12 –2%	1.00	0.50	0.50
GRM615C0G120J50	50	C0G	12 –5%	1.00	0.50	0.50
GRM615C0G130G50	50	C0G	13 –2%	1.00	0.50	0.50
GRM615C0G150G50	50	C0G	15 –2%	1.00	0.50	0.50
GRM615C0G150J50	50	C0G	15 –5%	1.00	0.50	0.50
GRM615C0G160G50	50	C0G	16 –2%	1.00	0.50	0.50
GRM615C0G180G50	50	C0G	18 –2%	1.00	0.50	0.50
GRM615C0G180J50	50	C0G	18 –5%	1.00	0.50	0.50
GRM615C0G1R1B50	50	C0G	1.1 –0.1pF	1.00	0.50	0.50
GRM615C0G1R2B50	50	C0G	1.2 –0.1pF	1.00	0.50	0.50
GRM615C0G1R3B50	50	C0G	1.3 –0.1pF	1.00	0.50	0.50
GRM615C0G1R5B50	50	C0G	1.5 –0.1pF	1.00	0.50	0.50
GRM615C0G1R5C50	50	C0G	1.5 –0.25pF	1.00	0.50	0.50
GRM615C0G1R6B50	50	C0G	1.6 –0.1pF	1.00	0.50	0.50
GRM615C0G1R8B50	50	C0G	1.8 –0.1pF	1.00	0.50	0.50

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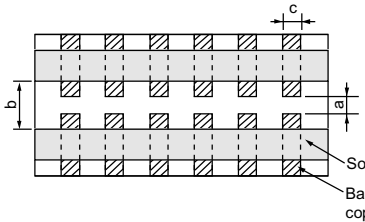
Part Number	Rated Voltage (Vdc)	TC Code	Capacitance (pF)	Length L (mm)	Width W (mm)	Thickness T (mm)
GRM615C0G200G50	50	C0G	20 –2%	1.00	0.50	0.50
GRM615C0G2R2B50	50	C0G	2.2 –0.1pF	1.00	0.50	0.50
GRM615C0G2R4B50	50	C0G	2.4 –0.1pF	1.00	0.50	0.50
GRM615C0G2R7B50	50	C0G	2.7 –0.1pF	1.00	0.50	0.50
GRM615C0G3R3B50	50	C0G	3.3 –0.1pF	1.00	0.50	0.50
GRM615C0G3R6B50	50	C0G	3.6 –0.1pF	1.00	0.50	0.50
GRM615C0G3R9B50	50	C0G	3.9 –0.1pF	1.00	0.50	0.50
GRM615C0G4R3B50	50	C0G	4.3 –0.1pF	1.00	0.50	0.50
GRM615C0G4R7B50	50	C0G	4.7 –0.1pF	1.00	0.50	0.50
GRM615C0G5R1C50	50	C0G	5.1 –0.25pF	1.00	0.50	0.50
GRM615C0G5R6C50	50	C0G	5.6 –0.25pF	1.00	0.50	0.50
GRM615C0G6R2C50	50	C0G	6.2 –0.25pF	1.00	0.50	0.50
GRM615C0G6R8C50	50	C0G	6.8 –0.25pF	1.00	0.50	0.50
GRM615C0G7R5C50	50	C0G	7.5 –0.25pF	1.00	0.50	0.50
GRM615C0G8R2C50	50	C0G	8.2 –0.25pF	1.00	0.50	0.50
GRM615C0G9R1C50	50	C0G	9.1 –0.25pF	1.00	0.50	0.50

Specifications and Test Methods

No.	Item		Specification: Temperature Compensating Type	Test Method
1	Operating Temperature Range		−55 to +125℃	
2	Rated Voltage		See the previous pages.	The rated voltage is defined as the maximum voltage which may be applied continuously to the capacitor. When AC voltage is superimposed on DC voltage, V^{P-P} or V^{O-P}, whichever is larger, shall be maintained within the rated voltage range.
3	Appearance		No defects or abnormalities.	Visual inspection.
4	Dimensions		Within the specified dimensions.	Using calipers.
5	Dielectric Strength		No defects or abnormalities.	No failure shall be observed when 300% of the rated voltage is applied between the terminations for 1 to 5 seconds, provided the charge/discharge current is less than 50mA.
6	Insulation Resistance (I.R.)		10,000MΩ min. or 500Ω • F min. (Whichever is smaller)	The insulation resistance shall be measured with a DC voltage not exceeding the rated voltage at 25℃ and 75%RH max. and within 2 minutes of charging.
7	Capacitance		Within the specified tolerance.	The capacitance/Q shall be measured at 25℃ at the frequency and voltage shown in the table.
8	Q		30pF min. : Q≧1,000 30pF max. : Q≧400+20C C : Nominal Capacitance (pF)	
9	Capacitance Temperature Characteristics	Capacitance Change	Within the specified tolerance. (Table A-1)	The capacitance change shall be measured after 5 min. at each specified temperature stage. Temperature Compensating Type The temperature coefficient is determined using the capacitance measured in step 3 as a reference. When cycling the temperature sequentially from step 1 through 5, (C0G : +25℃ to+125℃ : other temp. coeffs. : +25℃ to 85℃) the capacitance shall be within the specified tolerance for the temperature coefficient and capacitance change as Table A. The capacitance drift is calculated by dividing the differences between the maximum and minimum measured values in the step 1, 3 and 5 by the cap value in step 3.
		Temperature Coefficent	Within the specified tolerance. (Table A-1)	
		Capacitance Drift	Within ±0.2% or ±0.05pF (Whichever is larger.)	
10	Adhesive Strength of Termination		No removal of the terminations or other defect shall occur.	Solder the capacitor to the test jig (glass epoxy board) shown in Fig.1 using a eutectic solder. Then apply a 5N force in parallel with the test jig for 10±1sec. The soldering shall be done either with an iron or using the reflow method and shall be conducted with care so that the soldering is uniform and free of defects such as heat shock.

Item \ Char.	C0G(1000pF and below)
Frequency	1±0.1MHz
Voltage	0.5 to 5Vr.m.s.

Step	Temperature(℃)
1	25±2
2	−55±3
3	25±2
4	125±3
5	25±2



Type	a	b	c
GRM615	0.4	1.5	0.5

(in mm)

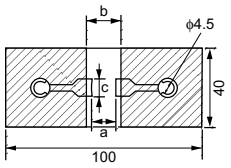
Fig.1

Continued on the following page.

Specifications and Test Methods

Continued from the preceding page.

No.	Item		Specification Temperature Compensating Type	Test Method
11	Vibration Resistance	Appearance	No defects or abnormalities.	Solder the capacitor to the test jig (glass epoxy board) in the same manner and under the same conditions as (10). The capacitor shall be subjected to a simple harmonic motion having a total amplitude of 1.5mm, the frequency being varied uniformly between the approximate limits of 10 and 55Hz. The frequency range, from 10 to 55Hz and return to 10Hz, shall be traversed in approximately 1 minute. This motion shall be applied for a period of 2 hours in each 3 mutually perpendicular directions (total of 6 hours).
		Capacitance	Within the specified tolerance.	
		Q	30pF min. : Q≧1,000 30pF max. : Q≧400+20C C : Nominal Capacitance (pF)	
12	Deflection		No cracking or marking defects shall occur.	Solder the capacitor to the test jig (glass epoxy boards) shown in Fig.2 using a eutectic solder. Then apply a force in the direction shown in Fig.3. The soldering shall be done either with an iron or using the reflow method and shall be conducted with care so that the soldering is uniform and free of defects such as heat shock..
13	Solderability of Termination		75% of the terminations is to be soldered evenly and continuously.	Immerse the capacitor in a solution of ethanol (JIS-K-8101) and rosin (JIS-K-5902) (25% rosin in weight proportion). Preheat at 80 to 120℃ for 10 to 30 seconds. After preheating, immerse in eutectic solder solution for 2±0.5 seconds at 230±5℃.
14	Resistance to Soldering Heat		The measured and observed characteristics shall satisfy the specifications in the following table.	Preheat the capacitor at 120 to 150℃ for 1 minute. Immerse the capacitor in a eutectic solder solution at 270±5℃ for 10±0.5 seconds. Let sit at room temperature for 24±2 hours.
		Appearance	No marking defects.	
		Capacitance Change	Within ±2.5% or ±0.25pF (Whichever is larger)	
		Q	30pF and over : Q≧1,000 30pF and below : Q≧400+20C C : Nominal Capacitance (pF)	
		I.R.	More than 10,000MΩ or 500Ω • F (Whichever is smaller)	
		Dielectric Strength	No failure	
15	Temperature Cycle		The measured and observed characteristics shall satisfy the specifications in the following table.	Fix the capacitor to the supporting jig in the same manner and under the same conditions as (10). Perform the five cycles according to the four heat treatments listed in the following table. Let sit for 24±2 hours at room temperature, then measure.
		Appearance	No marking defects.	
		Capacitance Change	Within ±2.5% or ±0.25pF (Whichever is larger)	
		Q	30pF and over : Q≧1,000 30pF and below : Q≧400+20C C : Nominal Capacitance (pF)	
		I.R.	More than 10,000MΩ or 500Ω • F (Whichever is smaller)	
		Dielectric Strength	No failure	
16	Humidity, Steady State		The measured and observed characteristics shall satisfy the specifications in the following table.	Sit the capacitor at 40±2℃ and 90 to 95% humidity for 500±12 hours. Remove and let sit for 24±2 hours (temperature compensating type) at room temperature, then measure.
		Appearance	No marking defects.	
		Capacitance Change	Within ±5% or ±0.5pF (Whichever is larger)	
		Q	30pF and over. : Q≧350 10pF and over, 30pF and below : Q≧275+ $\frac{5}{2}$C 10pF and below : Q≧200+10C C : Nominal Capacitance (pF)	
		I.R.	More than 10,000MΩ or 500Ω • F (Whichever is smaller)	



Type	a	b	c
GRM615	0.4	1.5	0.5

(in mm)

Fig.2

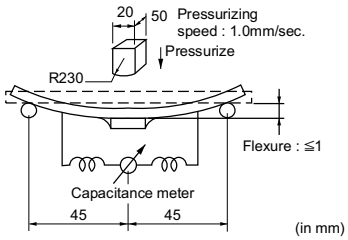


Fig.3

Step	1	2	3	4
Temp.(℃)	Min. Operating Temp. $^{+0}_{-3}$	Room Temp.	Max. Operating Temp. $^{+3}_{-0}$	Room Temp.
Time(min.)	30±3	2 to 3	30±3	2 to 3

Continued on the following page.

Specifications and Test Methods

Continued from the preceding page.

No.	Item		Specification Temperature Compensating Type	Test Method
17	Humidity Load		The measured and observed characteristics shall satisfy the specifications in the following table.	Apply the rated voltage at 40±2℃ and 90 to 95% humidity for 500±12 hours. Remove and let sit for 24±2 hours at room temperature, then measure. The charge/discharge current is less than 50mA.
		Appearance	No marking defects.	
		Capacitance Change	Within ±7.5% or ±0.75pF (Whichever is larger)	
		Q	30pF and over : Q≧200 30pF and below : Q≧100+ $\frac{10}{3}$ C C : Nominal Capacitance (pF)	
		I.R.	More than 500MΩ or 25Ω • F (Whichever is smaller)	
		Dielectric Strength	No failure	
18	High Temperature Load		The measured and observed characteristics shall satisfy the specifications in the following table.	Apply 200% of the rated voltage for 1000±12 hours at the maximum operating temperature ±3℃. Let sit for 24±2 hours (temperature compensating type) at room temperature, then measure. The charge/discharge current is less than 50mA.
		Appearance	No marking defects.	
		Capacitance Change	Within ±3% or ±0.3pF (Whichever is larger)	
		Q	30pF and over. : Q≧350 10pF and over, 30pF and below : Q≧275+ $\frac{5}{2}$ C 10pF and below : Q≧200+10C C : Nominal Capacitance (pF)	
		I.R.	More than 1,000MΩ or 50Ω • F (Whichever is smaller)	
		Dielectric Strength	No failure	
19	ESR		0.5pF≦C≦1pF : 350MΩ . pF below 1pF<C≦5pF : 300MΩ below 5pF<C≦10pF : 250MΩ below	The ESR shall be measured at room Temp. and frequency 1±0.2GHz with the equivalent of BOONTON Model 34A.
			10pF<C≦20pF : 400MΩ below	The ESR shall be measured at room Temp. and frequency 500±50MHz with the equivalent of HP8753B.

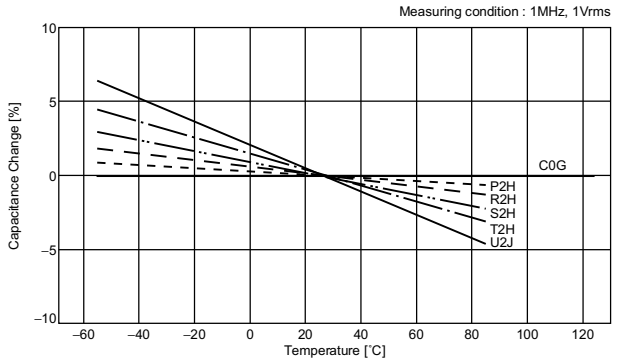
Table A

Char.	Temp. Coeff. (ppm/℃) Note 1	Capacitance Change from 25℃ Value (%)					
		−55℃		−30℃		−10℃	
		Max.	Min.	Max.	Min.	Max.	Min.
C0G	0±30	0.58	−0.24	0.40	−0.17	0.25	−0.11

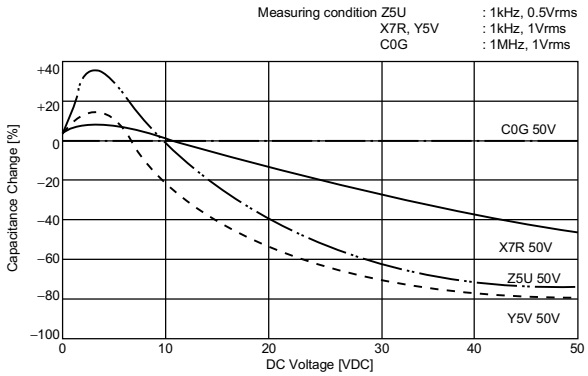
Note 1 : Nominal values denote the temperature coefficient within a range of 25 to 125℃.(for C0Δ)

GRM Series Data

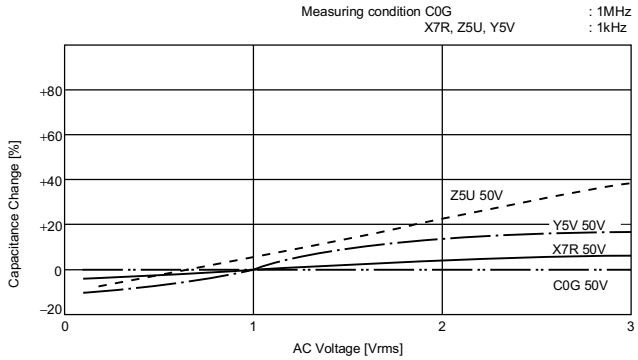
■ Capacitance-Temperature Characterstics



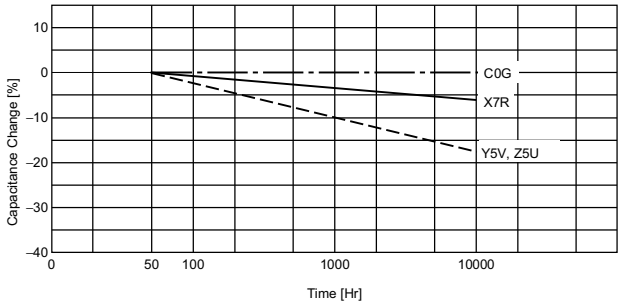
■ Capcitance-DC Voltage Characteristics



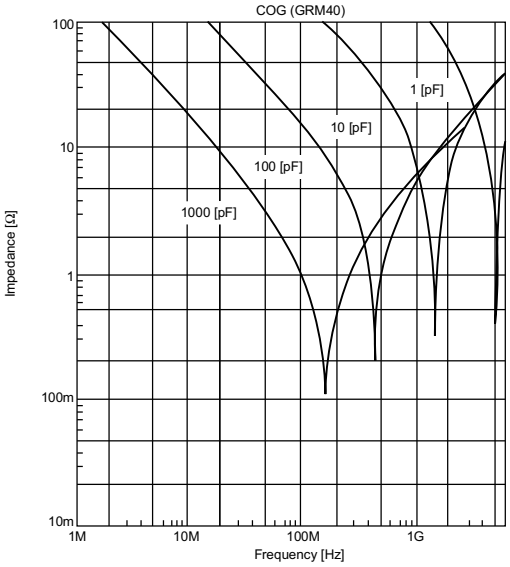
■ Capcitance-AC Voltage Characteristics



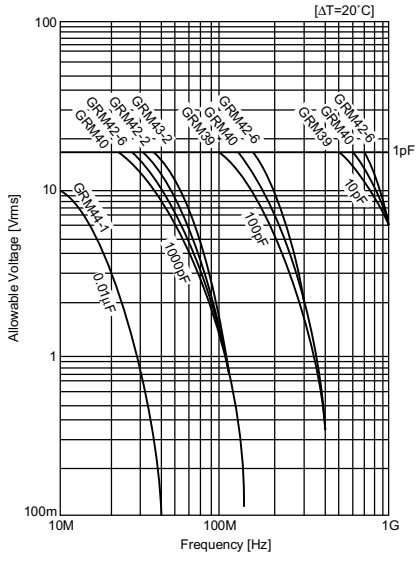
■ Capacitance Change-Aging



■ Impedance-Frequency Characteristics



■ Allowable Voltage-Frequency



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GRM Series Data

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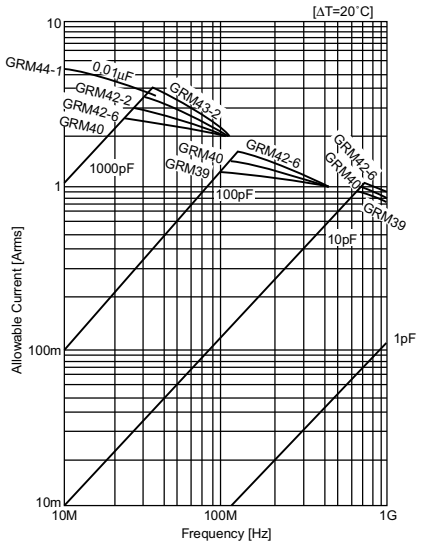
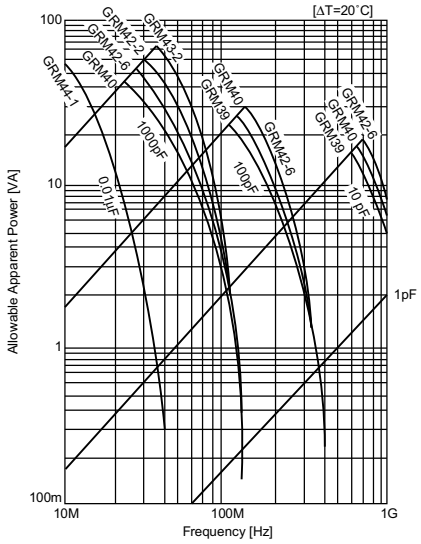
■ Allowable Current-Frequency



■ Allowable Appearant Power



CHIP MONOLITHIC CERAMIC CAPACITOR

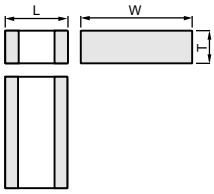
Low ESL Wide-width Type LL Series

■ Features

1. Low ESL, good for noise reduction for high frequency.
2. Small, high cap.

■ Application

• High speed micro processor.
• High frequency digital equipment



Part Number	Dimensions (mm)		
	L	W	T
LL0306	0.8 ±0.1	1.6 ±0.1	0.6 max.
LL0508	1.25 ±0.1	2.0 ±0.1	0.6 ±0.1
			0.85 ±0.1
LL0612	1.6 ±0.15	3.2 ±0.15	0.7 ±0.1
			1.15 ±0.1

LL0306 Series

Part Number	LL0306							
L x W(mm)	0.8x1.6							
TC Code	X7R				Y5V		Z5U	
Rated Volt.(Vdc)	10	16	25	50	16	50	25	50
Capacitance and T(mm)								
2200pF				0.6				
2700pF				0.6				
3300pF				0.6				
3900pF				0.6				
4700pF				0.6				
5600pF				0.6				
6800pF			0.6					
8200pF			0.6					
10000pF			0.6					0.6
12000pF			0.6					
15000pF			0.6			0.6	0.6	
18000pF			0.6					
22000pF			0.6			0.6	0.6	
27000pF		0.6						
33000pF		0.6			0.6			
39000pF		0.6						
47000pF		0.6			0.6			
56000pF		0.6						
68000pF		0.6			0.6			
82000pF	0.6							
0.1µF	0.6							

LL0508 Series

Part Number	LL0508								
L x W(mm)	1.25x2.0								
TC Code	X7R				Y5V			Z5U	
Rated Volt.(Vdc)	10	16	25	50	16	25	50	25	50
Capacitance and T(mm)									
0.15pF								0.85	
0.22pF	0.6								
4700pF				0.6					

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Part Number	LL0508								
L x W(mm)	1.25x2.0								
TC Code	X7R				Y5V			Z5U	
Rated Volt.(Vdc)	10	16	25	50	16	25	50	25	50
Capacitance and T(mm)									
5600pF				0.6					
6800pF				0.6					
8200pF				0.6					
10000pF				0.6					
12000pF				0.6					
15000pF				0.6					
18000pF				0.6					
22000pF				0.6					
27000pF			0.6	0.85					
33000pF		0.6	0.6	0.85					0.6
39000pF		0.6	0.6	0.85					
47000pF		0.6	0.6					0.6	0.85
56000pF		0.6	0.6						
68000pF		0.6	0.6				0.6	0.6	0.85
82000pF		0.6	0.6						
0.1µF		0.6	0.6			0.6	0.85	0.85	
0.12µF		0.6							
0.15µF		0.6	0.85		0.6	0.85		0.85	
0.18µF		0.6							
0.22µF		0.85			0.6				
0.27µF	0.6								
0.33µF	0.6				0.85				
0.39µF	0.85								
0.47µF	0.85								
0.56µF	0.85								

LL0612 Series

Part Number	LL0612								
L x W(mm)	1.6x3.2								
TC Code	X7R				Y5V			Z5U	
Rated Volt.(Vdc)	10	16	25	50	16	25	50	25	50
Capacitance and T(mm)									
10000pF				0.7					
12000pF				0.7					
15000pF				0.7					
18000pF				0.7					
22000pF				0.7					
27000pF				0.7					
33000pF				0.7					
39000pF				0.7					
47000pF				0.7					
56000pF				0.7					
68000pF				0.7					
82000pF			0.7	1.15					
0.1µF		0.7	0.7	1.15					0.7
0.12µF		0.7	0.7	1.15					
0.15µF		0.7	0.7					0.7	1.15
0.18µF		0.7	0.7						
0.22µF		0.7	1.15				0.7	0.7	1.15
0.27µF		0.7	1.15						
0.33µF		0.7	1.15				1.15	1.15	
0.39µF		0.7							

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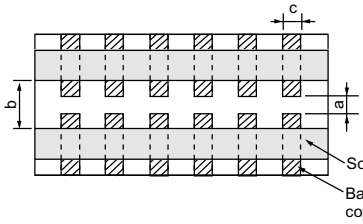
Part Number	LL0612								
L x W(mm)	1.6x3.2								
TC Code	X7R				Y5V			Z5U	
Rated Volt.(Vdc)	10	16	25	50	16	25	50	25	50
Capacitance and T(mm)									
0.47µF		0.7	1.15		0.7	1.15		1.15	
0.56µF	0.7	1.15							
0.68µF	0.7	1.15			0.7				
0.82µF	0.7	1.15							
1000000pF	0.7	1.15			1.15				
1.2µF	1.15								
1.5µF	1.15								
1.8µF	1.15								
2.2µF	1.15								

6

Specifications and Test Methods

<table>
<tr><th>No.</th><th>Item</th><th></th><th>Specification</th><th>Test Method</th></tr>
<tr><td>1</td><td>Operating Temperature Range</td><td></td><td>X7R : −55℃ to +125℃
Z5U : +10℃ to +85℃
Y5V : −30℃ to +85℃</td><td></td></tr>
<tr><td>2</td><td>Rated Voltage</td><td></td><td>See the previous pages.</td><td>The rated voltage is defined as the maximum voltage which may be applied continuously to the capacitor.
When AC voltage is superimposed on DC voltage, V_{P-P} or V_{O-P}, whichever is larger, shall be maintained within the rated voltage range.</td></tr>
<tr><td>3</td><td>Appearance</td><td></td><td>No defects or abnormalities.</td><td>Visual inspection.</td></tr>
<tr><td>4</td><td>Dimensions</td><td></td><td>Within the specified dimension.</td><td>Using calipers.</td></tr>
<tr><td>5</td><td>Dielectric Strength</td><td></td><td>No defects or abnormalities.</td><td>No failure shall be observed when 250% of the rated voltage is applied between the terminations for 1 to 5 seconds, provided the charge/discharge current is less than 50mA.</td></tr>
<tr><td>6</td><td>Insulation Resistance (I.R.)</td><td></td><td>More than 10,000MΩ or 500Ω • F (Whichever is smaller)</td><td>The insulation resistance shall be measured with a DC voltage not exceeding the rated voltage at 25℃ and 75%RH max. and within 2 minutes of charging.</td></tr>
<tr><td>7</td><td>Capacitance</td><td></td><td>Within the specified tolerance.</td><td rowspan="2">The capacitance/D.F. shall be measured at 25℃ at the frequency and voltage shown in the table.
<table><tr><th></th><th>X7R · Y5V</th><th>Z5U</th></tr><tr><td>Frequency</td><td>1±0.1kHz</td><td>1±0.1kHz</td></tr><tr><td>Voltage</td><td>1±0.2Vr.m.s.</td><td>0.5±0.05Vr.m.s.</td></tr></table></td></tr>
<tr><td>8</td><td>Dissipation Factor (D.F.)</td><td></td><td><table><tr><th>Char.</th><th>25V min.</th><th>16V</th></tr><tr><td>X7R</td><td>0.025 max.</td><td>0.035 max.</td></tr><tr><td>Z5U</td><td>0.025 max.</td><td>—</td></tr><tr><td rowspan="2">Y5V</td><td rowspan="2">0.05 max.</td><td>0.07 max. (C<1.0μF)</td></tr><tr><td>0.09 max. (C≧1.0μF)</td></tr></table></td></tr>
<tr><td>9</td><td>Capacitance Temperature Characteristics</td><td></td><td><table><tr><th>Char.</th><th>Temp. Range (℃)</th><th>Reference Temp.</th><th>Cap. Change.</th></tr><tr><td>X7R</td><td>−55 to +125</td><td rowspan="3">25℃</td><td>Within±15%</td></tr><tr><td>Z5U</td><td>+10 to +85</td><td>Within+22%/−56%</td></tr><tr><td>Y5V</td><td>−30 to +85</td><td>Within+22%/−82%</td></tr></table></td><td>The ranges of capacitance change compared with the 25℃ value over the temperature ranges shown in the table shall be within the specified ranges.
The capacitance change shall be measured after 5 min. at each specified temperature stage.</td></tr>
<tr><td>10</td><td>Adhesive Strength of Termination</td><td></td><td>No removal of the terminations or other defect shall occur.</td><td>Solder the capacitor to the test jig (glass epoxy board) shown in Fig.1 using a eutectic solder. Then apply 10N* force in the direction of the arrow. *5N:LL0306
The soldering shall be done either with an iron or using the reflow method and shall be conducted with care so that the soldering is uniform and free of defects such as heat shock.
 

<table><tr><th>Type</th><th>a</th><th>b</th><th>c</th></tr><tr><td>LL0306</td><td>0.3</td><td>1.2</td><td>2.0</td></tr><tr><td>LL0508</td><td>0.6</td><td>1.6</td><td>2.4</td></tr><tr><td>LL0612</td><td>1.0</td><td>3.0</td><td>3.7</td></tr></table>
(in mm)
Fig.1</td></tr>
<tr><td rowspan="3">11</td><td rowspan="3">Vibration Resistance</td><td>Appearance</td><td>No defects or abnormalities.</td><td rowspan="3">Solder the capacitor to the test jig (glass epoxy board) in the same manner and under the same conditions as (10).
The capacitor shall be subjected to a simple harmonic motion having a total amplitude of 1.5mm, the frequency being varied uniformly between the approximate limits of 10 and 55Hz. The frequency range, from 10 to 55Hz and return to 10Hz, shall be traversed in approximately 1 minute. This motion shall be applied for a period of 2 hours in each 3 mutually perpendicular directions (total of 6 hours).</td></tr>
<tr><td>Capacitance</td><td>Within the specified tolerance.</td></tr>
<tr><td>D.F.</td><td><table><tr><th>Char.</th><th>25V min.</th><th>16V</th></tr><tr><td>X7R</td><td>0.025 max.</td><td>0.035 max.</td></tr><tr><td>Z5U</td><td>0.025 max.</td><td>—</td></tr><tr><td rowspan="2">Y5V</td><td rowspan="2">0.05 max.</td><td>0.07 max. (C<1.0μF)</td></tr><tr><td>0.09 max. (C≧1.0μF)</td></tr></table></td></tr>
</table>

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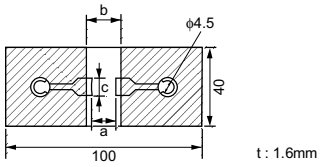
Specifications and Test Methods

Continued from the preceding page.

No.	Item		Specification	Test Method
12	Deflection		No crack or marked defect shall occur.	Solder the capacitor to the test jig (glass epoxy boards) shown in Fig.2 using a eutectic solder. Then apply a force in the direction shown in Fig.3. The soldering shall be done either with an iron or using the reflow method and shall be conducted with care so that the soldering is uniform and free of defects such as heat shock.
13	Solderability of Termination		75% of the terminations is to be soldered evenly and continuously.	Immerse the capacitor in a solution of ethanol (JIS-K-8101) and rosin (JIS-K-5902) (25% rosin in weight proportion). Preheat at 80 to 120℃ for 10 to 30 seconds. After preheating, immerse in eutectic solder solution for 2±0.5 seconds at 230±5℃.
14	Resistance to Soldering Heat	Appearance	No defects or abnormalities.	Preheat the capacitor at 120 to 150℃ for 1 minute. Immerse the capacitor in a eutectic solder solution at 270±5℃ for 10±0.5 seconds. Let sit at room temperature for 48±4 hours , then measure. •Initial measurement. Perform a heat treatment at 150 $^{+0}_{-10}$ ℃ for one hour and then let sit for 48±4 hours at room temperature. Perform the initial measurement.
		Capacitance Change	X7R : Within±7.5% Z5U · Y5V : Within±20%	
		D.F.	Char. / 25V min. / 16V: X7R 0.025 max. / 0.035 max.; Z5U 0.025 max. / —; Y5V 0.05 max. / 0.07 max. (C<1.0μF) / 0.09 max. (C≧1.0μF)	
		I.R.	More than 10,000MΩ or 500Ω • F (Whichever is smaller)	
		Dielectric Strength	No failure	
15	Temperature Cycle	Appearance	No defects or abnormalities.	Fix the capacitor to the supporting jig in the same manner and under the same conditions as (10). Perform the five cycles according to the four heat treatments listed in the following table. Let sit for 48±4 hours at room temperature, then measure.
		Capacitance Change	X7R : Within±7.5% Z5U · Y5V : Within±20%	
		D.F.	Char. / 25V min. / 16V: X7R 0.025 max. / 0.035 max.; Z5U 0.025 max. / —; Y5V 0.05 max. / 0.07 max. (C<1.0μF) / 0.09 max. (C≧1.0μF)	
		I.R.	More than 10,000MΩ or 500Ω • F (Whichever is smaller)	
		Dielectric Strength	No failure	•Initial measurement. Perform a heat treatment at 150 $^{+0}_{-10}$ ℃ for one hour and then let sit for 48±4 hours at room temperature. Perform the initial measurement.
16	Humidity, Steady State	Appearance	No defects or abnormalities.	Sit the capacitor at 40±2℃ and 90 to 95% humidity for 500±12 hours. Remove and let sit for 48±4 hours at room temperature, then measure.
		Capacitance Change	X7R : Within±12.5% Z5U · Y5V : Within±30%	
		D.F.	Char. / 25V min. / 16V: X7R 0.05 max. / 0.05 max.; Z5U 0.05 max. / —; Y5V 0.075 max. / 0.1 max. (C<1.0μF) / 0.125 max. (C≧1.0μF)	
		I.R.	More than 1,000MΩ or 50Ω • F (Whichever is smaller)	



Type	a	b	c
LL0306	0.3	1.2	2.0
LL0508	0.6	1.6	2.4
LL0612	1.0	3.0	3.7

(in mm)

Fig.2

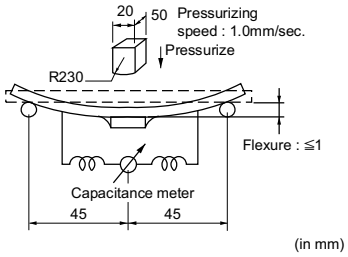


Fig.3

Step	1	2	3	4
Temp.(℃)	Min. Operating Temp. $^{+0}_{-3}$	Room Temp.	Max. Operating Temp. $^{+3}_{-0}$	Room Temp.
Time(min.)	30±3	2 to 3	30±3	2 to 3

Continued on the following page.

Specifications and Test Methods

Continued from the preceding page.

<table>
<tr><th>No.</th><th colspan="2">Item</th><th>Specification</th><th>Test Method</th></tr>
<tr><td rowspan="5">17</td><td rowspan="5">Humidity Load</td><td>Appearance</td><td>No defects or abnormalities.</td><td rowspan="5">Apply the rated voltage at 40±2℃ and 90 to 95% humidity for 500±12 hours. Remove and let sit for 48±4 hours at room temperature, then measure. The charge/discharge current is less than 50mA.</td></tr>
<tr><td>Capacitance Change</td><td>X7R : Within±12.5%
Z5U · Y5V : Within±30%</td></tr>
<tr><td>D.F.</td><td><table>
<tr><th>Char.</th><th>25V min.</th><th>16V</th></tr>
<tr><td>X7R</td><td>0.05 max.</td><td>0.05 max.</td></tr>
<tr><td>Z5U</td><td>0.05 max.</td><td>—</td></tr>
<tr><td rowspan="2">Y5V</td><td rowspan="2">0.075 max.</td><td>0.1 max. (C<1.0μF)</td></tr>
<tr><td>0.125 max. (C≧1.0μF)</td></tr>
</table></td></tr>
<tr><td>I.R.</td><td>More than 500MΩ or 25Ω • F (Whichever is smaller)</td></tr>
<tr><td>Dielectric Strength</td><td>No failure</td></tr>
<tr><td rowspan="5">18</td><td rowspan="5">High Temperature Load</td><td>Appearance</td><td>No defects or abnormalities.</td><td rowspan="5">Apply 200% of the rated voltage for 1,000±12 hours at maximum operating temperature ±3℃. Let sit for 48±4 hours at room temperature, then measure.
The charge/discharge current is less than 50mA.

•Initial measurement.
Apply 200% of the rated DC voltage for one hour at the maximum operating temperature ±3℃.
Remove and let sit for 48±4 hours at room temperature.
Perform initial measurement.</td></tr>
<tr><td>Capacitance Change</td><td>X7R : Within±12.5%
Z5U : Within±30%
Y5V : Within±30% (C<1.0μF)
Within $^{+30}_{-40}$ % (C≧1.0μF)</td></tr>
<tr><td>D.F.</td><td><table>
<tr><th>Char.</th><th>25V min.</th><th>16V</th></tr>
<tr><td>X7R</td><td>0.05 max.</td><td>0.05 max.</td></tr>
<tr><td>Z5U</td><td>0.05 max.</td><td>—</td></tr>
<tr><td rowspan="2">Y5V</td><td rowspan="2">0.075 max.</td><td>0.1 max. (C<1.0μF)</td></tr>
<tr><td>0.125 max. (C≧1.0μF)</td></tr>
</table></td></tr>
<tr><td>I.R.</td><td>More than 1,000MΩ or 50Ω • F (Whichever is smaller)</td></tr>
<tr><td>Dielectric Strength</td><td>No failure</td></tr>
</table>

6

CHIP MONOLITHIC CERAMIC CAPACITOR

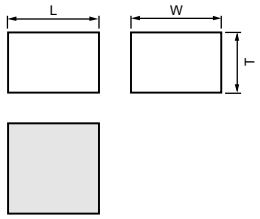
Monolithic Microchip GM Series

■ Features

1. Better micro wave characteristics.
2. Suitable for by-passing.
3. High density mounting.

■ Application

- Optical device for telecommunication.
- IC, IC packaging built-in.
- Measuring equipment.



Part Number	Dimensions (mm)		
	L	W	T
GM250	0.5 ±0.05	0.5 ±0.05	0.35 ±0.05
GM260	0.8 ±0.05	0.8 ±0.05	0.5 ±0.1

Part Number	Rated Voltage (Vdc)	TC Code	Capacitance	Length L (mm)	Width W (mm)	Thickness T (mm)
GM250X7R102M16	16	X7R	1000pF	0.5	0.5	0.35
GM250X7R152M16	16	X7R	1500pF	0.5	0.5	0.35
GM250X7R222M16	16	X7R	2200pF	0.5	0.5	0.35
GM250X7R471M50	50	X7R	470pF	0.5	0.5	0.35
GM250Y5V153Z10	10	Y5V	15000pF	0.5	0.5	0.35
GM250Y5V472Z16	16	Y5V	4700pF	0.5	0.5	0.35
GM250Y5V682Z16	16	Y5V	6800pF	0.5	0.5	0.35
GM260X7R103M16	16	X7R	10000pF	0.8	0.8	0.5
GM260Y5V104Z10	10	Y5V	0.1µF	0.8	0.8	0.5
GM260Y5V473Z16	16	Y5V	47000pF	0.8	0.8	0.5

Specifications and Test Methods

No.	Item		Specification	Test Method
1	Operating Temperature		X7R : −55℃ to +125℃ Y5V : −30℃ to +85℃	
2	Rated Voltage		See the previous pages.	The rated voltage is defined as the maximum voltage which may be applied continuously to the capacitor. When AC voltage is superimposed on DC voltage, V^{P-P} or V^{O-P}, whichever is larger, shall be maintained within the rated voltage range.
3	Appearance		No defects or abnormalities.	Visual inspection.
4	Dimensions		See the previous pages.	Visual inspection.
5	Dielectric Strength		No defects or abnormalities.	No failure shall be observed when a voltage of 250% of the rated voltage is applied between the both terminations for 1 to 5 seconds, provided the charge/discharge current is less than 50mA.
6	Insulation Resistance (I.R.)		10,000MΩ min.	The insulation resistance shall be measured with a DC voltage not exceeding the rated voltage at normal temperature and humidity and within 2 minutes of charging.
7	Capacitance		Within the specified tolerance.	The capacitance shall be measured at 25℃ with 1±0.1kHz in frequency and 1±0.2Vr.m.s. in voltage.
8	Dissipation Factor (D.F.)		X7R : 0.035 max. Y5V : 0.09 max. (for 16V) : 0.125 max. (for 10V)	D.F. shall be measured under the same conditions at the capacitance.
9	Capacitance Temperature Characteristics		<table><tr><th>Char.</th><th>Temp. Range</th><th>Reference Temp.</th><th>Cap. Change Rate</th></tr><tr><td>X7R</td><td>−55 to +125℃</td><td>25℃</td><td>Within±15%</td></tr><tr><td>Y5V</td><td>−30 to +85℃</td><td>25℃</td><td>Within$\pm^{22}_{82}$%</td></tr></table>	The range of capacitance change in reference to 25℃ within the temperature range shown in the table shall be within the specified ranges. The capacitance change shall be measured after 5 min. at each specified temperature stage.
10	Mechanical Strength	Bond Strength	Pull force : 3.0g min.	MIL-STD-883 Method 2011 Condition D Mount the capacitor on a gold metallized alumina substrate with Au-Sn (80/20) and bond a 20μm (0.0008 inch) gold wire to the capacitor terminal using an ultrasonic wedge bond. Then, pull wire.
		Die Shear Strength	Die Shear force : 200g min.	MIL-STD-883 Method 2019 Mount the capacitor on a gold metallized alumina substrate with Au-Sn (80/20). Apply the force parallel to the substrate.
11	Vibration Resistance	Appearance	No defects or abnormalities.	Ramp frequency from 10 to 55Hz then return to 10Hz all within 1 minute. Amplitude : 1.5 mm (0.06 inch) max. total excursion. Apply this motion for a period of 2 hours in each of 3 mutually perpendicular directions (total 6 hours).
		Capacitance	Within the specified tolerance.	
		D.F.	X7R : 0.035 max. Y5V : 0.09 max. (for 16V) : 0.125 max. (for 10V)	
12	Temperature Cycle		The measured values shall satisfy the values in the following table. <table><tr><th>Item</th><th>Specification</th></tr><tr><td>Appearance</td><td>No marked defect</td></tr><tr><td>Capacitance Change</td><td>X7R ····· Within±7.5% Y5V ····· Within±20%</td></tr><tr><td>I.R.</td><td>More than 10,000MΩ</td></tr><tr><td>D.F.</td><td>X7R ····· 0.035 max. Y5V ····· 0.09 max.(for 16V) 0.125 max.(for 10V)</td></tr><tr><td>Dielectric Strength</td><td>No failure</td></tr></table>	The capacitor shall be set for 48±4 hours at room temperature after one hour heat of treatment at 150^{+0}_{-10}℃, then measure for the initial measurement. Fix the capacitor to the supporting jig in the same manner and under the same conditions as (11) and conduct the five cycles according to the temperatures and time shown in the following table. Set it for 48±4 hours at room temperature, then measure. <table><tr><th>Step</th><th>1</th><th>2</th><th>3</th><th>4</th></tr><tr><td>Temp.(℃)</td><td>Min. Operating Temp. $^{+0}_{-3}$</td><td>Room Temp.</td><td>Max. Operating Temp. $^{+3}_{-0}$</td><td>Room Temp.</td></tr><tr><td>Time(min.)</td><td>30±3</td><td>2 to 3</td><td>30±3</td><td>2 to 3</td></tr></table>
13	Humidity (Steady State)		The measured values shall satisfy the values in the following table. <table><tr><th>Item</th><th>Specification</th></tr><tr><td>Appearance</td><td>No marked defect</td></tr><tr><td>Capacitance Change</td><td>X7R ····· Within±12.5% Y5V ····· Within±30%</td></tr><tr><td>I.R.</td><td>More than 1,000MΩ</td></tr><tr><td>D.F.</td><td>X7R ····· 0.05 max. Y5V ····· 0.125 max.(for 16V) 0.15 max.(for 10V)</td></tr><tr><td>Dielectric Strength</td><td>No failure</td></tr></table>	Set the capacitor for 500±12 hours at 40±20℃, in 90 to 95% humidity. Take it out and set it for 48±4 hours at room temperature, then measure.

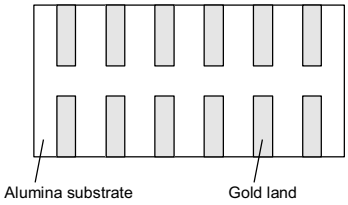
Continued on the following page.

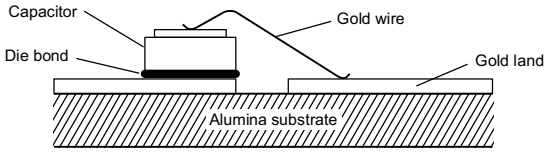
Specifications and Test Methods

Continued from the preceding page.

<table>
<tr><th>No.</th><th>Item</th><th>Specification</th><th>Test Method</th></tr>
<tr><td>14</td><td>Humidity Load</td><td>The measured values shall satisfy the values in the following table.<table><tr><th>Item</th><th>Specification</th></tr><tr><td>Appearance</td><td>No marked defect</td></tr><tr><td>Capacitance Change</td><td>X7R ····· Within±12.5%
Y5V ····· Within$\pm^{30}_{40}$%</td></tr><tr><td>I.R.</td><td>More than 500MΩ</td></tr><tr><td>D.F.</td><td>X7R ····· 0.05 max.
Y5V ····· 0.125 max.(for 16V)
0.15 max.(for 10V)</td></tr><tr><td>Dielectric Strength</td><td>No failure</td></tr></table></td><td>Apply the rated voltage for 500±12 hours at 40±20℃, in 90 to 95% humidity and set it for 48±4 hours at room temperature, then measure. The charge/discharge current is less than 50mA.
• Initial measurement for Y5V
Perform a heat treatment at 150$^{+0}_{-10}$℃ for one hour and then let sit for 48±4 hours at room temperature. Perform the initial measurement.</td></tr>
<tr><td>15</td><td>High Temperature Load</td><td>The measured values shall satisfy the values in the following table.<table><tr><th>Item</th><th>Specification</th></tr><tr><td>Appearance</td><td>No marked defect</td></tr><tr><td>Capacitance Change</td><td>X7R ····· Within±12.5%
Y5V ····· Within$\pm^{30}_{40}$%</td></tr><tr><td>I.R.</td><td>More than 1,000MΩ</td></tr><tr><td>D.F.</td><td>X7R ····· 0.05 max.
Y5V ····· 0.125 max.(for 16V)
0.15 max.(for 10V)</td></tr><tr><td>Dielectric Strength</td><td>No failure</td></tr></table></td><td>A voltage treatment shall be given to the capacitor, in which a DC voltage of 200% the rated voltage is applied for one hour at the maximum operating temperature ±3℃ then it shall be set for 48±4 hours at room temperature and the initial measurement shall be conducted.
Then apply the above mentioned voltage continuously for 1000±12 hours at the same temperature, remove it from the bath, and set it for 48±4 hours at room temperature, then measure. The charge/discharge current is less than 50mA.</td></tr>
</table>

Mounting for testing : The capacitors shall be mounted on the substrate as shown below using die bonding and wire bonding when tests No. 11 to 15 are performed.





7

CHIP MONOLITHIC CERAMIC CAPACITOR

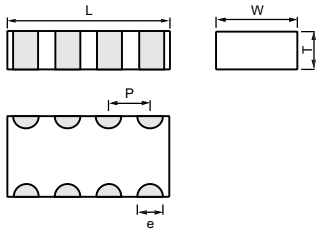
Capacitor Arrays GNM Series

■ Features

1. High density mounting due to mounting space saving.
2. Mounting cost saving.

■ Application

General electronic equipment



Part Number	Dimensions (mm)				
	L	W	T	P	e
GNM30-401	3.2 ±0.15	1.6 ±0.15	0.8 ±0.1	0.8 ±0.1	0.4 ±0.15

Temperature Compensating Type

Part Number	GNM30-401	
L x W(mm)	3.2x1.6	
TC Code	C0G	
Rated Volt.(Vdc)	50	100
Capacitance and T(mm)		
10pF	0.8	0.8
11pF	0.8	0.8
12pF	0.8	0.8
13pF	0.8	0.8
15pF	0.8	0.8
16pF	0.8	0.8
18pF	0.8	0.8
20pF	0.8	0.8
22pF	0.8	0.8
24pF	0.8	0.8
27pF	0.8	0.8
30pF	0.8	0.8
33pF	0.8	0.8
36pF	0.8	0.8
39pF	0.8	0.8
43pF	0.8	0.8
47pF	0.8	0.8
51pF	0.8	0.8
56pF	0.8	0.8
62pF	0.8	0.8
68pF	0.8	0.8
75pF	0.8	0.8
82pF	0.8	0.8
91pF	0.8	0.8
100pF	0.8	0.8
110pF	0.8	0.8
120pF	0.8	0.8
130pF	0.8	0.8
150pF	0.8	0.8
160pF	0.8	
180pF	0.8	
200pF	0.8	
220pF	0.8	

Continued on the following page.

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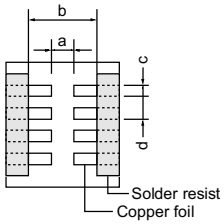
Part Number	GNM30-401	
L x W(mm)	3.2x1.6	
TC Code	C0G	
Rated Volt.(Vdc)	50	100
Capacitance and T(mm)		
240pF	0.8	
270pF	0.8	
300pF	0.8	
330pF	0.8	
360pF	0.8	

High Dielectric Constant Type

Part Number	GNM30-401						
L x W(mm)	3.2x1.6						
TC Code	X7R				Y5V		
Rated Volt.(Vdc)	16	25	50	100	16	50	100
Capacitance and T(mm)							
220pF				0.8			
240pF				0.8			
270pF				0.8			
300pF				0.8			
330pF				0.8			
360pF				0.8			
390pF			0.8	0.8			
470pF			0.8	0.8			
560pF			0.8	0.8			
680pF			0.8	0.8			
820pF			0.8	0.8			
1000pF			0.8	0.8			
1200pF			0.8	0.8			
1500pF			0.8	0.8			
1800pF			0.8	0.8			
2200pF			0.8	0.8			0.8
2700pF			0.8	0.8			
3300pF			0.8	0.8			0.8
3900pF			0.8	0.8			
4700pF			0.8	0.8			0.8
5600pF			0.8				
6800pF			0.8				
8200pF			0.8				
10000pF			0.8				
12000pF			0.8				
15000pF			0.8				
18000pF		0.8					
22000pF	0.8					0.8	
27000pF	0.8						
33000pF	0.8					0.8	
39000pF	0.8						
47000pF						0.8	
68000pF					0.8		
100000pF					0.8		
150000pF					0.8		

Specifications and Test Methods

<table>
<tr><th rowspan="2">No.</th><th rowspan="2" colspan="2">Item</th><th colspan="2">Specification</th><th rowspan="2">Test Method</th></tr>
<tr><th>Temperature Compensating Type</th><th>High Dielectric Constant Type</th></tr>
<tr><td>1</td><td colspan="2">Operating Temperature</td><td>C0G : −55 to +125℃</td><td>X7R : −55 to +125℃
Y5V : −30 to +85℃</td><td></td></tr>
<tr><td>2</td><td colspan="2">Rated Voltage</td><td colspan="2">See the previous page.</td><td>The rated voltage is defined as the maximum voltage which may be applied continuously to the capacitor.
When AC voltage is superimposed on DC voltage, V^{P-P} or V^{O-P}, whichever is larger, shall be maintained within the rated voltage range.</td></tr>
<tr><td>3</td><td colspan="2">Appearance</td><td colspan="2">No defects or abnormalities.</td><td>Visual inspection.</td></tr>
<tr><td>4</td><td colspan="2">Dimensions</td><td colspan="2">Within the specified dimension.</td><td>Using calipers.</td></tr>
<tr><td>5</td><td colspan="2">Dielectric Strength</td><td colspan="2">No defects or abnormalities.</td><td>No failure shall be observed when 300% of the rated voltage (C0G) or 250% of the rated voltage (X7R and Y5V) is applied between the terminations for 1 to 5 seconds, provided the charge/discharge current is less than 50mA.</td></tr>
<tr><td>6</td><td colspan="2">Insulation Resistance (I.R.)</td><td colspan="2">More than 10,000MΩ or 500Ω • F (Whichever is smaller)</td><td>The insulation resistance shall be measured with a DC voltage not exceeding the rated voltage at 25℃ and 75%RH max. and within 2 minutes of charging.</td></tr>
<tr><td>7</td><td colspan="2">Capacitance</td><td colspan="2">Within the specified tolerance.</td><td rowspan="2">The capacitance/Q/D.F. shall be measured at 25℃ at the frequency and voltage shown in the table.
<table><tr><th>Item \ Char.</th><th>C0G</th><th>X7R, Y5V</th></tr><tr><td>Frequency</td><td>1±0.1MHz</td><td>1±0.1MHz</td></tr><tr><td>Voltage</td><td>0.5 to 5Vr.m.s.</td><td>1±0.2Vr.m.s.</td></tr></table></td></tr>
<tr><td>8</td><td colspan="2">Q/Dissipation Factor (D.F.)</td><td>30pF min. : Q≧1,000
30pF max. : Q≧400+20C
C : Nominal Capacitance (pF)</td><td><table><tr><th>Char.</th><th>25V min.</th><th>16V</th></tr><tr><td>X7R</td><td>0.025 max.</td><td>0.035 max.</td></tr><tr><td>Y5V</td><td>0.05 max.</td><td>0.07 max.</td></tr></table></td></tr>
<tr><td rowspan="3">9</td><td rowspan="3">Capacitance Temperature Characteristics</td><td>Capacitance Change</td><td>Within the specified tolerance. (Table A-5)</td><td rowspan="3"><table><tr><th>Char.</th><th>Temp. Range.</th><th>Reference Temp.</th><th>Cap. Change</th></tr><tr><td>X7R</td><td>−55to +125℃</td><td rowspan="2">25℃</td><td>Within±15%</td></tr><tr><td>Y5V</td><td>−30to +85℃</td><td>Within $^{+22}_{-82}$%</td></tr></table></td><td rowspan="3">The capacitance change shall be measured after 5 min. at each specified temperature stage.
(1) Temperature Compensating Type
The temperature coefficient is determined using the capacitance measured in step 3 as a reference.
When cycling the temperature sequentially from step 1 through 5, the capacitance shall be within the specified tolerance for the temperature coefficient and capacitance change as Table A.
The capacitance drift is calculated by dividing the differences between the maximum and minimum measured values in the step 1, 3 and 5 by the cap. value in step 3.
<table><tr><th>Step</th><th>Temperature(℃)</th></tr><tr><td>1</td><td>25±2</td></tr><tr><td>2</td><td>−55±3</td></tr><tr><td>3</td><td>25±2</td></tr><tr><td>4</td><td>125±3</td></tr><tr><td>5</td><td>25±2</td></tr></table>(2) High Dielectric Constant Type
The ranges of capacitance change compared with the 25℃ value over the temperature ranges shown in the table shall be within the specified ranges.</td></tr>
<tr><td>Temperature Coefficient</td><td>Within the specified tolerance. (Table A-5)</td></tr>
<tr><td>Capacitance Drift</td><td>Within ±0.2% or ±0.05pF (Whichever is larger)</td></tr>
<tr><td>10</td><td colspan="2">Adhesive Strength of Termination</td><td colspan="2">No removal of the terminations or other defects shall occur.</td><td>Solder the capacitor to the test jig (glass epoxy board) shown in Fig.1 using a eutectic solder. Then apply 5N force in parallel with the test jig for 10±1 sec.
The soldering shall be done either with an iron or using the reflow method and shall be conducted with care so that the soldering is uniform and free of defects such as heat shock.
 

<table><tr><th>Type</th><th>a</th><th>b</th><th>c</th><th>d</th></tr><tr><td>GNM30-401</td><td>0.8</td><td>2.5</td><td>0.4</td><td>0.8</td></tr></table>(in mm)
Fig.1</td></tr>
</table>

Continued on the following page.

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Specifications and Test Methods

Continued from the preceding page.

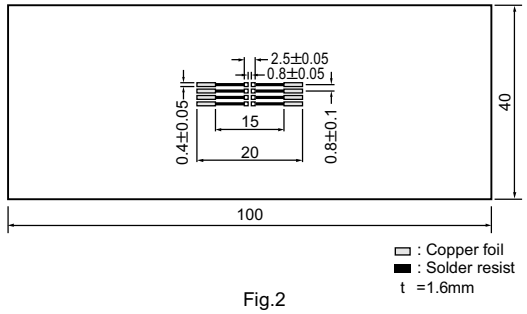
<table>
<tr><th rowspan="2">No.</th><th rowspan="2" colspan="2">Item</th><th colspan="2">Specification</th><th rowspan="2">Test Method</th></tr>
<tr><th>Temperature Compensating Type</th><th>High Dielectric Constant Type</th></tr>
<tr><td rowspan="3">11</td><td rowspan="3">Vibration Resistance</td><td>Appearance</td><td colspan="2">No defects or abnormalities.</td><td rowspan="3">Solder the capacitor to the test jig (glass epoxy board) in the same manner and under the same conditions as (10).
The capacitor shall be subjected to a simple harmonic motion having a total amplitude of 1.5mm, the frequency being varied uniformly between the approximate limits of 10 and 55Hz.
The frequency range, from 10 to 55Hz and return to 10Hz, shall be traversed in approximately 1 minute. This motion shall be applied for a period of 2 hours in each 3 mutually perpendicular directions (total of 6 hours).</td></tr>
<tr><td>Capacitance</td><td colspan="2">Within the specified tolerance.</td></tr>
<tr><td>Q/D.F.</td><td>30pF min. : Q≧1000
30pF max. : Q≧400+20C
C : Nominal Capacitance (pF)</td><td><table><tr><th>Char.</th><th>25V min.</th><th>16V</th></tr><tr><td>X7R</td><td>0.025 max.</td><td>0.035 max.</td></tr><tr><td>Y5V</td><td>0.05 max.</td><td>0.07 max.</td></tr></table></td></tr>
<tr><td>12</td><td colspan="2">Deflection</td><td colspan="2">No cracking or marking defects shall occur.
 

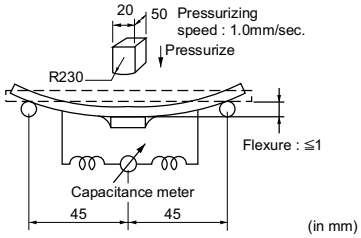
Fig.2</td><td>Solder the capacitor to the test jig (glass epoxy boards) shown in Fig.2 using a eutectic solder. Then apply a force in the direction shown in Fig.3. The soldering shall be done either with an iron or using the reflow method and shall be conducted with care so that the soldering is uniform and free of defects such as heat shock.
 

Fig.3</td></tr>
<tr><td>13</td><td colspan="2">Solderability of Termination</td><td colspan="2">75% of the terminations is to be soldered evenly and continuously.</td><td>Immerse the capacitor in a solution of ethanol (JIS-K-8101) and rosin (JIS-K-5902) (25% rosin in weight proportion). Preheat at 80 to 120℃ for 10 to 30 seconds. After preheating, immerse in eutectic solder solution for 2±0.5 seconds at 230±5℃.</td></tr>
<tr><td rowspan="6">14</td><td rowspan="6">Resistance to Soldering Heat</td><td colspan="3">The measured and observed characteristics shall satisfy the specifications in the following table.</td><td rowspan="6">Preheat the capacitor at 120 to 150℃ for 1 minute. Immerse the capacitor in a eutectic solder solution at 270±5℃ for 10±0.5 seconds. Let sit at room temperature for 24±2 hours (temperature compensating type) or 48±4 hours (high dielectric constant type), then measure.
• Initial measurement for high dielectric constant type
Perform a heat treatment at 150 $^{+0}_{-10}$ ℃ for one hour and then let sit for 48±4 hours at room temperature. Perform the initial measurement.</td></tr>
<tr><td>Appearance</td><td colspan="2">No marking defects.</td></tr>
<tr><td>Capacitance Change</td><td>Within ±2.5% or ±0.25pF (Whichever is larger)</td><td>X7R ····· Within±7.5%
Y5V ····· Within±20%</td></tr>
<tr><td>Q/D.F.</td><td>30pF and over : Q≧1,000
30pF and below : Q≧400+20C
C : Nominal Capacitance (pF)</td><td><table><tr><th>Char.</th><th>25V min.</th><th>16V</th></tr><tr><td>X7R</td><td>0.025 max.</td><td>0.035 max.</td></tr><tr><td>Y5V</td><td>0.05 max.</td><td>0.07 max.</td></tr></table></td></tr>
<tr><td>I.R.</td><td colspan="2">More than 10,000MΩ or 500Ω • F (Whichever is smaller)</td></tr>
<tr><td>Dielectric Strength</td><td colspan="2">No failure</td></tr>
<tr><td rowspan="6">15</td><td rowspan="6">Temperature Cycle</td><td colspan="3">The measured and observed characteristics shall satisfy the specifications in the following table.</td><td rowspan="6">Fix the capacitor to the supporting jig in the same manner and under the same conditions as (10). Perform the five cycles according to the four heat treatments listed in the following table. Let sit for 24±2 hours (temperature compensating type) or 48±4 hours (high dielectric constant type) at room temperature, then measure.
<table><tr><th>Step</th><th>1</th><th>2</th><th>3</th><th>4</th></tr><tr><td>Temp.(℃)</td><td>Min. Operating Temp. $^{+0}_{-3}$</td><td>Room Temp.</td><td>Max. Operating Temp. $^{+3}_{-0}$</td><td>Room Temp.</td></tr><tr><td>Time(min.)</td><td>30±3</td><td>2 to 3</td><td>30±3</td><td>2 to 3</td></tr></table>• Initial measurement for high dielectric constant type
Perform a heat treatment at 150 $^{+0}_{-10}$ ℃ for one hour and then let sit for 48±4 hours at room temperature. Perform the initial measurement.</td></tr>
<tr><td>Appearance</td><td colspan="2">No marking defects.</td></tr>
<tr><td>Capacitance Change</td><td>Within ±2.5% or ±0.25pF (Whichever is larger)</td><td>X7R ····· Within±7.5%
Y5V ····· Within±20%</td></tr>
<tr><td>Q/D.F.</td><td>30pF and over : Q≧1,000
30pF and below : Q≧400+20C
C : Nominal Capacitance (pF)</td><td><table><tr><th>Char.</th><th>25V min.</th><th>16V</th></tr><tr><td>X7R</td><td>0.025 max.</td><td>0.035 max.</td></tr><tr><td>Y5V</td><td>0.05 max.</td><td>0.07 max.</td></tr></table></td></tr>
<tr><td>I.R.</td><td colspan="2">More than 10,000MΩ or 500Ω • F (Whichever is smaller)</td></tr>
<tr><td>Dielectric Strength</td><td colspan="2">No failure</td></tr>
</table>

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Specifications and Test Methods

Continued from the preceding page.

No.	Item		Specification: Temperature Compensating Type	Specification: High Dielectric Constant Type	Test Method
16	Humidity, Steady State		The measured and observed characteristics shall satisfy the specifications in the following table.		Sit the capacitor at 40±2℃ and 90 to 95% humidity for 500±12 hours. Remove and let sit for 24±2 hours (temperature compensating type) or 48±4 hours (high dielectric constant type) at room temperature, then measure.
		Appearance	No marking defects.		
		Capacitance Change	Within ±5% or ±0.5pF (Whichever is larger)	X7R ····· Within±12.5% Y5V ····· Within±30%	
		Q/D.F.	30pF and over : Q≧350 10pF and over, 30pF and below : Q≧275+$\frac{5}{2}$C 10pF and below : Q≧200+10C C : Nominal Capacitance (pF)	Char. / 25V min. / 16V X7R / 0.05 max. / 0.05 max. Y5V / 0.075 max. / 0.1 max.	
		I.R.	More than 1,000MΩ or 50Ω • F (Whichever is smaller)		
17	Humidity Load		The measured and observed characteristics shall satisfy the specifications in the following table.		Apply the rated voltage at 40±2℃ and 90 to 95% humidity for 500±12 hours. Remove and let sit for 24±2 hours (temperature compensating type) or 48±4 hours (high dielectric constant type) at room temperature, then measure. The charge/discharge current is less than 50mA.
		Appearance	No marking defects.		
		Capacitance Change	Within ±7.5% or ±0.75pF (Whichever is larger)	X7R ····· Within±12.5% Y5V ····· Within±30%	
		Q/D.F.	30pF and over : Q≧200 30pF and below : Q≧100+$\frac{10}{3}$C C : Nominal Capacitance (pF)	Char. / 25V min. / 16V X7R / 0.05 max. / 0.05 max. Y5V / 0.075 max. / 0.1 max.	
		I.R.	More than 500MΩ or 25Ω • F (Whichever is smaller)		
		Dielectric Strength	No failure		
18	High Temperature Load		The measured and observed characteristics shall satisfy the specifications in the following table.		Apply 200% of the rated voltage for 1,000±12 hours at the maximum operating temperature ±3℃. Let sit for 24±2 hours (temperature compensating type) or 48±4 hours (high dielectric constant type) at room temperature, then measure. The charge/discharge current is less than 50mA. •Initial measurement for high dielectric constant type. Apply 200% of the rated DC voltage for one hour at the maximum operating temperature ±3℃. Remove and let sit for 48±4 hours at room temperature. Perform initial measurement.
		Appearance	No marking defects.		
		Capacitance Change	Within ±3% or ±0.3pF (Whichever is larger)	X7R ····· Within±12.5% Y5V ····· Within±30%	
		Q/D.F.	30pF and over : Q≧350 10pF and over, 30pF and below : Q≧275+$\frac{5}{2}$C 10pF and below : Q≧200+10C C : Nominal Capacitance (pF)	Char. / 25V min. / 16V X7R / 0.04 max. / 0.05 max. Y5V / 0.075 max. / 0.1 max.	
		I.R.	More than 1,000MΩ or 50Ω • F (Whichever is smaller)		
		Dielectric Strength	No failure		

Table A

Char.	Temp. Coeff. (ppm/℃) Note 1	Capacitance Change from 25℃ (%)					
		−55℃		−30℃		−10℃	
		Max.	Min.	Max.	Min.	Max.	Min.
C0G	0±30	0.58	−0.24	0.40	−0.17	0.25	−0.11

Note 1 : Nominal values denote the temperature coefficient within a range of 25 to 125℃.

CHIP MONOLITHIC CERAMIC CAPACITOR

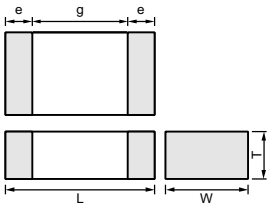
for Ultrasonic Sensors ZLM Type

■ Features

1. Proper to compensate for ultrasonic sensor.
2. Small chip size and high cap. Value.

■ Application

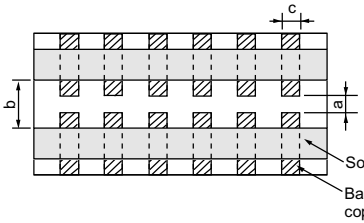
Ultrasonic sensor
(Back sonar, Corner sonar and etc.)



Part Number	Dimensions (mm)				
	L	W	T	e	g min.
GRM40	2.0 ±0.1	1.25 ±0.1	0.85 ±0.1	0.2 to 0.7	0.7

Part Number	Rated Voltage (Vdc)	TC Code	Capacitance (pF)	Length L (mm)	Width W (mm)	Thickness T (mm)
GRM40ZLM102K100	100	ZLM	1000 ±10%	2.0 ±0.1mm	1.25 ±0.1mm	0.85 ±0.1mm
GRM40ZLM152K100	100	ZLM	1500 ±10%	2.0 ±0.1mm	1.25 ±0.1mm	0.85 ±0.1mm

Specifications and Test Methods

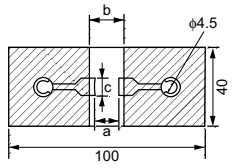
No.	Item	Specification	Test Method
1	Operating Temperature	−25℃ to +85℃	
2	Rated Voltage	See the previous pages.	The rated voltage is defined as the maximum voltage which may be applied continuously to the capacitor. When AC voltage is superimposed on DC voltage, V^{P-P} or V^{O-P}, whichever is larger, shall be maintained within the rated voltage range.
3	Appearance	No defects or abnormalities.	Visual inspection.
4	Dimensions	Within the specified dimensions.	Using calipers.
5	Dielectric Strength	No defects or abnormalities.	No failure shall be observed when 300% of the rated voltage is applied between the terminations for 1 to 5 seconds, provided the charge/discharge current is less than 50mA.
6	Insulation Resistance (I.R.)	More than 10,000MΩ or 500Ω • F. (Whichever is smaller)	The insulation resistance shall be measured with a DC voltage not exceeding the rated voltage at 20℃ and 75%RH max. and within 2 minutes of charging.
7	Capacitance	Within the specified tolerance.	The capacitance/D.F. shall be measured at 20℃ with 1±0.1kHz in frequency and 1±0.2Vr.m.s. in voltage.
8	Dissipation Factor (D.F.)	0.01 max.	
9	Capacitance Temperature Characteristics	Within $-4{,}700^{+1{,}000}_{-2{,}500}$ ppm/℃ (at −25 to +20℃) Within $-4{,}700^{+500}_{-1{,}000}$ ppm/℃ (at +20 to +85℃)	The temperature coefficient is determined using the capacitance measured in step 1 as a reference. When cycling the temperature sequentially from step 1 through 5, the capacitance shall be within the specified tolerance for the temperature coefficient. The capacitance change shall be measured after 5 min. at each specified temperature stage. Step / Temperature(℃): 1: 20±2; 2: −25±3; 3: 20±2; 4: 85±3; 5: 20±2
10	Adhesive Strength of Termination	No removal of the terminations or other defect shall occur.	Solder the capacitor to the test jig (glass epoxy board) shown in Fig.1 using a eutectic solder. Then apply 10N force in the direction of the arrow. The soldering shall be done either with an iron or using the reflow method and shall be conducted with care so that the soldering is uniform and free of defects such as heat shock.  Type / a / b / c: GRM40 / 1.2 / 4.0 / 1.65 (in mm) Fig.1
11	Vibration Resistance	Appearance: No defects or abnormalities. Capacitance: Within the specified tolerance. D.F.: 0.01 max.	Solder the capacitor to the test jig (glass epoxy board) in the same manner and under the same conditions as (10). The capacitor shall be subjected to a simple harmonic motion having a total amplitude of 1.5mm, the frequency being varied uniformly between the approximate limits of 10 and 55Hz. The frequency range, from 10 to 55Hz and return to 10Hz, shall be traversed in approximately 1 minute. This motion shall be applied for a period of 2 hours in each 3 mutually perpendicular directions (total of 6 hours).

Continued on the following page.

Specifications and Test Methods

Continued from the preceding page.

No.	Item		Specification	Test Method
12	Deflection		No cracking or marking defects shall occur.	Solder the capacitor to the test jig (glass epoxy boards) shown in Fig.2 using a eutectic solder. Then apply a force in the direction shown in Fig.3. The soldering shall be done either with an iron or using the reflow method and shall be conducted with care so that the soldering is uniform and free of defects such as heat shock.
13	Solderability of Termination		75% of the terminations is to be soldered evenly and continuously.	Immerse the capacitor in a solution of ethanol (JIS-K-8101) and rosin (JIS-K-5902) (25% rosin in weight proportion). Preheat at 80 to 120℃ for 10 to 30 seconds. After preheating, immerse in eutectic solder solution for 2±0.5 seconds at 230±5℃.
14	Resistance to Soldering Heat	Appearance	No defects or abnormalities.	Preheat the capacitor at 120 to 150℃ for 1 minute. Immerse the capacitor in a eutectic solder solution at 270±5℃ for 10±0.5 seconds. Let sit at room temperature for 24±2 hours , then measure.
		Capacitance Change	Within ±7.5%	
		D.F.	0.01 max.	
		I.R.	More than 10,000MΩ or 500Ω • F (Whichever is smaller)	
		Dielectric Strength	No failure	
15	Temperature Cycle	Appearance	No defects or abnormalities.	Fix the capacitor to the supporting jig in the same manner and under the same conditions as (11). Perform the five cycles according to the four heat treatments listed in the following table. Let sit for 24±2 hours at room temperature, then measure.
		Capacitance Change	Within ±7.5%	
		D.F.	0.01 max.	
		I.R.	More than 10,000MΩ or 500Ω • F (Whichever is smaller)	
		Dielectric Strength	No failure	
16	Humidity, Steady State	Appearance	No defects or abnormalities.	Sit the capacitor at 40±2℃ and 90 to 95% humidity for 500±12 hours. Remove and let sit for 24±2 hours at room temperature, then measure.
		Capacitance Change	Within ±12.5%	
		D.F.	0.02 max.	
		I.R.	More than 1,000MΩ or 50Ω • F (Whichever is smaller)	
		Dielectric Strength	No failure	
17	Humidity Load	Appearance	No defects or abnormalities.	Apply the rated voltage at 40±2℃ and 90 to 95% humidity for 500±12 hours. Remove and let sit for 24±2 hours at room temperature, then measure. The charge/discharge current is less than 50mA.
		Capacitance Change	Within ±12.5%	
		D.F.	0.02 max.	
		I.R.	More than 500MΩ or 25Ω • F (Whichever is smaller)	
18	High Temperature Load	Appearance	No defects or abnormalities.	Apply 200% of the rated voltage for 1,000±12 hours at 85±3℃. Let sit for 24±2 hours at room temperature, then measure. The charge/discharge current is less than 50mA.
		Capacitance Change	Within ±12.5%	
		D.F.	0.02 max.	
		I.R.	More than 1,000MΩ or 50Ω • F (Whichever is smaller)	



Type	a	b	c
GRM40	1.2	4.0	1.65

(in mm)

Fig.2

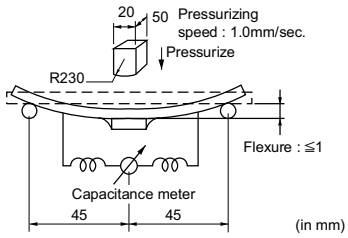


Fig.3

Step	1	2	3	4
Temp.(℃)	-25^{+0}_{-3}	RoomTemp.	85^{+3}_{-0}	RoomTemp.
Time(min.)	30±3	2 to 3	30±3	2 to 3

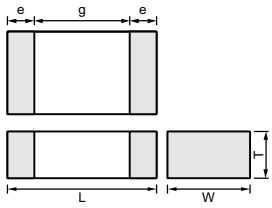
9

CHIP MONOLITHIC CERAMIC CAPACITOR

High-frequency for Flow/Reflow Soldering GRQ Series

■ Features

1.HiQ and low ESR at VHF, UHF, Microwave.
2.Feature improvement, low power consumption for mobile telecommunication (Base station, terminal, etc.)



■ Application

High-frequency circuit (Mobile telecommunication, etc.)

Part Number	Dimensions (mm)				
	L	W	T	e	g min.
GRQ706	1.6 ±0.1	0.8 ±0.1	0.8 ±0.1	0.2 to 0.5	0.5
GRQ708	2.0 ±0.1	1.25 ±0.1	0.85 ±0.1	0.2 to 0.7	0.7

Part Number	GRQ706		GRQ708	
L x W(mm)	1.60x0.80		2.00x1.25	
TC Code	C0G		C0G	
Rated Volt.(Vdc)	50	100	50	100
Capacitance and T(mm)				
0.5pF		0.80		0.85
0.75pF		0.80		0.85
1.0pF		0.80		0.85
1.1pF		0.80		0.85
1.2pF		0.80		0.85
1.3pF		0.80		0.85
1.5pF		0.80		0.85
1.6pF		0.80		0.85
1.8pF		0.80		0.85
2.0pF		0.80		0.85
2.2pF		0.80		0.85
2.4pF		0.80		0.85
2.7pF		0.80		0.85
3.0pF		0.80		0.85
3.3pF		0.80		0.85
3.6pF		0.80		0.85
3.9pF		0.80		0.85
4.0pF		0.80		0.85
4.3pF		0.80		0.85
4.7pF		0.80		0.85
5.0pF		0.80		0.85
5.1pF		0.80		0.85
5.6pF		0.80		0.85
6.0pF		0.80		0.85
6.2pF		0.80		0.85
6.8pF		0.80		0.85
7.0pF	0.80			0.85
7.5pF	0.80			0.85
8.0pF	0.80			0.85
8.2pF	0.80			0.85
9.0pF	0.80			0.85
9.1pF	0.80			0.85
10.0pF	0.80			0.85
11pF	0.80			0.85
12pF	0.80			0.85

Continued on the following page.

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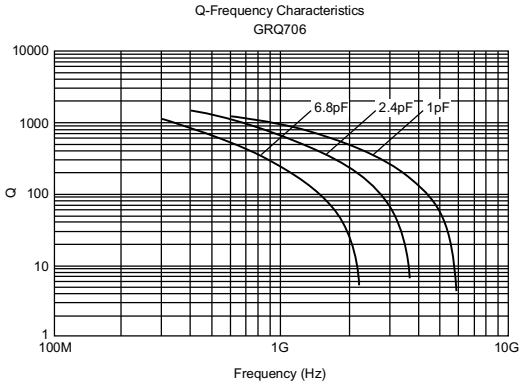
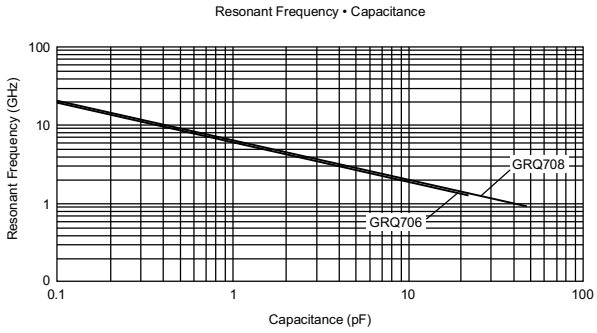
Part Number	GRQ706		GRQ708	
L x W(mm)	1.60x0.80		2.00x1.25	
TC Code	C0G		C0G	
Rated Volt.(Vdc)	50	100	50	100
Capacitance and T(mm)				
13pF	0.80			0.85
15pF	0.80			0.85
16pF	0.80			0.85
18pF	0.80			0.85
20pF	0.80		0.85	
22pF	0.80		0.85	
24pF	0.80		0.85	
27pF			0.85	
30pF			0.85	
33pF			0.85	
36pF			0.85	
39pF			0.85	
43pF			0.85	
47pF			0.85	

■ Q-Frequency Characteristics



■ Resonant Frequency-Capacitance



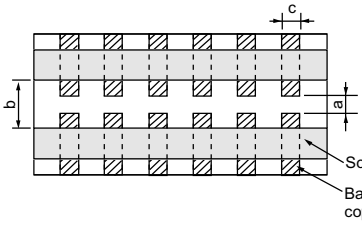
10

Specifications and Test Methods

No.	Item		Specification	Test Method
1	Operating Temperature Range		C0G : −55℃ to 125℃	
2	Rated Voltage		See the previous pages.	The rated voltage is defined as the maximum voltage which may be applied continuously to the capacitor. When AC voltage is superimposed on DC voltage, V^{P-P} or V^{O-P}, whichever is larger, shall be maintained within the rated voltage range.
3	Appearance		No defects or abnormalities.	Visual inspection.
4	Dimensions		Within the specified dimensions.	Using calipers.
5	Dielectric Strength		No defects or abnormalities.	No failure shall be observed when 300% of the rated voltage is applied between the terminations for 1 to 5 seconds, provided the charge/discharge current is less than 50mA.
6	Insulation Resistance (I.R.)		More than 10,000MΩ or 500Ω • F. (Whichever is smaller)	The insulation resistance shall be measured with a DC voltage not exceeding the rated voltage at 25℃ and 75%RH max. and within 2 minutes of charging.
7	Capacitance		Within the specified tolerance.	The capacitance/Q shall be measured at 25℃ at the frequency and voltage shown in the table.
8	Q		Q≧1000	
9	Capacitance Temperature Characteristics	Capacitance Change	Within the specified tolerance. (Table A-1)	The temperature coefficient is determined using the capacitance measured in step 3 as a reference. When cycling the temperature sequentially from step 1 through 5, the capacitance shall be within the specified tolerance for the temperature coefficient and capacitance change as Table A. The capacitance drift is caluculated by dividing the differences between the maximum and minimum measured values in the step 1, 3 and 5 by the cap. value in step 3.
		Temperature Coefficent	Within the specified tolerance. (Table A-1)	
		Capacitance Drift	Within ±0.2% or ±0.05pF (Whichever is larger.)	
10	Adhesive Strength of Termination		No removal of the terminations or other defect shall occur.	Solder the capacitor to the test jig (glass epoxy board) shown in Fig.1 using a eutectic solder. Then apply 10N* force in parallel with the test jig for 10±1sec. The soldering shall be done either with an iron or using the reflow method and shall be conducted with care so that the soldering is uniform and free of defects such as heat shock. *5N (GRQ706)
11	Vibration Resistance	Appearance	No defects or abnormalities.	Solder the capacitor to the test jig (glass epoxy board) in the same manner and under the same conditions as (10). The capacitor shall be subjected to a simple harmonic motion having a total amplitude of 1.5mm, the frequency being varied uniformly between the approximate limits of 10 and 55Hz. The frequency range, from 10 to 55Hz and return to 10Hz, shall be traversed in approximately 1 minute. This motion shall be applied for a period of 2 hours in each 3 mutually perpendicular directions (total of 6 hours).
		Capacitance	Within the specified tolerance.	
		Q	Q≧1000	

Item \ Char.	C0G(1000pF and below)
Frequency	1±0.1MHz
Voltage	0.5 to 5Vrms

Step	Temperature(℃)
1	25±2
2	−55±3
3	25±2
4	125±3
5	25±2



Type	a	b	c
GRQ706	1.0	3.0	1.2
GRQ708	1.2	4.0	1.65

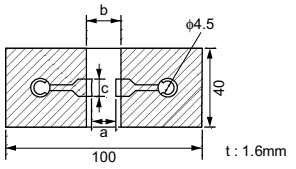
(in mm)

Fig.1

Continued on the following page.

Specifications and Test Methods

Continued from the preceding page.

<table>
<tr><th>No.</th><th>Item</th><th>Specification</th><th>Test Method</th></tr>
<tr><td>12</td><td>Deflection</td><td>No cracking or marking defects shall occur.
 

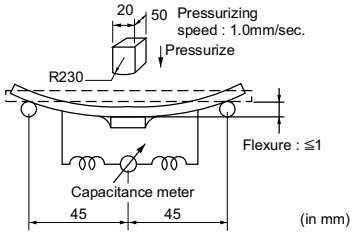
<table>
<tr><th>Type</th><th>a</th><th>b</th><th>c</th></tr>
<tr><td>GRQ706</td><td>1.0</td><td>3.0</td><td>1.2</td></tr>
<tr><td>GRQ708</td><td>1.2</td><td>4.0</td><td>1.65</td></tr>
</table>
(in mm)
Fig.2</td><td>Solder the capacitor to the test jig (glass epoxy board) shown in Fig.2 using a eutectic solder. Then apply a force in the direction shown in Fig.3. The soldering shall be done either with an iron or using the reflow method and shall be conducted with care so that the soldering is uniform and free of defects such as heat shock.
 

Fig.3</td></tr>
<tr><td>13</td><td>Solderability of Termination</td><td>75% of the terminations is to be soldered evenly and continuously.</td><td>Immerse the capacitor in a solution of ethanol (JIS-K-8101) and rosin (JIS-K-5902) (25% rosin in weight proportion). Preheat at 80 to 120℃ for 10 to 30 seconds. After preheating, immerse in eutectic solder solution for 2±0.5 seconds at 230±5℃.</td></tr>
<tr><td rowspan="6">14</td><td rowspan="6">Resistance to Soldering Heat</td><td colspan="2">The measured and observed characteristics shall satisfy the specifications in the following table.</td><td rowspan="6">Preheat the capacitor at 120 to 150℃ for 1 minute. Immerse the capacitor in a eutectic solder solution at 270±5℃ for 10±0.5 seconds. Let sit at room temperature for 24±2 hours.</td></tr>
<tr><td>Appearance</td><td>No marking defects.</td></tr>
<tr><td>Capacitance Change</td><td>Within ±2.5% or ±0.25pF
(Whichever is larger)</td></tr>
<tr><td>Q</td><td>Q≧1000</td></tr>
<tr><td>I.R.</td><td>More than 10,000MΩ or 500Ω • F (Whichever is smaller)</td></tr>
<tr><td>Dielectric Strength</td><td>No failure</td></tr>
<tr><td rowspan="6">15</td><td rowspan="6">Temperature Cycle</td><td colspan="2">The measured and observed characteristics shall satisfy the specifications in the following table.</td><td rowspan="6">Fix the capacitor to the supporting jig in the same manner and under the same conditions as (10).
Perform the five cycles according to the four heat treatments listed in the following table.
Let sit for 24±2 hours at room temperature, then measure.
<table>
<tr><th>Step</th><th>1</th><th>2</th><th>3</th><th>4</th></tr>
<tr><td>Temp.(℃)</td><td>Min. Operating Temp.+0/−3</td><td>Room Temp.</td><td>Max. Operating Temp.+3/−0</td><td>Room Temp.</td></tr>
<tr><td>Time(min.)</td><td>30±3</td><td>2 to 3</td><td>30±3</td><td>2 to 3</td></tr>
</table></td></tr>
<tr><td>Appearance</td><td>No marking defects.</td></tr>
<tr><td>Capacitance Change</td><td>Within ±2.5% or ±0.25pF
(Whichever is larger)</td></tr>
<tr><td>Q</td><td>Q≧1000</td></tr>
<tr><td>I.R.</td><td>More than 10,000MΩ or 500Ω • F (Whichever is smaller)</td></tr>
<tr><td>Dielectric Strength</td><td>No failure</td></tr>
<tr><td rowspan="6">16</td><td rowspan="6">Humidity, Steady State</td><td colspan="2">The measured and observed characteristics shall satisfy the specifications in the following table.</td><td rowspan="6">Sit the capacitor at 40±2℃ and 90 to 95% humidity for 500±12 hours.
Remove and let sit for 24±2 hours (temperature compensating type) at room temperature, then measure.</td></tr>
<tr><td>Appearance</td><td>No marking defects.</td></tr>
<tr><td>Capacitance Change</td><td>Within ±5% or ±0.5pF
(Whichever is larger)</td></tr>
<tr><td>Q</td><td>Q≧350</td></tr>
<tr><td>I.R.</td><td>More than 1,000MΩ or 50Ω • F (Whichever is smaller)</td></tr>
<tr><td>Dielectric Strength</td><td>No failure</td></tr>
<tr><td rowspan="6">17</td><td rowspan="6">Humidity Load</td><td colspan="2">The measured and observed characteristics shall satisfy the specifications in the following table.</td><td rowspan="6">Apply the rated voltage at 40±2℃ and 90 to 95% humidity for 500±12 hours. Remove and let sit for 24±2 hours at room temperature, then measure. The charge/discharge current is less than 50mA.</td></tr>
<tr><td>Appearance</td><td>No marking defects.</td></tr>
<tr><td>Capacitance Change</td><td>Within ±7.5% or ±0.75pF
(Whichever is larger)</td></tr>
<tr><td>Q</td><td>Q≧200</td></tr>
<tr><td>I.R.</td><td>More than 500MΩ or 25Ω • F (Whichever is smaller)</td></tr>
<tr><td>Dielectric Strength</td><td>No failure</td></tr>
</table>

Continued on the following page.

Specifications and Test Methods

Continued from the preceding page.

No.	Item		Specification	Test Method
18	High Temperature Load		The measured and observed characteristics shall satisfy the specifications in the following table.	Apply 200% of the rated voltage for 1,000±12 hours at the maximum operating temperature ±3℃. Let sit for 24±2 hours (temperature compensating type) at room temperature, then measure. The charge/discharge current is less than 50mA.
		Appearance	No marking defects.	
		Capacitance Change	Within ±3% or ±0.3pF (Whichever is larger)	
		Q	Q≧350	
		I.R.	More than 1,000MΩ or 50Ω • F (Whichever is smaller)	
		Dielectric Strength	No failure	

Table A

Char.	Nominal Values (ppm/℃) Note 1	Capacitance Change from 25℃ (%)					
		−55℃		−30℃		−10℃	
		Max.	Min.	Max.	Min.	Max.	Min.
C0G	0±30	0.58	−0.24	0.40	−0.17	0.25	−0.11

Note 1 : Nominal values denote the temperature coefficient within a range of 25℃ to 125℃. (for C0G)

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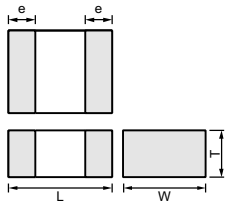
CHIP MONOLITHIC CERAMIC CAPACITOR

High-Q & High-power GRH/RPN100 Series

■ Features(GRH100 Series)

1. The dielectric is composed of low dielectric loss ceramics. This series is perfectly suited to high-frequency applications (VHS-microwave band).
2. The series is ultraminiature, yet has a high-power capacity. This is the best capacitor available for transmitter and amplifier circuits such as those in broadcasting equipment and mobile base stations.
3. GRH110 type is designed for both flow and reflow soldering and GRH111 type is designed for reflow soldering.
4. GRH type capacitors exhibit better solderability and lower solder leaching because of its nickel barriered terminations.



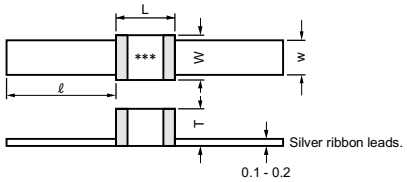
Part Number	Dimensions (mm)			
	L	W	T	e
GRH110	$1.4^{+0.6}_{-0.4}$	$1.4^{+0.6}_{-0.4}$	0.8 to 1.65	$0.25^{+0.25}_{-0.15}$
GRH111	$2.8^{+0.6}_{-0.4}$	$2.8^{+0.6}_{-0.4}$	2.0 to 2.8	$0.4^{+0.4}_{-0.3}$

■ Application

High-frequency and high-power circuits.

■ Features(RPN100 Series)

1. The dielectric is composed of low dielectric loss ceramics. This series is perfectly suited to high-frequency applications (VHS-microwave band).
2. The series is ultraminiature, yet has a high-power capacity. This is the best capacitor available for transmitter and amplifier circuits such as those in broadcasting equipment and mobile base stations.
3. RPN type capacitors withstand high temperatures because ribbon leads are attached with silver paste.
4. RPN type capacitors are easily soldered and especially well suited in applications where only a soldering iron can be used.



*** : Capacitance Code

Part Number	Dimensions (mm)				
	L	W	T max.	ℓ	w
RPN110	1.6 ±0.4	1.4 ±0.4	1.6	5.0 min.	1.3 ±0.4
RPN111	3.2 ±0.4	2.8 ±0.4	3.0	9.0 ±2.0	2.35 ±0.15

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■ Application

High-frequency and high-power circuits.

Part Number	GRH110	GRH111					RPN110	RPN111				
L x W(mm)	1.40x1.40	2.80x2.80					1.60x1.40	3.20x2.80				
TC Code	C0G	C0G					C0G	C0G				
Rated Volt.(Vdc)	50	50	100	200	300	500	50	50	100	200	300	500
Capacitance and T(mm)												
0.5pF	1.20					2.40	1.60					3.00
0.6pF	1.20					2.40	1.60					3.00
0.7pF	1.20					2.40	1.60					3.00
0.8pF	1.20					2.40	1.60					3.00
0.9pF	1.20					2.40	1.60					3.00
1.0pF	1.20					2.40	1.60					3.00
1.1pF	1.20					2.40	1.60					3.00
1.2pF	1.20					2.40	1.60					3.00
1.3pF	1.20					2.40	1.60					3.00
1.4pF	1.20					2.40	1.60					3.00
1.5pF	1.20					2.40	1.60					3.00

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Part Number	GRH110	GRH111					RPN110	RPN111				
L x W(mm)	1.40x1.40	2.80x2.80					1.60x1.40	3.20x2.80				
TC Code	C0G	C0G					C0G	C0G				
Rated Volt.(Vdc)	50	50	100	200	300	500	50	50	100	200	300	500
Capacitance and T(mm)												
1.6pF	1.20					2.40	1.60					3.00
1.7pF	1.20					2.40	1.60					3.00
1.8pF	1.20					2.40	1.60					3.00
1.9pF	1.20					2.40	1.60					3.00
2.0pF	1.20					2.40	1.60					3.00
2.1pF	1.20					2.40	1.60					3.00
2.2pF	1.20					2.40	1.60					3.00
2.4pF	1.20					2.40	1.60					3.00
2.7pF	1.20					2.40	1.60					3.00
3.0pF	1.20					2.40	1.60					3.00
3.3pF	1.20					2.40	1.60					3.00
3.6pF	1.20					2.40	1.60					3.00
3.9pF	1.20					2.40	1.60					3.00
4.3pF	1.20					2.40	1.60					3.00
4.7pF	1.20					2.40	1.60					3.00
5.1pF	1.20					2.40	1.60					3.00
5.6pF	1.20					2.40	1.60					3.00
6.2pF	1.20					2.40	1.60					3.00
6.8pF	1.20					2.40	1.60					3.00
7.5pF	1.20					2.40	1.60					3.00
8.2pF	1.20					2.40	1.60					3.00
9.1pF	1.20					2.40	1.60					3.00
10.0pF	1.20					2.40	1.60					3.00
11pF	1.20					2.40	1.60					3.00
12pF	1.20					2.40	1.60					3.00
13pF	1.20					2.40	1.60					3.00
15pF	1.20					2.40	1.60					3.00
16pF	1.20					2.40	1.60					3.00
18pF	1.20					2.40	1.60					3.00
20pF	1.20					2.40	1.60					3.00
22pF	1.20					2.40	1.60					3.00
24pF	1.20					2.40	1.60					3.00
27pF	1.20					2.40	1.60					3.00
30pF	1.20					2.40	1.60					3.00
33pF	1.20					2.40	1.60					3.00
36pF	1.20					2.40	1.60					3.00
39pF	1.20					2.40	1.60					3.00
43pF	1.20					2.40	1.60					3.00
47pF	1.20					2.40	1.60					3.00
51pF	1.20					2.40	1.60					3.00
56pF	1.20					2.40	1.60					3.00
62pF	1.20					2.40	1.60					3.00
68pF	1.20					2.40	1.60					3.00
75pF	1.20					2.40	1.60					3.00
82pF	1.20					2.40	1.60					3.00
91pF	1.20					2.40	1.60					3.00
100pF	1.20					2.40	1.60					3.00
110pF					2.40						3.00	
120pF					2.40						3.00	
130pF					2.40						3.00	
150pF					2.40						3.00	
160pF					2.40						3.00	
180pF					2.40						3.00	
200pF					2.40						3.00	

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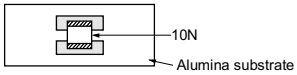
Part Number	GRH110	GRH111					RPN110	RPN111				
L x W(mm)	1.40x1.40	2.80x2.80					1.60x1.40	3.20x2.80				
TC Code	C0G	C0G					C0G	C0G				
Rated Volt.(Vdc)	50	50	100	200	300	500	50	50	100	200	300	500
Capacitance and T(mm)												
220pF				2.40						3.00		
240pF				2.40						3.00		
270pF				2.40						3.00		
300pF				2.40						3.00		
330pF				2.40						3.00		
360pF				2.40						3.00		
390pF				2.40						3.00		
430pF				2.40						3.00		
470pF				2.40						3.00		
510pF			2.40						3.00			
560pF			2.40						3.00			
620pF			2.40						3.00			
680pF			2.40						3.00			
750pF		2.40						3.00				
820pF		2.40						3.00				
910pF		2.40						3.00				
1000pF		2.40						3.00				

Specifications and Test Methods

No.	Item		Specification	Test Method
1	Operating Temperature Range		−55℃ to +125℃	
2	Rated Voltage		See the previous pages.	The rated voltage is defined as the maximum voltage which may be applied continuously to the capacitor. When AC voltage is superimposed on DC voltage, V^{P-P} or V^{O-P}, whichever is larger, shall be maintained within the rated voltage range.
3	Appearance		No defects or abnormalities.	Visual inspection.
4	Dimensions		Within the specified dimension.	Using calipers.
5	Dielectric Strength		No defects or abnormalities.	No failure shall be observed when 250% of the rated voltage is applied between the terminations for 1 to 5 seconds, provided the charge/discharge current is less than 50mA.
6	Insulation Resistance (I.R.)	25℃	C≦ 470pF :1,000,000MΩ min. 470pF<C≦1,000pF : 100,000MΩ min.	The insulation resistance shall be measured with a DC voltage not exceeding the rated voltage at 25℃ and 125℃ standard humidity and within 2 minutes of charging.
		125℃	C≦ 470pF : 100,000MΩ min. 470pF<C≦1,000pF : 10,000MΩ min.	
7	Capacitance		Within the specified tolerance.	The capacitance/Q shall be measured at 25℃ at the frequency and voltage shown in the table. Item / Char. | C0G (1,000pF and below) Frequency | 1±0.1MHz Voltage | 0.5 to 5Vr.m.s.
8	Q		C≦ 220pF : Q≧10,000 220pF<C≦ 470pF : Q≧ 5,000 470pF<C≦1,000pF : Q≧ 3,000 C : Nominal Capacitance (pF)	
9	Capacitance Temperature Characteristics	Capacitance Variation Rate	Within the specified tolerance. (Table A-7)	The temperature coefficient is determined using the capacitance measured in step 3 as a reference. When cycling the temperature sequentially from step 1 through 5, the capacitance shall be within the specified tolerance for the temperature coefficient and capacitance change as Table A. The capacitance drift is calculated by dividing the differences between the maximum and minimum measured values in the step 1, 3 and 5 by the cap. value in step 3. The capacitance change shall be measured after 5 min. at each specified temperature stage. Step | Temperature(℃) 1 | 25±2 2 | −55±3 3 | 25±2 4 | 125±3 5 | 25±2
		Temperature Coefficient	Within the specified tolerance. (Table A-7)	
		Capacitance Drift	Within ±0.2% or ±0.05pF (Whichever is larger)	
10	Terminal Strength	Adhesive Strength of Termination (for chip type)	No removal of the terminations or other defects shall occur.	Solder the capacitor to the test jig (alumina substrate) shown in Fig.1 using solder containing 2.5% silver. The soldering shall be done either with an iron or in furnace and be conducted with care so the soldering is uniform and free of defects such as heat shock. Then apply a 10N force in the direction of the arrow.  Fig.1
		Tensile Strength (for micro-strip type)	Capacitor shall not be broken or damaged.	The capacitor body is fixed and a load is applied gradually in the axial direction until its value reaches 10N (5N for RPN110).
		Bending Strength of lead wire terminal (for micro-strip type)	Lead wire shall not be cut or broken.	Position the main body of the capacitor so the lead wire terminal is perpendicular, and load 2.5N to the lead wire terminal. Bend the main body by 90 degrees, bend back to original position, bend 90 degrees in the reverse direction, and then bend back to original position.

Continued on the following page.

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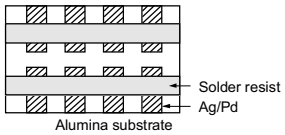
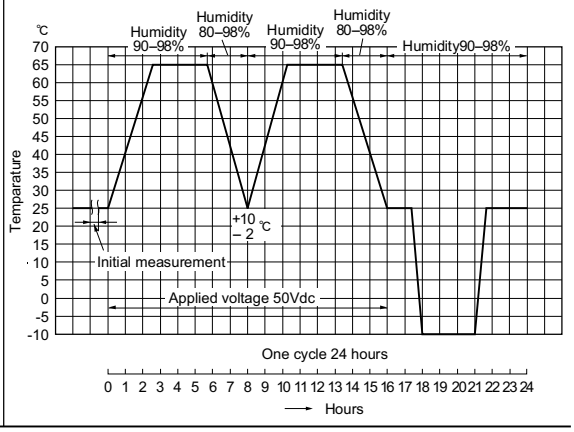
Specifications and Test Methods

Continued from the preceding page.

No.	Item		Specification	Test Method
11	Vibration Resistance	Appearance	No defects or abnormalities.	Solder the capacitor to the test jig (alumina substrate) shown in Fig.2 using solder containing 2.5% silver. The soldering shall be done either with an iron or using the reflow method and shall be conducted with care so the soldering is uniform and free of defects such as heat shock.The capacitor shall be subjected to a simple harmonic motion having a total amplitude of 1.5mm, the frequency being varied uniformly between the approximate limits of 10 and 55Hz. The frequency range, from 10 to 55Hz and return to 10Hz, shall be traversed in approximately 1 minute. This motion shall be applied for a period of 2 hours in each 3 mutually perpendicular directions (total of 6 hours).  Fig. 2
		Capacitance	Within the specified tolerance.	
		Q	Satisfies the initial value. C≦ 220pF : Q≧10,000 220pF<C≦ 470pF : Q≧ 5,000 470pF<C≦1,000pF : Q≧ 3,000 C : Nominal Capacitance (pF)	
12	Solderability of Termination		95% of the terminations is to be soldered evenly and continuously.	Immerse the capacitor in a solution of ethanol (JIS-K-8101) and rosin (JIS-K-5902) (25% rosin in weight proportion). Preheat at 80 to 120℃ for 10 to 30 seconds. After preheating immerse in solder containing 2.5% silver for 5±0.5 seconds at 230±5℃. The dipping depth for microstrip type capacitors is up to 1 mm from the root of the terminal.
13	Resistance to Soldering Heat		The measured and observed characteristics shall satisfy the specifications in the following table. Item / Specification Appearance: No marked defect Capacitance Change: Within ±2.5% or ±0.25pF (Whichever is larger) Q: C≦ 220pF : Q≧10,000; 220pF<C≦ 470pF : Q≧ 5,000; 470pF<C≦1,000pF : Q≧ 3,000 I.R.: More than 30% of the initial specification value at 25℃. Dielectric Strength: No failure C : Nominal Capacitance (pF)	Preheat the capacitor at 80 to 100℃ for 2 minutes and then at 150 to 200℃ for 5 minutes. Immerse in solder containing 2.5% silver for 3±0.5 seconds at 270±5℃. Set at room temperature for 24±2 hours, then measure. The dipping depth for microstrip type capacitors is up to 2mm from the root of the terminal.
14	Temperature Cycle		The measured and observed characteristics shall satisfy the specifications in the following table. Item / Specification Appearance: No marked defect Capacitance Change: Within ±1% or ±0.25pF (Whichever is larger) Q: C≦ 220pF : Q≧10,000; 220pF<C≦ 470pF : Q≧ 5,000; 470pF<C≦1,000pF : Q≧ 3,000 I.R.: More than 30% of the initial specification value at 25℃. Dielectric Strength: No failure C : Nominal Capacitance (pF)	Fix the capacitor to the supporting jig in the same manner and under the same conditions as (11). Perform the five cycles according to the four heat treatments listed in the following table. Then, repeat twice the successive cycles of immersion, each cycle consisting of immersion in a fresh water at 65 $^{+5}_{-0}$℃ for 15 minutes and immersion in a saturated uqueous solution of salt at 0±3℃ for 15 minutes. The cpapcitor is promptly washed with running water, dried with a dry cloth, and allowed to sit at room temperature for 24±2 hours. Step / 1 / 2 / 3 / 4 Temp.(℃) / -55^{+0}_{-3} / RoomTemp. / 125^{+3}_{-0} / RoomTemp. Time(min.) / 30±3 / 2 to 3 / 30±3 / 2 to 3
15	Humidity		The measured and observed characteristics shall satisfy the specifications in the following table. Item / Specification Appearance: No marked defect Capacitance Change: Within ±5% or ±0.5pF (Whichever is larger) Q: C≦ 220pF : Q≧10,000; 220pF<C≦ 470pF : Q≧ 5,000; 470pF<C≦1,000pF : Q≧ 3,000 I.R.: More than 30% of the initial specification value at 25℃. C : Nominal Capacitance (pF)	Apply the 24-hour heat (−10 to +65℃) and humidity (80 to 98%) treatment shown below, 10 consecutive times. Remove, set for 24±2 hours at room temperature, and measure. 

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11

Specifications and Test Methods

Continued from the preceding page.

No.	Item	Specification	Test Method
16	High Temperature Load	The measured and observed characteristics shall satisfy the specifications in the following table. Appearance: No marked defect Capacitance Change: Within ±2.5% or ±0.25pF (Whichever is larger) Q: C≦ 220pF : Q≧10,000 220pF<C≦ 470pF : Q≧ 5,000 470pF<C≦1,000pF : Q≧ 3,000 I.R.: More than 30% of the initial specification value at 25℃. C : Nominal Capacitance (pF)	Apply 150% of the rated voltage for 2,000±12 hours at 125±3℃. Remove and set for 24±2 hours at room temperature, then measure. The charge/discharge current is less than 50mA.

Table A

Char.	Temp. Coeff. (ppm/℃) Note 1	Capacitance Change from 25℃ Value (%)					
		−55℃		−30℃		−10℃	
		Max.	Min.	Max.	Min.	Max.	Min.
C0G	0±30	0.58	−0.24	0.40	−0.17	0.25	−0.11

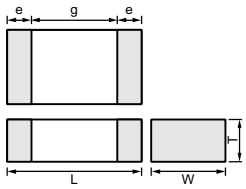
Note 1 : Nominal values denote the temperature coefficient within a range of 25 to 125℃.

CHIP MONOLITHIC CERAMIC CAPACITOR

High-frequency GRH/RPN700 Series

■ Features(GRH700 Series)

1. Negligible inductance is achieved by its monolithic structure so the series can be used at frequencies above 1GHz.
2. Nickel barriered terminations of GRH type improve solderability and decrease solder leaching.
3. GRH706/GRH708 type is designed for both flow and reflow soldering and GRH710 type is designed for reflow soldering.



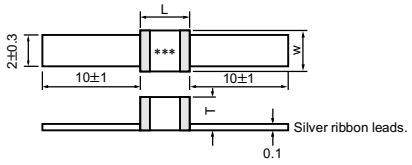
Part Number	Dimensions (mm)				
	L	W	T max.	e	g min.
GRH706	$1.25^{+0.5}_{-0.3}$	$1.0^{+0.5}_{-0.3}$	1.2	0.15 min.	0.3
GRH708	$2.0^{+0.5}_{-0.3}$	$1.25^{+0.5}_{-0.3}$	1.45	0.2 max.	0.5
GRH710	$3.2^{+0.6}_{-0.4}$	$2.5^{+0.5}_{-0.3}$	1.9	0.3 max.	0.5

■ Application

High-frequency and high-power circuits.

■ Features(RPN700 Series)

1. Negligible inductance is achieved by its monolithic structure so the series can be used at frequencies above 1GHz.
2. RPN type capacitors withstand at high temperatures because ribbon leads are attached with silver paste.
3. RPN type capacitors are easily soldered and are especially well suited in applications where only a soldering iron can be used.



*** : Capacitance Code

Part Number	Dimensions (mm)		
	L max.	W max.	T max.
RPN710	4.0	3.0	2.3

■ Application

High-frequency and high-power circuits.

Part Number	GRH706			GRH708			GRH710			RPN710		
L x W(mm)	1.25x1.00			2.00x1.25			3.20x2.50			4.00x3.00		
TC Code	C0G			C0G			C0G			C0G		
Rated Volt.(Vdc)	50	100	200	50	100	200	50	100	200	50	100	200
Capacitance and T(mm)												
0.5pF			1.20			1.45			1.90			2.30
0.6pF			1.20			1.45			1.90			2.30
0.7pF			1.20			1.45			1.90			2.30
0.8pF			1.20			1.45			1.90			2.30
0.9pF			1.20			1.45			1.90			2.30
1.0pF			1.20			1.45			1.90			2.30
1.1pF			1.20			1.45			1.90			2.30
1.2pF			1.20			1.45			1.90			2.30
1.3pF			1.20			1.45			1.90			2.30
1.4pF			1.20			1.45			1.90			2.30
1.5pF			1.20			1.45			1.90			2.30
1.6pF			1.20			1.45			1.90			2.30
1.7pF			1.20			1.45			1.90			2.30
1.8pF			1.20			1.45			1.90			2.30
1.9pF			1.20			1.45			1.90			2.30
2.0pF			1.20			1.45			1.90			2.30
2.1pF			1.20			1.45			1.90			2.30
2.2pF			1.20			1.45			1.90			2.30
2.4pF			1.20			1.45			1.90			2.30
2.7pF			1.20			1.45			1.90			2.30

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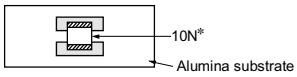
Part Number	GRH706			GRH708			GRH710			RPN710		
L x W(mm)	1.25x1.00			2.00x1.25			3.20x2.50			4.00x3.00		
TC Code	C0G			C0G			C0G			C0G		
Rated Volt.(Vdc)	50	100	200	50	100	200	50	100	200	50	100	200
Capacitance and T(mm)												
3.0pF			1.20			1.45			1.90			2.30
3.3pF			1.20			1.45			1.90			2.30
3.6pF			1.20			1.45			1.90			2.30
3.9pF			1.20			1.45			1.90			2.30
4.3pF			1.20			1.45			1.90			2.30
4.7pF			1.20			1.45			1.90			2.30
5.1pF			1.20			1.45			1.90			2.30
5.6pF			1.20			1.45			1.90			2.30
6.2pF			1.20			1.45			1.90			2.30
6.8pF			1.20			1.45			1.90			2.30
7.5pF			1.20			1.45			1.90			2.30
8.2pF			1.20			1.45			1.90			2.30
9.1pF			1.20			1.45			1.90			2.30
10pF			1.20			1.45			1.90			2.30
11pF			1.20			1.45			1.90			2.30
12pF			1.20			1.45			1.90			2.30
13pF			1.20			1.45			1.90			2.30
15pF		1.20				1.45			1.90			2.30
16pF		1.20				1.45			1.90			2.30
18pF		1.20				1.45			1.90			2.30
20pF		1.20				1.45			1.90			2.30
22pF		1.20				1.45			1.90			2.30
24pF	1.20					1.45			1.90			2.30
27pF	1.20					1.45			1.90			2.30
30pF	1.20					1.45			1.90			2.30
33pF	1.20					1.45			1.90			2.30
36pF	1.20					1.45			1.90			2.30
39pF	1.20					1.45			1.90			2.30
43pF	1.20					1.45			1.90			2.30
47pF	1.20					1.45			1.90			2.30
51pF	1.20					1.45			1.90			2.30
56pF					1.45				1.90			2.30
62pF					1.45				1.90			2.30
68pF					1.45				1.90			2.30
75pF					1.45				1.90			2.30
82pF					1.45				1.90			2.30
91pF					1.45				1.90			2.30
100pF				1.45					1.90			2.30
110pF				1.45					1.90			2.30
120pF				1.45					1.90			2.30
130pF				1.45					1.90			2.30
150pF				1.45					1.90			2.30
160pF				1.45					1.90			2.30
180pF								1.90			2.30	
200pF								1.90			2.30	
220pF								1.90			2.30	
240pF								1.90			2.30	
270pF								1.90			2.30	
300pF								1.90			2.30	
330pF								1.90			2.30	
360pF								1.90			2.30	
390pF								1.90			2.30	
430pF								1.90			2.30	
470pF								1.90			2.30	

Continued on the following page.

Continued from the preceding page.

Part Number	GRH706			GRH708			GRH710			RPN710		
L x W(mm)	1.25x1.00			2.00x1.25			3.20x2.50			4.00x3.00		
TC Code	C0G			C0G			C0G			C0G		
Rated Volt.(Vdc)	50	100	200	50	100	200	50	100	200	50	100	200
Capacitance and T(mm)												
510pF								1.90			2.30	
560pF							1.90			2.30		
620pF							1.90			2.30		
680pF							1.90			2.30		
750pF							1.90			2.30		
820pF							1.90			2.30		
910pF							1.90			2.30		
1000pF							1.90			2.30		

Specifications and Test Methods

No.	Item		Specification	Test Method
1	Operating Temperature Range		−55℃ to +125℃	
2	Rated Voltage		See the previous pages.	The rated voltage is defined as the maximum voltage which may be applied continuously to the capacitor. When AC voltage is superimposed on DC voltage, V^{P-P} or V^{O-P}, whichever is larger, shall be maintained within the rated voltage range.
3	Appearance		No defects or abnormalities.	Visual inspection.
4	Dimensions		Within the specified dimension.	Using calipers.
5	Dielectric Strength		No defects or abnormalities.	No failure shall be observed when 300% of the rated voltage is applied between the terminations for 1 to 5 seconds, provided the charge/discharge current is less than 50mA.
6	Insulation Resistance (I.R.)		10,000MΩ min.	The insulation resistance shall be measured with a DC voltage not exceeding the rated voltage at 25℃ and standard humidity and within 2 minutes of charging.
7	Capacitance		Within the specified tolerance.	The capacitance/Q shall be measured at 25℃ at the frequency and voltage shown in the table. Item / Char. | C0G (1,000pF and below) Frequency | 1±0.1MHz Voltage | 0.5 to 5Vr.m.s.
8	Q		C≦ 220pF : Q≧10,000 220pF<C≦ 470pF : Q≧ 5,000 470pF<C≦1,000pF : Q≧ 3,000 C : Nominal Capacitance (pF)	
9	Capacitance Temperature Characteristics	Capacitance Variation Rate	Within the specified tolerance. (Table A-6)	The temperature coefficient is determined using the capacitance measured in step 3 as a reference. When cycling the temperature sequentially from step 1 through 5, the capacitance shall be within the specified tolerance for the temperature coefficient and capacitance change as Table A. The capacitance drift is calculated by dividing the differences between the maximum and minimum measured values in the step 1, 3 and 5 by the cap. value in step 3. The capacitance change shall be measured after 5 min. at each specified temperature stage. Step | Temperature(℃) 1 | 25±2 2 | −55±3 3 | 25±2 4 | 125±3 5 | 25±2
		Temperature Coefficient	Within the specified tolerance. (Table A-6)	
		Capacitance Drift	Within ±0.2% or ±0.05pF (Whichever is larger)	
10	Terminal Strength	Adhesive Strength of Termination (for chip type)	No removal of the terminations or other defects shall occur.	Solder the capacitor to the test jig (alumina substrate) shown in Fig.1 using solder containing 2.5% silver. The soldering shall be done either with an iron or in furnace and be conducted with care so the soldering is uniform and free of defects such as heat shock. Then apply a 10N* force in the direction of the arrow. *5N (GRH 706)  Fig.1
		Tensile Strength (for micro-strip type)	Capacitor shall not be broken or damaged.	The capacitor body is fixed and a load is applied gradually in the axial direction until its value reaches 5N.
		Bending Strength of lead wire terminal (for micro-strip type)	Lead wire shall not be cut or broken.	Position the main body of the capacitor so the lead wire terminal is perpendicular, and load 2.5N to the lead wire terminal. Bend the main body by 90 degrees, bend back to original position, bend 90 degrees in the reverse direction, and then bend back to original position.

Continued on the following page.

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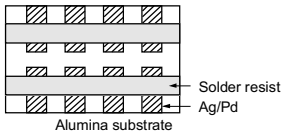
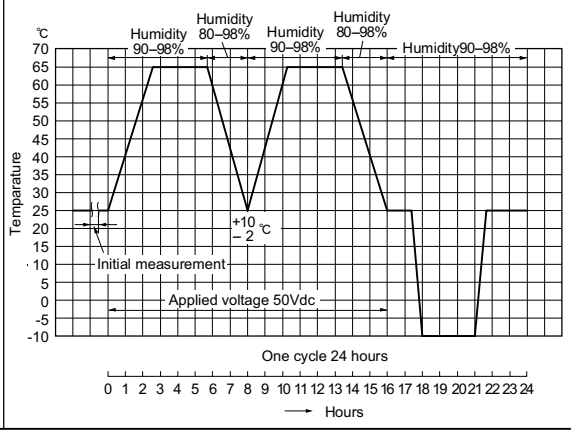
Specifications and Test Methods

Continued from the preceding page.

No.	Item		Specification	Test Method
11	Vibration Resistance	Appearance	No defects or abnormalities.	Solder the capacitor to the test jig (alumina substrate) shown in Fig.2 using solder containing 2.5% silver. The soldering shall be done either with an iron or using the reflow method and shall be conducted with care so the soldering is uniform and free of defects such as heat shock.The capacitor shall be subjected to a simple harmonic motion having a total amplitude of 1.5mm, the frequency being varied uniformly between the approximate limits of 10 and 55Hz. The frequency range, from 10 to 55Hz and return to 10Hz, shall be traversed in approximately 1 minute. This motion shall be applied for a period of 2 hours in each 3 mutually perpendicular directions (total of 6 hours).  Fig.2
		Capacitance	Within the specified tolerance.	
		Q	Satisfies the initial value. C≦ 220pF : Q≧10,000 220pF<C≦ 470pF : Q≧ 5,000 470pF<C≦1,000pF : Q≧ 3,000 C : Nominal Capacitance (pF)	
12	Solderability of Termination		75% of the terminations is to be soldered evenly and continuously.	Immerse the capacitor in a solution of ethanol (JIS-K-8101) and rosin (JIS-K-5902) (25% rosin in weight proportion). Preheat at 80 to 120℃ for 10 to 30 seconds. After preheating immerse in solder containing 2.5% silver for 5±0.5 seconds at 230±5℃. The dipping depth for microstrip type capacitors is up to 1 mm from the root of the terminal.
13	Resistance to Soldering Heat		The measured and observed characteristics shall satisfy the specifications in the following table. Item / Specification Appearance / No marked defect Capacitance Change / Within ±2.5% or ±0.25pF (Whichever is larger) Q / C≦ 220pF : Q≧10,000; 220pF<C≦ 470pF : Q≧ 5,000; 470pF<C≦1,000pF : Q≧ 3,000 Dielectric Strength / No failure C : Nominal Capacitance (pF)	Preheat according to the conditions listed in the table below. Immerse in solder containing 2.5% silver for 3±0.5 seconds at 270±5℃. Set at room temperature for 24±2 hours, then measure. The dipping depth for microstrip type capacitors is up to 2mm from the root of the terminal. Chip Size / Preheat Condition 2.0×1.25mm max. / 1minute at 120 to 150℃ 3.2×2.5mm / Each 1 minute at 100 to 120℃ and then 170 to 200℃
14	Temperature Cycle		The measured and observed characteristics shall satisfy the specifications in the following table. Item / Specification Appearance / No marked defect Capacitance Change / Within ±5% or ±0.5pF (Whichever is larger) Q / C≧30pF : Q≧350; 10pF≦C<30pF : Q≧275+ 5/2 C; C<10pF : Q≧200+10C I.R. / 1,000MΩ min. Dielectric Strength / No failure C : Nominal Capacitance (pF)	Fix the capacitor to the supporting jig in the same manner and under the same conditions as (11). Perform the five cycles according to the four heat treatments listed in the following table. Let sit for 24±2 hours at room temperature, then measure. Step / 1 / 2 / 3 / 4 Temp.(℃) / −55 +0 −3 / RoomTemp. / 125 +3 −0 / RoomTemp. Time(min.) / 30±3 / 2 to 3 / 30±3 / 2 to 3
15	Humidity		The measured and observed characteristics shall satisfy the specifications in the following table. Item / Specification Appearance / No marked defect Capacitance Change / Within ±5% or ±0.5pF (Whichever is larger) Q / C≧30pF : Q≧350; 10pF≦C<30pF : Q≧275+ 5/2 C; C<10pF : Q≧200+10C I.R. / 1,000MΩ min. C : Nominal Capacitance (pF)	Apply the 24-hour heat (−10 to +65℃) and humidity (80 to 98%) treatment shown below, 10 consecutive times. Remove, set for 24±2 hours at room temperature, and measure. 

Continued on the following page.

12

Specifications and Test Methods

Continued from the preceding page.

<table>
<tr><th>No.</th><th>Item</th><th>Specification</th><th>Test Method</th></tr>
<tr><td>16</td><td>High Temperature Load</td><td>The measured and observed characteristics shall satisfy the specifications in the following table.
<table>
<tr><th>Item</th><th>Specification</th></tr>
<tr><td>Appearance</td><td>No marked defect</td></tr>
<tr><td>Capacitance Change</td><td>Within ±3% or ±0.3pF (Whichever is larger)</td></tr>
<tr><td>Q</td><td>C≧30pF : Q≧350
10pF≦C<30pF : Q≧275+$\frac{5}{2}$C
C<10pF : Q≧200+10C</td></tr>
<tr><td>I.R.</td><td>1,000MΩ min.</td></tr>
</table>
C : Nominal Capacitance (pF)</td><td>Apply 200% of the rated voltage for 1,000±12 hours at 125±3℃.
Remove and set for 24±2 hours at room temperature, then measure.
The charge/discharge current is less than 50mA.</td></tr>
</table>

Table A

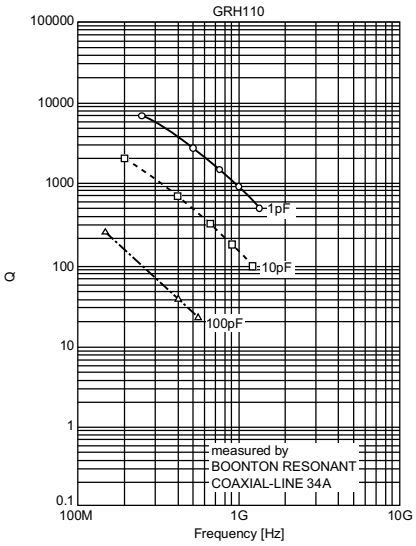
Char.	Temperature Coefficient (ppm/℃) Note 1	Capacitance Change from 25℃ Value (%)					
		−55℃		−30℃		−10℃	
		Max.	Min.	Max.	Min.	Max.	Min.
C0G	0±30	0.58	−0.24	0.40	−0.17	0.25	−0.11

Note 1 : Nominal values denote the temperature coefficient within a range of 25 to 125℃.

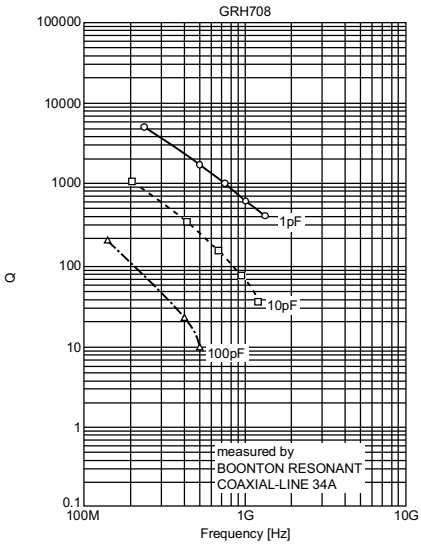
GRH/RPN Series Data

■ Q-Frequency Characteristics

GRH100 Series

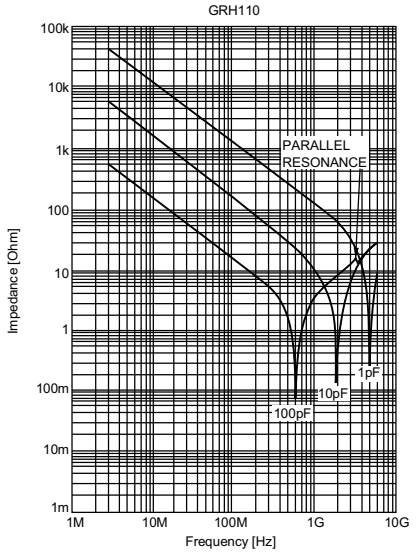


GRH700 Series

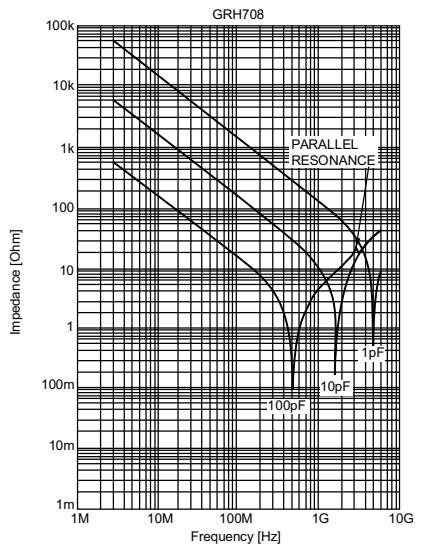


■ Impedance-Frequency Characteristics

GRH100 Series

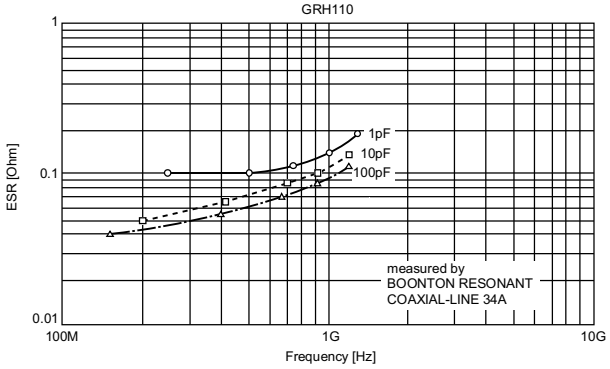


GRH700 Series

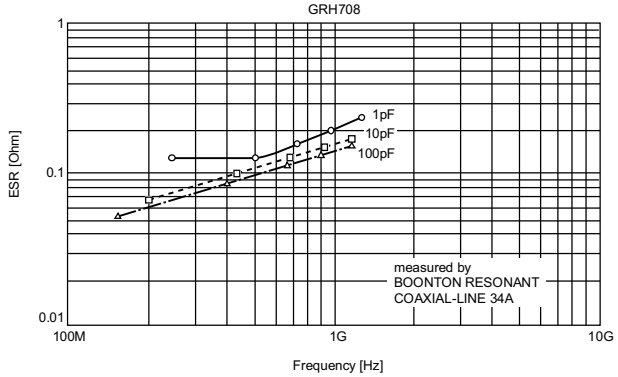


■ ESR-Frequency Characteristics

GRH100 Series



GRH700 Series



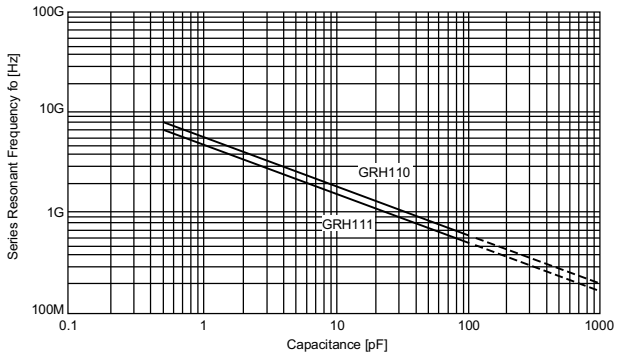
Continued on the following page.

GRH/RPN Series Data

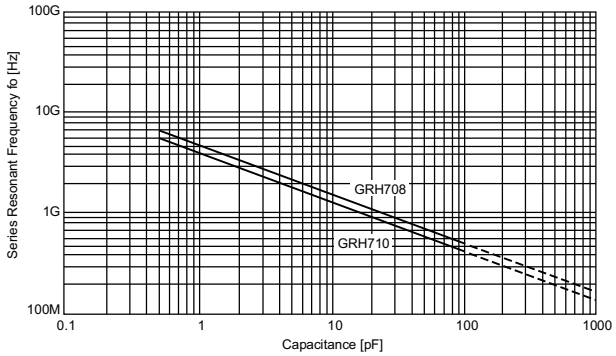
Continued from the preceding page.

■ Resonant Frequency-Capcitance

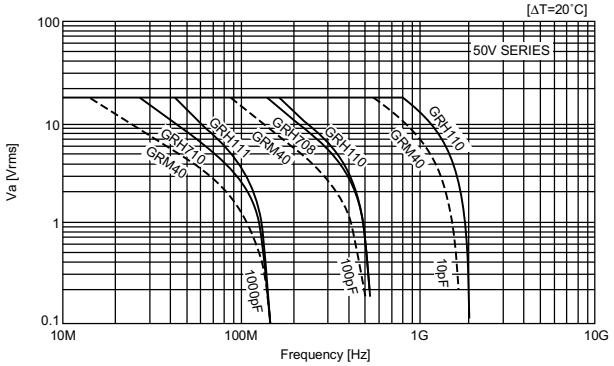
GRH100 Series



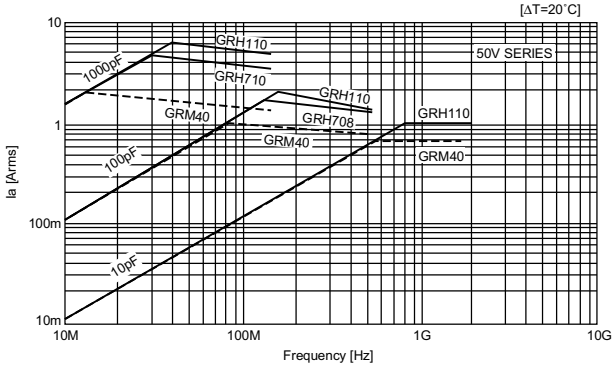
GRH700 Series



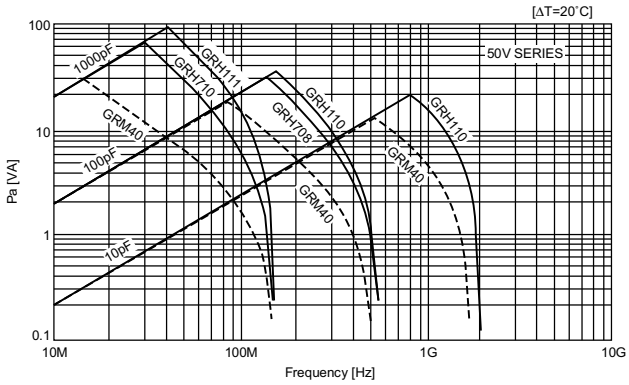
■ Allowable Voltage-Frequency



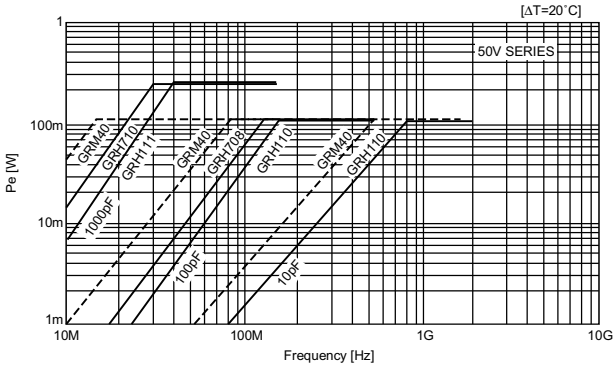
■ Allowable Current-Frequency



■ Allowable Appearent Power-Frequency



■ Allowable Effcteve Power-Frequency



■ Packaging Code

Packaging Type	Tape Carrier Packaging	Bulk Case Packaging	Bulk Packaging	
			Bulk Packaging in a bag	Bulk Packaging in a tray
Packaging Code	PT	PC	PB	PM

■ Minimum Quantity Guide

Part Number		Dimensions (mm)			Quantity (pcs.)					
					ϕ180mm reel		ϕ330mm reel		Bulk Case	Bulk Bag
		L	W	T	Paper Tape	Plastic Tape	Paper Tape	Plastic Tape		
Ultra-miniaturized	GRM33	0.6	0.3	0.3	15,000	-	-	-	-	1,000
For Flow/Reflow	GRM36	1.0	0.5	0.5	10,000	-	50,000	-	50,000	1,000
	GRM39	1.6	0.8	0.8	4,000	-	10,000	-	15,000 [1]	1,000 [1]
	GRM40	2.0	1.25	0.6	4,000	-	10,000	-	10,000	1,000
				0.85	4,000	-	10,000	-	-	1,000
				1.25	-	3,000	-	10,000	5,000	1,000
	GRM42-6	3.2	1.6	0.85	4,000	-	10,000	-	-	1,000
				1.15	-	3,000	-	10,000	-	1,000
				1.6	-	2,000	-	6,000	-	1,000
For Reflow	GRM42-2	3.2	2.5	1.15	-	3,000	-	10,000	-	1,000
				1.35	-	2,000	-	8,000	-	1,000
				1.8	-	1,000	-	4,000	-	1,000
				2.5	-	1,000	-	4,000	-	1,000
	GRM43-2	4.5	3.2	2.0	-	1,000	-	4,000 [2]	-	1,000
	GRM44-1	5.7	5.0	2.0	-	1,000	-	4,000 [2]	-	1,000
High-power Type	GRM615	1.0	0.5	0.5	10,000	-	50,000	-	50,000	1,000
Low-distortion Series	GRM420	1.6	0.8	0.8	4,000	-	10,000	-	-	1,000
	GRM425	2.0	1.25	0.7	4,000	-	10,000	-	-	1,000
				1.0	4,000	-	10,000	-	-	1,000
	GRM430	3.2	1.6	0.7	4,000	-	10,000	-	-	1,000
				1.0	4,000	-	10,000	-	-	1,000
				1.25	-	3,000	-	10,000	-	1,000
	GRM435	4.5	2.5	2.0	-	1,000	-	4,000	-	1,000
High-frequency	GRQ706	1.6	0.8	0.8	4,000	-	10,000	-	-	1,000
	GRQ708	2.0	1.25	1.0	4,000	-	10,000	-	-	1,000
	GRH706	1.25	1.0	1.2	-	-	-	-	-	1,000
	GRH708	2.0	1.25	1.45	-	3,000	-	-	-	1,000
	GRH710	3.2	2.5	1.9	-	2,000	-	-	-	1,000
	GRH110	1.4	1.4	1.65	-	2,000	-	-	-	1,000
	GRH111	2.8	2.8	2.8	-	1,000	-	-	-	1,000
For Ultrasonic	GRM40	2.0	1.25	0.85	4,000	-	10,000	-	-	1,000
Micro Chip	GM250	0.5	0.5	0.35	-	-	-	-	-	400 [3]
	GM260	0.8	0.8	0.5	-	-	-	-	-	400 [3]
Array	GNM30-401	3.2	1.6	0.8	4,000	-	10,000	-	-	1,000
Low ESL	LL0306	0.8	1.6	0.6	4,000	-	10,000	-	-	1,000
	LL0508	1.25	2.0	1.0	-	4,000 [4]	-	10,000	-	1,000
	LL0612	1.6	3.2	0.7	-	4,000	-	10,000	-	1,000
				1.25	-	3,000	-	10,000	-	1,000

1) 0.15 µF and 0.22 µF of X7R, 10V rated are available by taping packages only. (Applied to neither bulk case nor bag package.) 560pF of C0G, 50V rated and 0.47µF or 1.0µF of X5R, 6.3V rated are not availalble by bulk case. (Applied to taping or bag packages only.)
2) Depending on capacitance, some products are supplied on the 5,000pcs./reel basis.
3) Tray
4) Depending on capacitance, some products are supplied on the 3,000 pcs./reel basis.

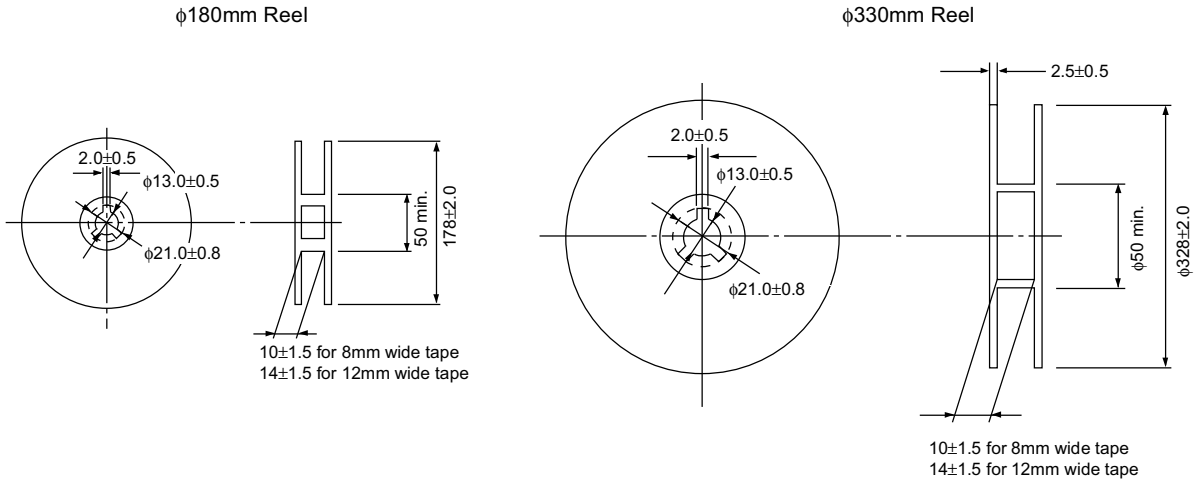
Continued on the following page.

Package

Continued from the preceding page.

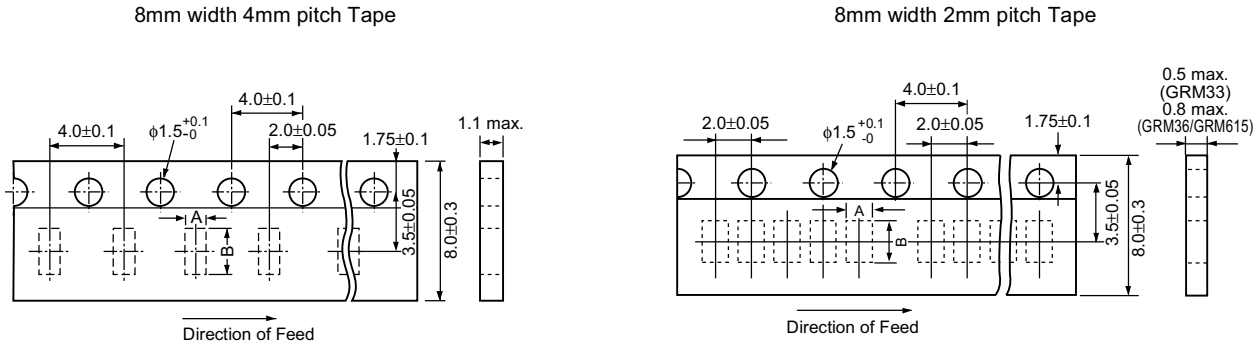
■ Tape Carrier Packaging

(1) Dimensions of Reel



(in mm)

(2) Dimensions of Paper Tape



Part Number	A	B
GR(M)39 **GRM420** **LL0306** **GRQ706**	1.05±0.1	1.85±0.1
GR(M)40 **GRM425** (T≦1.0mm) **GRQ708**	1.55±0.15	2.3±0.15
GR(M)42-6 **GRM430** **GNM30-401** (T≦1.0mm)	2.0±0.2	3.6±0.2
GRM42-2 (T=0.85mm)	2.8±0.2	3.6±0.2

Part Number	A*	B*
GRM33	0.37	0.67
GRM615 **GR(M)36**	0.65	1.15

*Nominal Value

(in mm)

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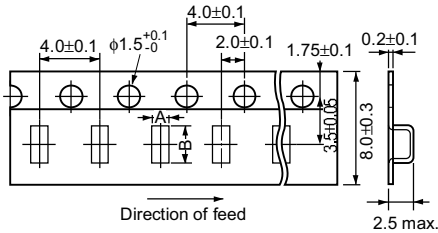
(3) Dimensions of Plastic Tape

8mm width 4mm pitch Tape

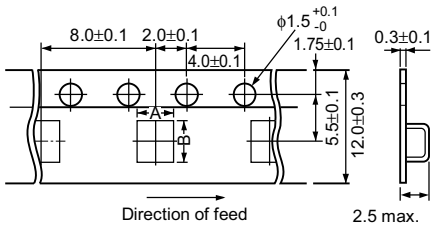


2.5 max.
(3.0 max. T=1.8/2.0 rank)
(3.7 max. for T≦2.5 mm)

Part Number	A	B
GR(M)40 (T=1.25mm) **LL0508**	1.45±0.2	2.25±0.2
GR(M)42-6 GRM430 (T≧1.15mm) **LL0612**	1.9±0.2	3.5±0.2
GRM435 GR(M)42-2 (T≧1.15mm)	2.8±0.2	3.5±0.2
GRH708	1.8*	2.6*
GRH710	2.8*	3.5*
GRH110	2.0*	2.1*
GRH111	3.1*	3.2*

*Nominal Value

12mm width 8mm pitch Tape



2.5 max.
for GR(M)43-2/GR(M)44-1
(3.7 max. for T≧2.5mm)

Part Number	A*	B*
GR(M)43-2	3.6	4.9
GR(M)44-1	5.2	6.1

*Nominal Value

(in mm)

(4) Taping Method

① Tapes for capacitors are wound clockwise. The sprocket holes are to the right as the tape is pulled toward the user.

② Part of the leader and part of the empty tape shall be attached to the end of the tape as follows.

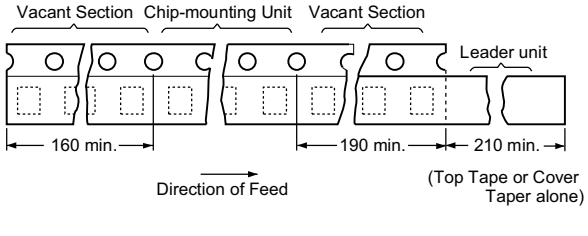
③ The top tape and base tape are not atteached at the end of the tape for a minimum of 5 pitches.

④ Missing capacitors number within 0.1% of the number per reel or 1 pc, whichever is greater, and are not continuous.

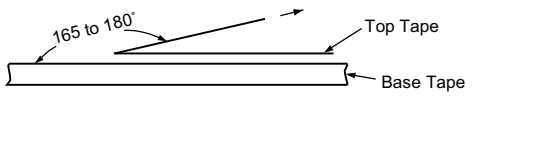
⑤ The top tape and bottom tape shall not protrude beyond the edges of the tape and shall not cover sprocked holes.

⑥ Cumulative tolerance of sprocket holes, 10 pitches : ±0.3mm.

⑦ Peeling off force : 0.1 to 0.6N* in the direction shown below. *GRM33:0.05 to 0.5N



(in mm)



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Package

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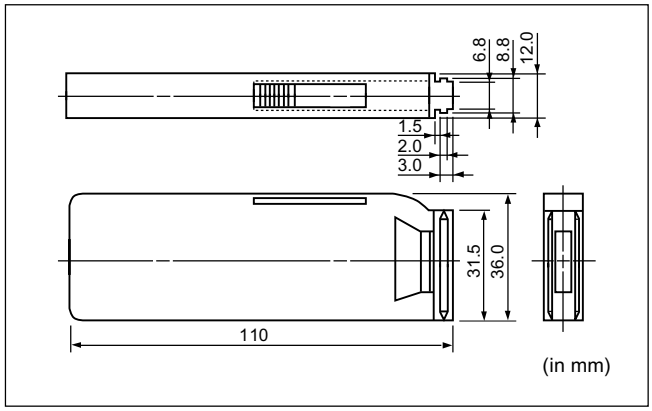
■ Dimensions of Bulk Case Packaging

The bulk case used antistatic materials. Please contact Murata for details.



Notice

■ Storage and Operating Conditions

Chip monolithic ceramic capacitors (chips) can experience degradation of termination solderability when subjected to high temperature or humidity, or if exposed to sulfur or chlorine gases.
(Reference Data 1. Solderability)

■ Rating

Die Bonding/Wire Bonding (GM Series)

(1) Die Bonding of Capacitors

- Use the following materials
  Braze alloy : Au-Si (98/2) 400 to 420D in N2 atmosphere
  Au-Sn (80/20) 300 to 320D in N2 atmosphere
  Au-Ge (88/12) 380 to 400D in N2 atmosphere
- Mounting
  1. Control the temperature of the substrate so that it matches the temperature of the braze alloy.
  2. Place braze alloy on substrate and place the capacitor on the alloy. Hold the capacitor and gently apply the load. Be sure to complete the operation in 1 minute.

(2) Wire Bonding

- Wire
  Gold wire : 20mm (0.0008 inch), 25mm (0.001 inch) diameter
- Bonding
  1. Thermocompression, ultrasonic wedge or ball bonding. Required stage temperature : 150 to 250D.
  2. Required wedge or capillary weight : 0.2N to 0.5N.
  3. Bond the capacitor and base substrate or other devices with gold wire.

■ Handling

1. Inspection
   Thrusting force of the test probe can flex the PCB,resulting in cracked chips or open solder joints. Provide support pins on the back side of the PCB to prevent warping or flexing.
2. Board Separation (or Depane-lization)

- Board flexing at the time of separation causes cracked chips or broken solder.
- Severity of stresses imposed on the chip at the time of board break is in the order of : PushbackFSlitterFV SlotFPerforator.
- Board separation must be performed using special jigs, not with hands.

■ Others

1. Resin Coating
   When selecting resin materials, select those with low contraction.
2. Circuit Design
   These capacitors on this catalog are not safety recognized products
3. Remarks
   The above notices are for standard applications and conditions. Contact us when the products are used in special mounting conditions. Select optimum conditions for operation as they determine the reliability of the product after assembly.
   The data here in are given in typical values, not guaranteed ratings.

■ Soldering and Mounting

1. PCB Design

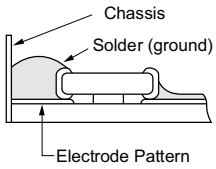
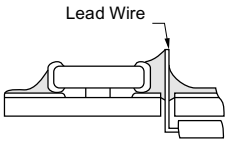
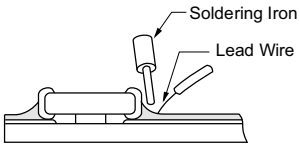
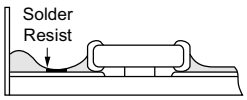
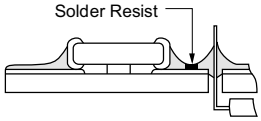
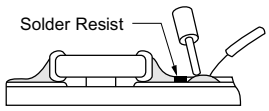
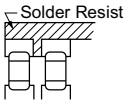
(1) Notice for Pattern Forms

Unlike leaded components, chip components are susceptible to flexing stresses since they are mounted directly on the substrate.

They are also more sensitive to mechanical and thermal stresses than leaded components.

Excess solder fillet height can multiply these stresses and cause chip cracking. When designing substrates, take land patterns and dimensions into consideration to eliminate the possibility of excess solder fillet height.

Pattern Forms

	Placing Close to Chassis	Placing of Chip Components and Leaded Components	Placing of Leaded Components after Chip Component	Lateral Mounting
Incorrect				
Correct				

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Notice

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(2) Land Dimensions

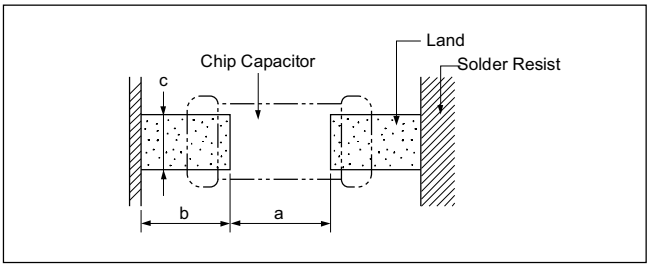

Table 1 Flow Soldering Method

Part Number \ Dimensions	Dimensions (L×W)	a	b	c
GRM39 GRM420 GRQ706	1.6×0.8	0.6—1.0	0.8—0.9	0.6—0.8
GRM40 GRM425 GRQ708	2.0×1.25	1.0—1.2	0.9—1.0	0.8—1.1
GRM42-6 GRM430	3.2×1.6	2.2—2.6	1.0—1.1	1.0—1.4
LL0508	1.25×2.0	0.4—0.7	0.5—0.7	1.4—1.8
LL0612	1.6×3.2	0.6—1.0	0.8—0.9	2.6—2.8
GRH706	1.25×1.0	0.4—0.6	0.6—0.8	0.8—1.0
GRH708	2.0×1.25	1.0—1.2	0.9—1.0	0.8—1.0
GRH110	1.4×1.4	0.5—0.8	0.8—0.9	1.0—1.2

(in mm)

Table 2 Reflow Soldering Method

Part Number \ Dimensions	Dimensions (L×W)	a	b	c
GRM33	0.6×0.3	0.2—0.3	0.2—0.35	0.2—0.4
GRM36 GRM615	1.0×0.5	0.3—0.5	0.35—0.45	0.4—0.6
GRM39 GRM420 GRQ706	1.6×0.8	0.6—0.8	0.6—0.7	0.6—0.8
GRM40 GRM425 GRQ708	2.0×1.25	1.0—1.2	0.6—0.7	0.8—1.1
GRM42-6 GRM430	3.2×1.6	2.2—2.4	0.8—0.9	1.0—1.4
GRM42-2 GRM435	3.2×2.5	2.0—2.4	1.0—1.2	1.8—2.3
GRM43-2	4.5×3.2	3.0—3.5	1.2—1.4	2.3—3.0
GRM44-1	5.7×5.0	4.0—4.6	1.4—1.6	3.5—4.8
LL0306	0.8×1.6	0.2—0.4	0.3—0.4	1.0—1.4
LL0508	1.25×2.0	0.4—0.6	0.3—0.5	1.4—1.8
LL0612	1.6×3.2	0.6—0.8	0.6—0.7	2.6—2.8
GRH706	1.25×1.0	0.4—0.6	0.6—0.8	0.8—1.0
GRH708	2.0×1.25	1.0—1.2	0.6—0.8	0.8—1.0
GRH710	3.2×2.5	2.2—2.5	0.8—1.0	1.9—2.3
GRH110	1.4×1.4	0.4—0.8	0.6—0.8	1.0—1.2
GRH111	2.8×2.8	1.8—2.1	0.7—0.9	2.2—2.6
GR530	4.5×3.8	3.2—3.4	0.9—1.2	3.0—3.8
GR535	5.6×5.0	4.2—4.5	0.9—1.2	4.0—5.0
GR540	10.6×5.0	8.5—9.0	1.3—1.5	4.0—5.0
GR545	10.6×10.0	8.5—9.0	1.3—1.5	8.0—10.0
GR550	11.8×10.6	9.0—9.5	1.8—2.0	8.0—10.0
GR555	16.0×5.0	13.0—13.5	1.8—2.0	4.0—5.0
GR580	28.1×13.2	25.0—25.5	2.2—2.4	10.0—13.0

(in mm)

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Notice

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● GNM Series for reflow soldering method

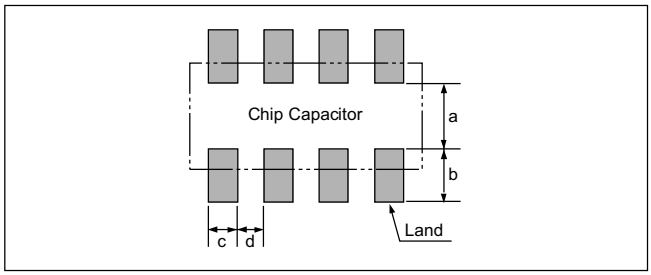
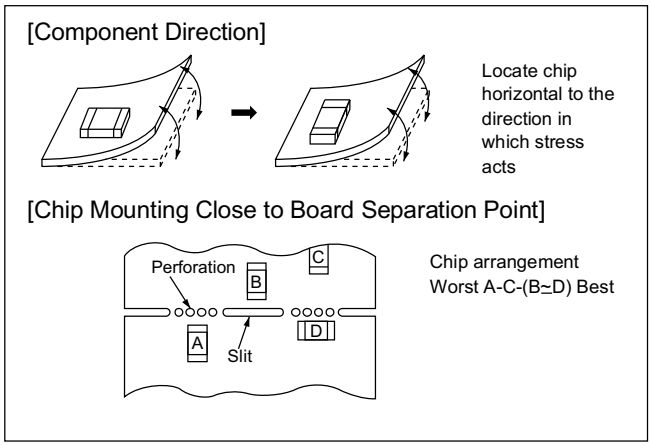


Table 3

Part Number	Dimensions (mm)					
	L	W	a	b	c	d
GNM30-401	3.2	1.6	0.8—1.0	0.7—0.9	0.3—0.4	0.4—0.5

(3) Mounting Position

Choose a mounting position that minimizes the stress imposed on the chip during flexing or bending of the board.



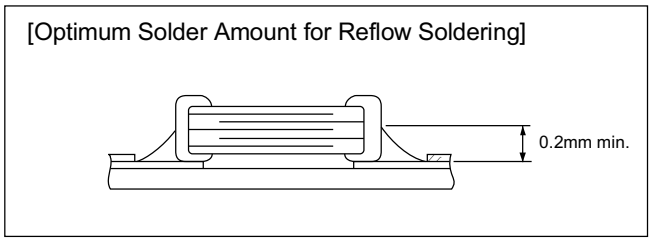
(Reference Data 2. Board bending strength for solder fillet height)
(Reference Data 3. Temperature cycling for solder fillet height)
(Reference Data 4. Board bending strength for board material)

2. Solder Paste Printing

● Overly thick application of solder paste results in excessive fillet height solder.
This makes the chip more susceptible to mechanical and thermal stress on the board and may cause cracked chips.

● Too little solder paste results in a lack of adhesive strength on the outer electrode, which may result in chips breaking loose from the PCB.

● Make sure the solder has been applied smoothly to the end surface to a height of 0.2mm min.



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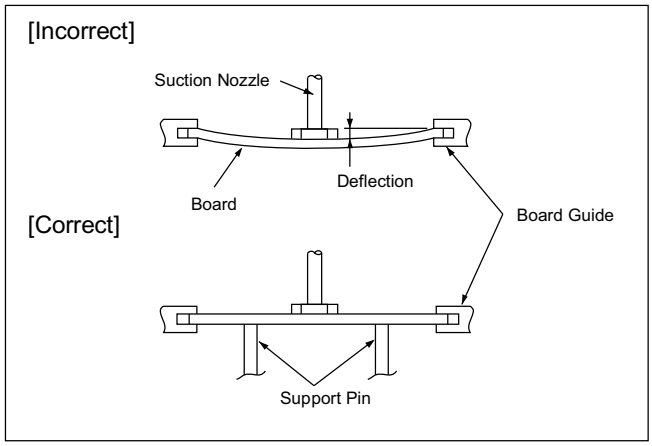
3. Chip Placing

- An excessively low bottom dead point of the suction nozzle imposes great force on the chip during mounting, causing cracked chips. So adjust the suction nozzle's bottom dead point by correcting warp in the board. Normally, the suction nozzle's bottom dead point must be set on the upper surface of the board. Nozzle pressure for chip mounting must be a 1 to 3N static load.
- Dirt particles and dust accumulated between the suction nozzle and the cylinder inner wall prevent the nozzle from moving smoothly. This imposes great force on the chip during mounting, causing cracked chips. And the locating claw, when worn out, imposes uneven forces on the chip when positioning, causing cracked chips. The suction nozzle and the locating claw must be maintained, checked and replaced periodically.

(Reference Data 5. Break strength)



4. Reflow Soldering

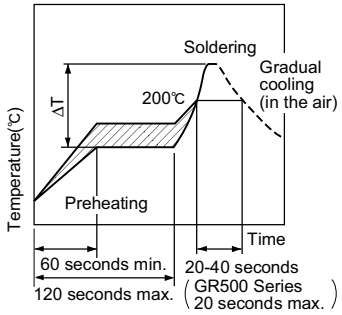
- Sudden heating of the chip results in distortion due to excessive expansion and construction forces within the chip causing cracked chips. So when preheating, keep temperature differential,ΔT, within the range shown in Table 4. The smaller the ΔT, the less stress on the chip.
- When components are immersed in solvent after mounting, be sure to maintain the temperature difference (ΔT) between the component and solvent within the range shown in the above table.

Table 4

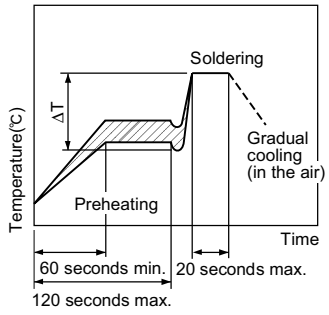
Part Number	Temperature Differential
GRM33/36/39/40/42-6 **GRM420/425/430/615** **LL0306/0508/0612** **GRH706/708/110** **GRQ706/708**	ΔT≦190℃
GRM42-2/43-2/44-1/435 **GNM30-401** **GRH710/111** **GR530/535/540/545/550/555/580**	ΔT≦130℃

[Standard Conditions for Reflow Soldering]

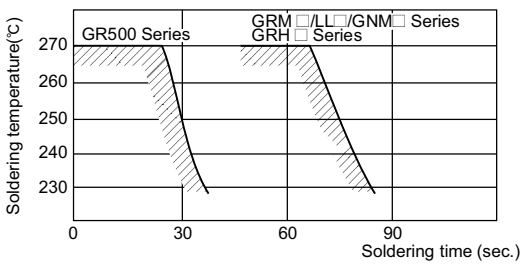
Infrared Reflow



Vapor Reflow



[Allowable Soldering Temperature and Time]



In case of repeated soldering, the accumulated soldering time must be within the range shown above.

Inverting the PCB

Make sure not to impose an abnormal mechanical shock on the PCB.

Continued on the following page.

Notice

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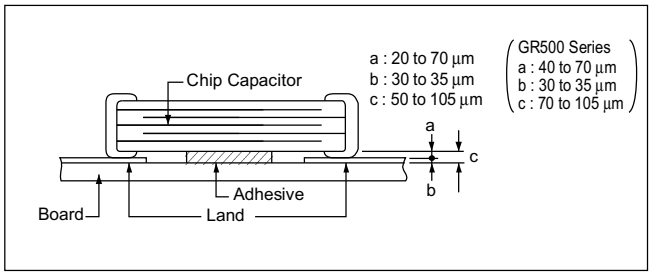
5. Adhesive Application

- Thin or insufficient adhesive causes chips to loosen or become disconnected when flow soldered. The amount of adhesive must be more than dimension C shown in the drawing below to obtain enough bonding strength.
  The chip's electrode thickness and land thickness must be taken into consideration.
- Low viscosity adhesive causes chips to slip after mounting. Adhesive must have a viscosity of 5000pa-s (500ps)min. (at 25℃)



6. Adhesive Curing

Insufficient curing of the adhesive causes chips to disconnect during flow soldering and causes deteriorated insulation resistance between outer electrodes due to moisture absorption.
Control curing temperature and time in order to prevent insufficient hardening.

Inverting the PCB

Make sure not to impose an abnormal mechanical shock on the PCB.

7. Leaded Component Insertion

If the PCB is flexed when leaded components (such as transformers and ICs) are being mounted, chips may crack and solder joints may break.
Before mounting leaded components, support the PCB using backup pins or special jigs to prevent warping.

8. Flux Application

- An excessive amount of flux generates a large quantity of flux gas, causing deteriorated solderability. So apply flux thinly and evenly throughout. (A foaming system is generally used for flow soldering).
- Flux containing too high a percentage of halide may cause corrosion of the outer electrodes unless sufficiently cleaned.Use flux with a halide content of 0.2wt% max.
  But do not use strongly acidix flux.
  Wash thoroughly because water soluble flux causes deteriorated insulation resistance between outer electrodes unless sufficiently cleaned.

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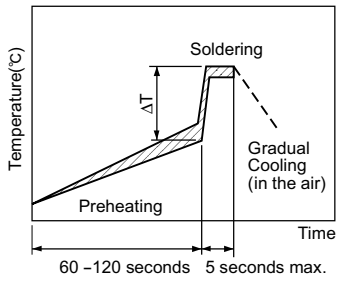
9. Flow Soldering

- Sudden heating of the chip results in thermal distortion causing cracked chips. And an excessively long soldering time or high soldering temperature results in leaching of the outer electrodes, causing poor adhesion or a reduction in capacitance value due to loss of contact between electrodes and end termination.
- When preheating, keep the temperature differential between solder temperature and chip surface temperature, ΔT, within the range shown in Table 5. The smaller the ΔT, the less stress on the chip.
  When components are immersed in solvent after mounting, be sure to maintain the temperature difference between the component and solvent within the range shown in Table 5.
  Do not apply flow soldering to chips not listed in Table 5.

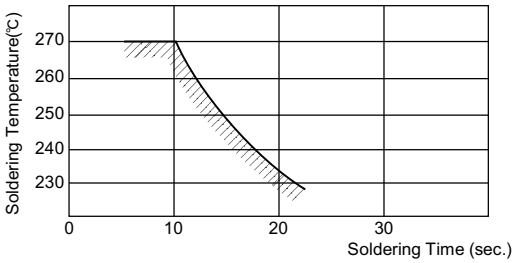
Table 5

Part Number	Temperature Differential
GRM39/40/42-6 **GRM420/425/430** **LL0508/0612** **GRH706/708/110** **GRQ706/708**	ΔT≦150℃

[Standard Conditions for Flow Soldering]

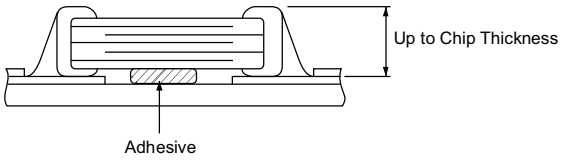


[Allowable Soldering Temperature and Time]



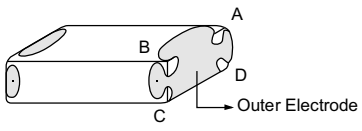
In case of repeated soldering, the accumulated soldering time must be within the range shown above.

- Optimum Solder Amount for Flow Soldering

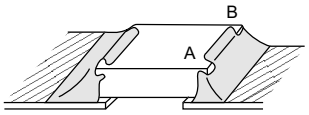


- Set temperature and time to ensure that leaching of the outer electrode does not exceed 25% of the chip end area as a single chip (full length of the edge A-B-C-D shown below) and 25% of the length A-B shown below as mounted on substrate.

[As a Single Chip]



[As Mounted on Substrate]



(Reference Data 6. Thermal shock)

(Reference Data 7. Solder heat resistance)

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Notice

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10. Correction with a Soldering Iron

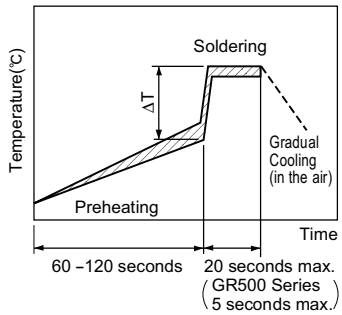
(1) For Chip Type Capacitors

● Sudden heating of the chip results in distortion due to a high internal temperature differential, causing cracked chips. When preheating, keep temperature differential, ΔT, within the range shown in Table 6. The smaller theΔT, the less stress on the chip.

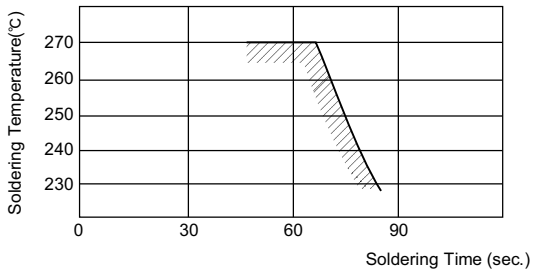
Table 6

Part Number	Temperature Differential
GRM36/39/40/42-6 **GRM420/425/430/615** **LL0306/0508/0612** **GRQ706/708** **GRH706/708/110**	ΔT≦190℃
GRM42-2/43-2/44-1/435 **GNM30-401** **GRH710/111** **GR530/535/540/545/550/555/580**	ΔT≦130℃

[Standard Conditions for Soldering Iron Temperature]

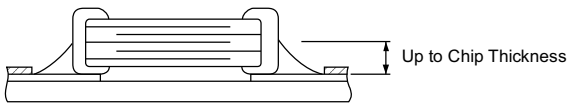


[Allowable Time and Temperature for Making Corrections with a Soldering Iron]



The accumulated soldering Time / temperature including reflow / flow soldering must be within the range shown above.

● Optimum Solder Amount when Corrections Are Made Using a Soldering Iron



● When correcting chips with a soldering iron, no preheating is required if the chip is listed in Table 7 and the following conditions (Table 7) are met.
Preheating should be performed on chips not listed in Table 7.
(Reference Data 8. Thermal shock when making a correction with a soldering iron)

Table 7 Correction with a Soldering Iron

Part Number	Temperature of Iron Tip	Soldering Iron Wattage	Diameter of Iron Tip	Restriction
GRM36/39/40 **GRM420/425/615** **LL0306/0508** **GRQ706/708** **GRH706/708/110**	300℃ max.	20W max.	ϕ 3mm max.	Do not allow the iron tip to directly touch the ceramic element.
GRM42-6 **GRM430** **LL0612** **GNM30-401**	270℃ max.			

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(2) For Microstrip Types

- Solder 1mm away from the ribbon terminal base, being careful that the solder tip does not directly contact the capacitor. Preheating is unnecessary.
- Complete soldering within 3 seconds with a soldering tip less than 270D in temperature.

11. Washing

Excessive output of ultrasonic oscillation during cleaning causes PCBs to resonate, resulting in cracked chips or broken solder. Take note not to vibrate PCBs.

Reference Data

1. Solderability

(1) Test Method

Subject the chip capacitor to the following conditions. Then apply flux (a ethanol solution of 25% rosin) to the chip and dip it in 230℃ eutectic solder for 2 seconds.

Conditions :

Expose prepared at room temperature (for 6 months and 12 months, respectively)

Prepared at high temperature (for 100 hours at 85℃)

Prepared left at high humidity (for 100 hours under 90%RH to 95%RH at 40℃)

(2) Test Samples

GRM40 : Products for flow/reflow soldering.

(3) Acceptance Criteria

With a 60-power optical microscope, measure the surface area of the outer electrode that is covered with solder.

(4) Results

Refer to Table 1.

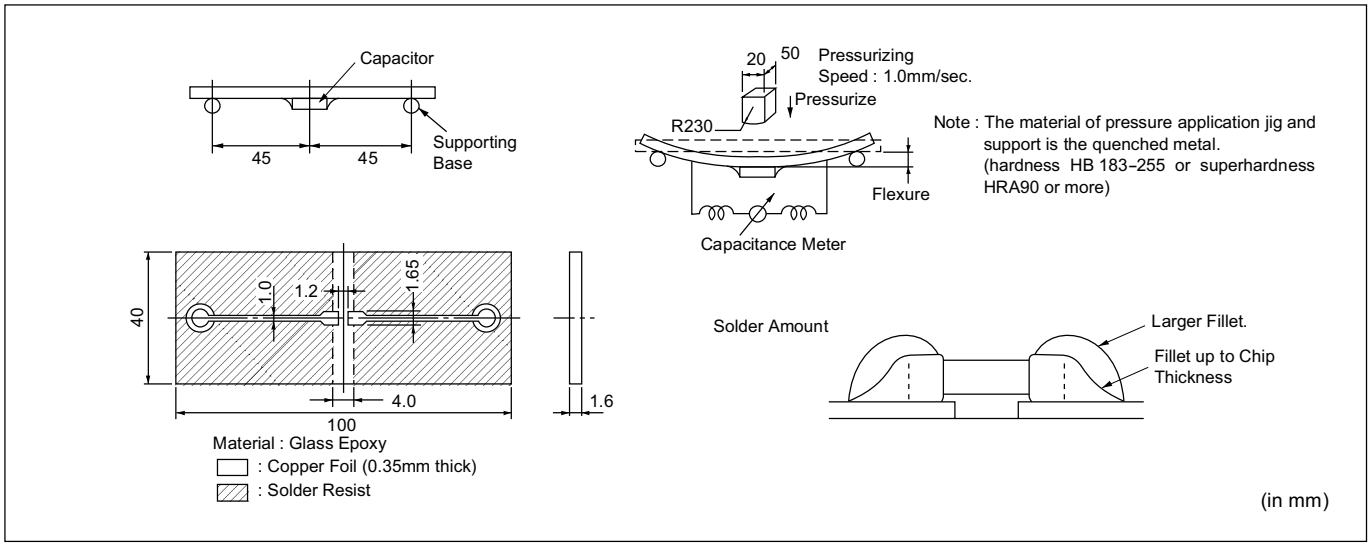
Table 1

Sample	Initial State	Prepared at Room Temperature		Prepared at High Temperature for 100 Hours at 85℃	Prepared at High Humidity for 100 Hours at 90 to 95% RH and 40℃
		6 months	12 months		
GRM40 for flow/reflow soldering	95 to 100%	95 to 100%	95%	90 to 95%	95%

2. Board Bending Strength for Solder Fillet Height

(1) Test Method

Solder the chip capacitor to the test PCB with the amount of solder paste necessary to achieve the fillet heights. Then bend the PCB using the method illustrated and measure capacitance.



(2) Test Samples

GRM40 C0G/X7R/Y5V Characteristics T=0.6mm

(3) Acceptance Criteria

Products shall be determined to be defective if the change in capacitance has exceeded the values specified in Table 2.

Table 2

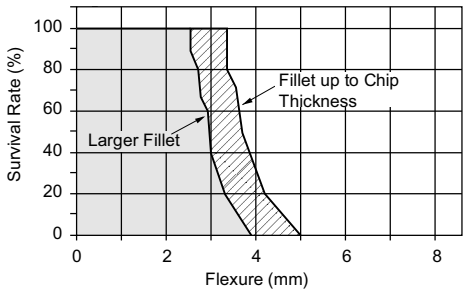
Characteristics	Change in Capacitance
C0G	Within ±5% or ±0.5pF, whichever is greater
X7R	Within ±12.5%
Y5V	Within ±20%

Continued on the following page.

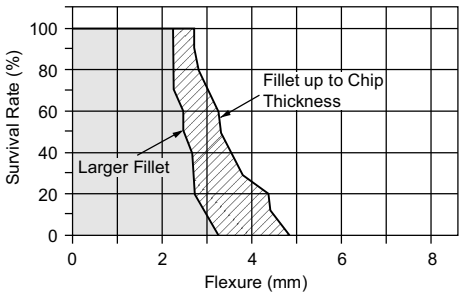
Continued from the preceding page.

(4) Results

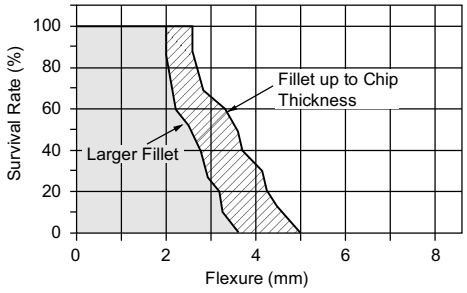
GRM40 C0G (T=0.6)



GRM40 X7R (T=0.6)



GRM40 Y5V (T=0.6)

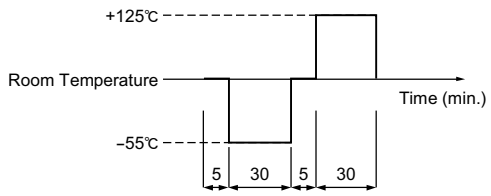


3. Temperature Cycling for Solder Fillet Height

(1) Test Method

Solder the chips to the substrate various test fixtures using sufficient amounts of solder to achieve the required fillet height. Then subject the fixtures to the cycle illustrated below 200 times.

[Temperature Cycling]



① Solder Amount

Alumina substrates are typically designed for reflow soldering.

Glass epoxy or paper phenol substrates are typically used for flow soldering.

② Material

Alumina (Thickness : 0.64mm)

Glass epoxy (Thickness : 1.6 mm)

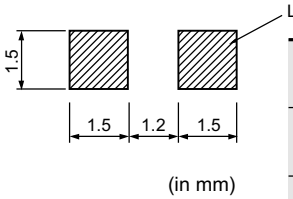
Paper phenol (Thickness : 1.6 mm)

[Solder Amount]

Substrate		Alumina	Glass Epoxy or Paper Phenol
Solder Amount	❶	0.5T	T
	❷	0.7T	1.3T
	❸	T	1.6T
Solder to be used		6×4 Eutectic solder	

③ Land Dimension

[Land Dimension]



Alumina Substrate	Ag/Pd=72/28 Thickness : 10 to 12μm
Glass Epoxy Substrate	Cu Thickness : 35μm
Paper Phenol Substrate	

Continued on the following page.

Reference Data

Continued from the preceding page.

(2) Test Samples

GRM40 C0G/X7R/Y5V Characteristics T=0.6mm

(3) Acceptance Criteria

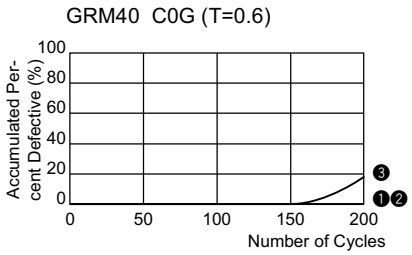
Products shall be determined to be defective if the change in capacitance has exceeded the values specified in Table 3.

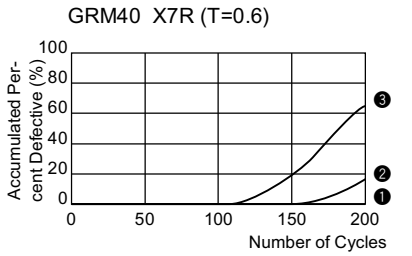
Table 3

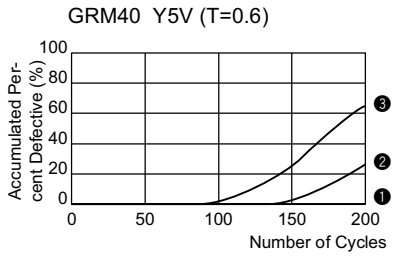
Characteristics	Change in Capacitance
C0G	Within ±2.5% or ±0.25pF, whichever is greater
X7R	Within ±7.5%
Y5V	Within ±20%

(4) Results

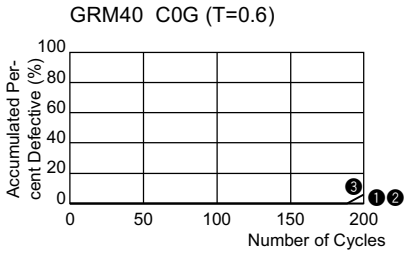
Alumina Substrate

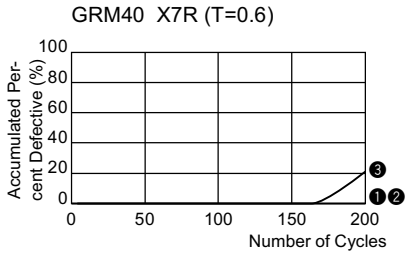


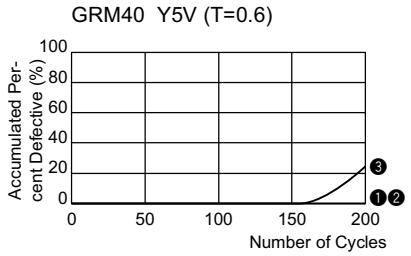




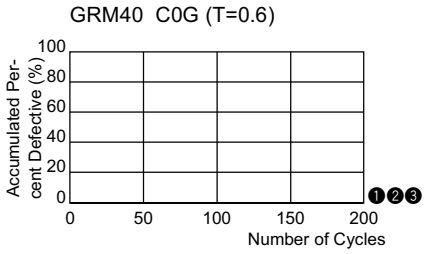
Glass Epoxy Substrate

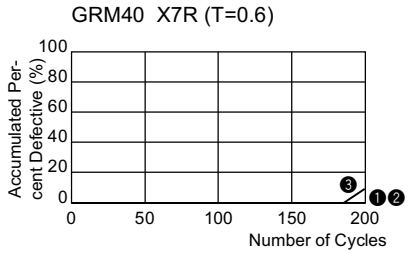


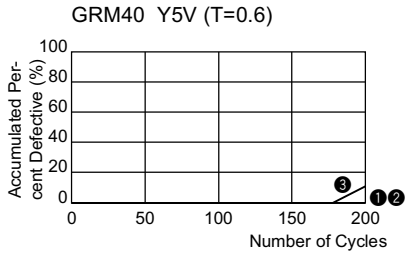




Paper Phenol Substrate







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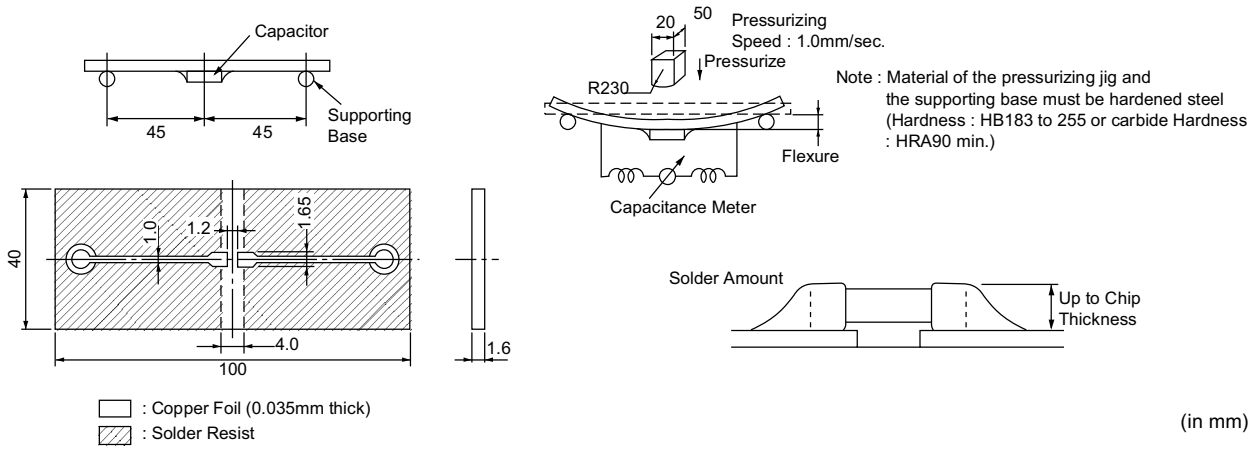
4. Board Bending Strength for Board Material

(1) Test Method

Solder the chip to the test board. Then bend the board using the method illustrated below, as measure capacitance.



(2) Test Samples

GRM40 C0G/X7R/Y5V Characteristics T=0.6mm typical

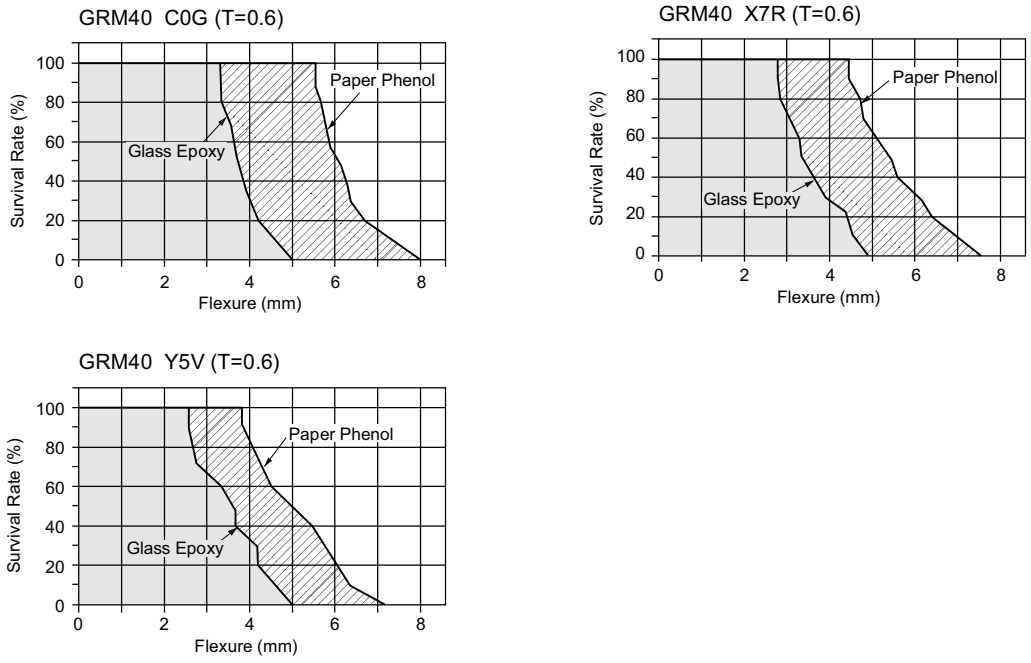
(3) Acceptance Criteria

Products shall be determined to be defective if the change in capacitance has exceeded the values specified in Table 4.

Table 4

Characteristics	Change in Capacitance
C0G	Within ±5% or ±0.5pF, whichever is greater
X7R	Within ±12.5%
Y5V	Within ±20%

(4) Results



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Reference Data

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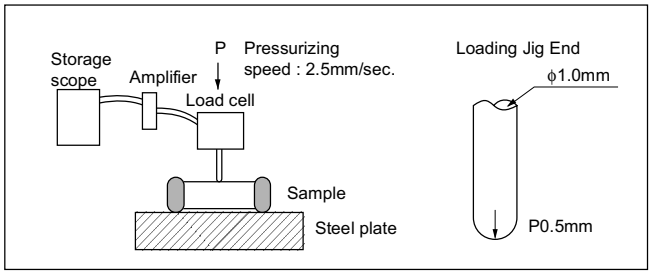
5. Break Strength

(1) Test Method

Place the chip on a steel plate as illustrated on the right. Increase load applied to a point near the center of the test sample.



(2) Test Samples

GRM40 C0G/X7R/Y5V Characteristics
GRM42-6 C0G/X7R/Y5V Characteristics

(3) Acceptance Criteria

Define the load that has caused the chip to break or crack, as the bending force.

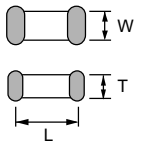
(4) Explanation

Break strength, P, is proportionate to the square of the thickness of the ceramic element and is expressed as a curve of secondary degree.

The formula is :

$$P = \frac{2\gamma WT^2}{3L} \quad (N)$$

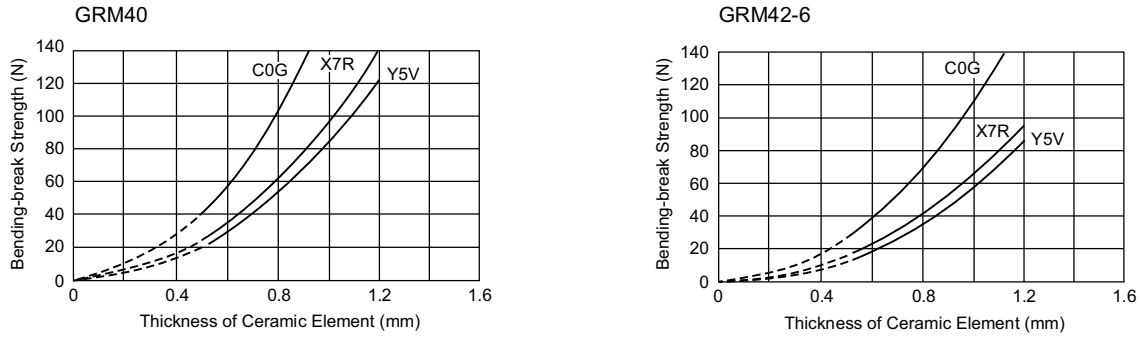
W : Width of ceramic element (mm)
T : Thickness of element (mm)
L : Distance between fulcrums (mm)
γ : Bending stress (N/mm^2)



Chip Size	L	W	γ		
			C0G Charac-teristics	X7R Charac-teristics	Y5V Charac-teristics
GRM40	1.5	1.2	300	180	160
GRM42-6	2.7	1.5			

(in mm)

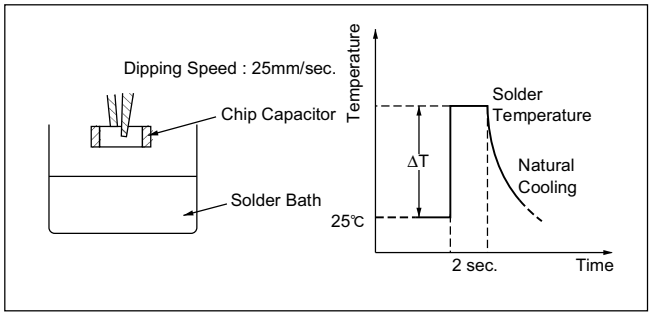
(5) Results



6. Thermal Shock

(1) Test method

After applying flux (an ethanol solution of 25% rosin), dip the chip in a solder bath (6X4 eutectic solder) in accordance with the following conditions :



(2) Test samples

GRM40 C0G/X7R/Y5V Characteristics T=0.6mm typical

(3) Acceptance criteria

Visually inspect the test sample with a 60-power optical microscope. Chips exhibiting breaks or cracks shall be determined to be defective.

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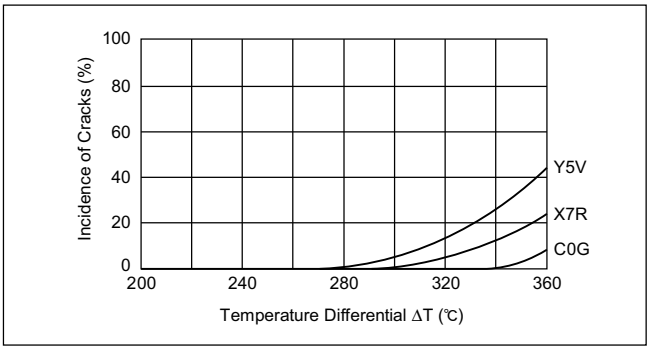
(4) Results



7. Solder Heat Resistance

(1) Test Method

① Reflow soldering :
Apply about 300 μm of solder paste over the alumina substrate. After reflow soldering, remove the chip and check for leaching that may have occurred on the outer electrode.

② Flow soldering :
After dipping the test sample with a pair of tweezers in wave solder (eutectic solder), check for leaching that may have occurred on the outer electrode.

③ Dip soldering :
After dipping the test sample with a pair of tweezers in static solder (eutectic solder), check for leaching that may have occurred on the outer electrode.

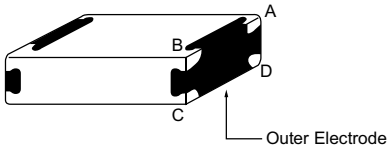
④ Flux to be used : An ethanol solution of 25 % rosin.

(2) Test samples

GRM40 : For flow/reflow soldering T=0.6mm

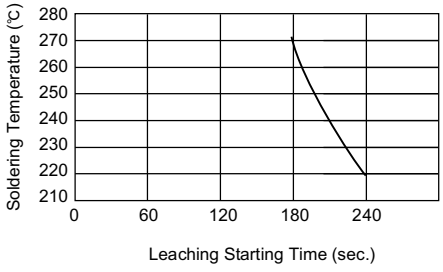
(3) Acceptance criteria

The starting time of leaching shall be defined as the time when the outer electrode has lost 25 % of the total edge length of A-B-C-D as illustrated :



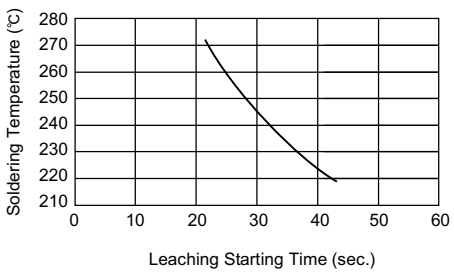
(4) Results

Reflow Soldering



Flow Soldering

Dip Soldering



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Reference Data

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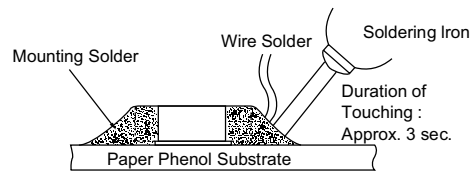
8. Thermal Shock when Making Corrections with a Soldering Iron

(1) Test Method

Apply a soldering iron meeting the conditions below to the soldered joint of a chip that has been soldered to a paper phenol board, while supplying wire solder. (Note: the soldering iron tip shall not directly touch the ceramic element of the chip.)



Soldering Iron	Tip diameter
Ceramic heater 20W	ϕ3mm

(2) Test Samples

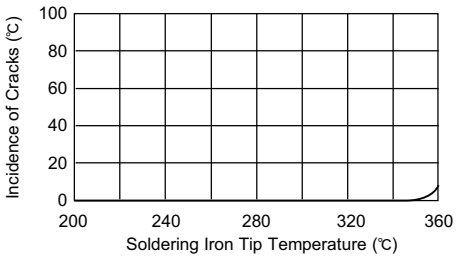
GRM40 C0G/X7R/Y5V Characteristics T=0.6mm

(3) Acceptance Criteria for Defects

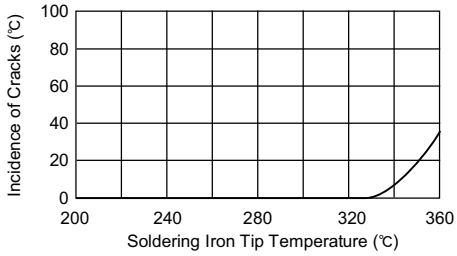
Observe the appearance of the test sample with a 60-power optical microscope. Those units displaying any breaks cracks shall be determined to be defective.

(4) Results

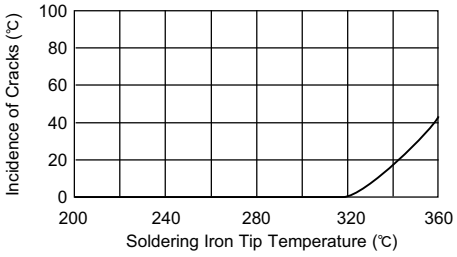
GRM40 C0G (T=0.6)



GRM40 X7R (T=0.6)



GRM40 Y5V (T=0.6)

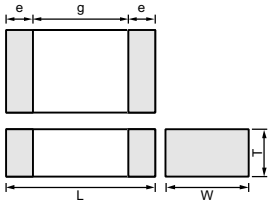


CHIP MONOLITHIC CERAMIC CAPACITOR

for High-voltage Low Dissipation Type GHM1000 Series

■ Features

1. Murata's original internal electrode structure realizes high Flash-over Voltage.
2. A new monolithic structure for small, surface-mountable devices capable of operating at high-voltage levels.
3. Sn-plated external electrodes allow mounting without silver compound solder.
4. The GHM1030 type for flow and reflow soldering, and other types for reflow soldering.
5. Low-loss and suitable for high-frequency circuits.
6. The temperature characteristics R is high dielectric constant type, and SL is temperature compensating type.



Part Number	Dimensions (mm)				
	L	W	T	e min.	g min.
GHM1030	3.2 ±0.2	1.6 ±0.2	1.0 +0 -0.3	0.3	1.5*
			1.25 +0 -0.3		
GHM1035	3.2 ±0.2	2.5 ±0.2	1.5 +0 -0.3		1.8
GHM1038	4.5 ±0.3	2.0 ±0.2	2.0 ±0.3		2.9
GHM1040	4.5 ±0.3	3.2 ±0.3	2.0 +0 -0.3		
			2.5 +0 -0.3		

* SL 2kV : 1.8mm min.

■ Application

1. Ideal use on high-frequency pulse circuit such as snubber circuit for switching power supply, DC-DC converter, ballast(inverter fluorescent lamp), and so on. (R Characteristics)
2. Ideal for use as the ballast in liquid crystal back lighting inverters. (SL Characteristics)

Part Number	Rated Voltage (V)	TC Code	Capacitance (pF)	Length L (mm)	Width W (mm)	Thickness T (mm)	Electrode g (mm)	Electrode e (mm)
GHM1030R101K630	DC630	R	100 +10,-10%	3.2	1.6	1.0	1.5 min.	0.3 min.
GHM1030R151K630	DC630	R	150 +10,-10%	3.2	1.6	1.0	1.5 min.	0.3 min.
GHM1030R221K630	DC630	R	220 +10,-10%	3.2	1.6	1.0	1.5 min.	0.3 min.
GHM1030R331K630	DC630	R	330 +10,-10%	3.2	1.6	1.0	1.5 min.	0.3 min.
GHM1030R471K630	DC630	R	470 +10,-10%	3.2	1.6	1.25	1.5 min.	0.3 min.
GHM1030R681K630	DC630	R	680 +10,-10%	3.2	1.6	1.25	1.5 min.	0.3 min.
GHM1030R102K630	DC630	R	1000 +10,-10%	3.2	1.6	1.25	1.5 min.	0.3 min.
GHM1030R470K1K	DC1000	R	47 +10,-10%	3.2	1.6	1.0	1.5 min.	0.3 min.
GHM1030R680K1K	DC1000	R	68 +10,-10%	3.2	1.6	1.0	1.5 min.	0.3 min.
GHM1030R101K1K	DC1000	R	100 +10,-10%	3.2	1.6	1.0	1.5 min.	0.3 min.
GHM1030R151K1K	DC1000	R	150 +10,-10%	3.2	1.6	1.0	1.5 min.	0.3 min.
GHM1030R221K1K	DC1000	R	220 +10,-10%	3.2	1.6	1.0	1.5 min.	0.3 min.
GHM1030R331K1K	DC1000	R	330 +10,-10%	3.2	1.6	1.0	1.5 min.	0.3 min.
GHM1030R471K1K	DC1000	R	470 +10,-10%	3.2	1.6	1.25	1.5 min.	0.3 min.
GHM1030SL100D2K	DC2000	SL	10 +0.5,-0.5pF	3.2	1.6	1.25	1.8 min.	0.3 min.
GHM1030SL120J2K	DC2000	SL	12 +5,-5%	3.2	1.6	1.25	1.8 min.	0.3 min.
GHM1030SL150J2K	DC2000	SL	15 +5,-5%	3.2	1.6	1.25	1.8 min.	0.3 min.
GHM1030SL180J2K	DC2000	SL	18 +5,-5%	3.2	1.6	1.25	1.8 min.	0.3 min.
GHM1030SL220J2K	DC2000	SL	22 +5,-5%	3.2	1.6	1.25	1.8 min.	0.3 min.
GHM1035SL270J2K	DC2000	SL	27 +5,-5%	3.2	2.5	1.5	1.8 min.	0.3 min.
GHM1035SL330J2K	DC2000	SL	33 +5,-5%	3.2	2.5	1.5	1.8 min.	0.3 min.
GHM1035SL390J2K	DC2000	SL	39 +5,-5%	3.2	2.5	1.5	1.8 min.	0.3 min.
GHM1035SL470J2K	DC2000	SL	47 +5,-5%	3.2	2.5	1.5	1.8 min.	0.3 min.
GHM1035SL560J2K	DC2000	SL	56 +5,-5%	3.2	2.5	1.5	1.8 min.	0.3 min.
GHM1035SL680J2K	DC2000	SL	68 +5,-5%	3.2	2.5	1.5	1.8 min.	0.3 min.
GHM1035SL820J2K	DC2000	SL	82 +5,-5%	3.2	2.5	1.5	1.8 min.	0.3 min.
GHM1040SL121J2K	DC2000	SL	120 +5,-5%	4.5	3.2	2.0	2.9 min.	0.3 min.

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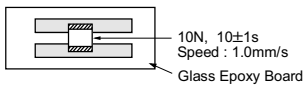
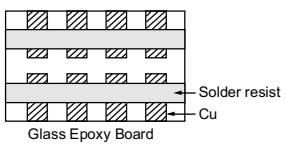
Part Number	Rated Voltage (V)	TC Code	Capacitance (pF)	Length L (mm)	Width W (mm)	Thickness T (mm)	Electrode g (mm)	Electrode e (mm)
GHM1040SL151J2K	DC2000	SL	150 +5,-5%	4.5	3.2	2.0	2.9 min.	0.3 min.
GHM1040SL181J2K	DC2000	SL	180 +5,-5%	4.5	3.2	2.0	2.9 min.	0.3 min.
GHM1040SL221J2K	DC2000	SL	220 +5,-5%	4.5	3.2	2.0	2.9 min.	0.3 min.
GHM1038SL100D3K	DC3150	SL	10 +0.5,-0.5pF	4.5	2.0	2.0	2.9 min.	0.3 min.
GHM1038SL120J3K	DC3150	SL	12 +5,-5%	4.5	2.0	2.0	2.9 min.	0.3 min.
GHM1038SL150J3K	DC3150	SL	15 +5,-5%	4.5	2.0	2.0	2.9 min.	0.3 min.
GHM1038SL180J3K	DC3150	SL	18 +5,-5%	4.5	2.0	2.0	2.9 min.	0.3 min.
GHM1038SL220J3K	DC3150	SL	22 +5,-5%	4.5	2.0	2.0	2.9 min.	0.3 min.
GHM1038SL270J3K	DC3150	SL	27 +5,-5%	4.5	2.0	2.0	2.9 min.	0.3 min.
GHM1038SL330J3K	DC3150	SL	33 +5,-5%	4.5	2.0	2.0	2.9 min.	0.3 min.
GHM1038SL390J3K	DC3150	SL	39 +5,-5%	4.5	2.0	2.0	2.9 min.	0.3 min.
GHM1038SL470J3K	DC3150	SL	47 +5,-5%	4.5	2.0	2.0	2.9 min.	0.3 min.
GHM1038SL560J3K	DC3150	SL	56 +5,-5%	4.5	2.0	2.0	2.9 min.	0.3 min.
GHM1038SL680J3K	DC3150	SL	68 +5,-5%	4.5	2.0	2.0	2.9 min.	0.3 min.
GHM1038SL820J3K	DC3150	SL	82 +5,-5%	4.5	2.0	2.0	2.9 min.	0.3 min.
GHM1040SL101J3K	DC3150	SL	100 +5,-5%	4.5	3.2	2.5	2.9 min.	0.3 min.

Specifications and Test Methods

No.	Item		Specification: Temperature Compensating Type (SL Char.)	Specification: High Dielectric Constant Type (R Char.)	Test Method
1	Operating Temperature Range		−55 to +125℃		
2	Appearance		No defects or abnormalities.		Visual inspection.
3	Dimensions		Within the specified dimension.		Using calipers.
4	Dielectric Strength		No defects or abnormalities.		No failure shall be observed when voltage in Table is applied between the terminations for 1 to 5 s, provided the charge/discharge current is less than 50mA. Rated voltage / Test voltage More than DC 1kV: 120% of the rated voltage Less than DC 1kV: 150% of the rated voltage
5	Insulation Resistance (I.R.)		More than 10,000MΩ		The insulation resistance shall be measured with 500±50V and within 60±5 s of charging.
6	Capacitance		Within the specified tolerance.		The capacitance/Q/D.F. shall be measured at 20℃ at the frequency and voltage shown as follows. (1) Temperature Compensating Type Frequency : 1±0.2MHz Voltage : 0.5 to 5V (r.m.s.) (2) High Dielectric Constant Type Frequency : 1±0.2kHz Voltage : 1±0.2V (r.m.s.)
7	Q/ Dissipation Factor (D.F.)		C≧30pF : Q≧1,000 C<30pF : Q≧400+20C C : Nominal Capacitance (pF)	D.F.≦0.01	
8	Capacitance Temperature Characteristics		Temp. Coefficient +350 to −1,000 ppm/℃ (Temp. Range : +20 to +85℃)	Cap. Change Within ±15%	(1) Temperature Compensating Type The temperature coefficient is determined using the capacitance measured in step 3 as a reference. When cycling the temperature sequentially from step 1 through 5 (+20 to +85 ℃) the capacitance shall be within the specified tolerance for the temperature coefficient. Step / Temperature(℃) 1: 20±2 2: Min. Operating Temp.±3 3: 20±2 4: Max. Operating Temp.±2 5: 20±2 (2) High Dielectric Constant Type The range of capacitance change compared to the 20℃ value within −55 to +125℃ shall be within the specified range. •Pretreatment Perform a heat treatment at 150 $^{+0}_{-10}$ ℃ for 60±5 min and then let sit for 24±2 h at room condition.
9	Adhesive Strength of Termination		No removal of the terminations or other defect shall occur.		Solder the capacitor to the testing jig (glass epoxy board) shown in Fig.1 using a eutectic solder. Then apply 10N force in the direction of the arrow. The soldering shall be done either with an iron or using the reflow method and shall be conducted with care so that the soldering is uniform and free of defects such as heat shock.  Fig.1
10	Vibration Resistance	Appearance	No defects or abnormalities.		Solder the capacitor to the test jig (glass epoxy board). The capacitor shall be subjected to a simple harmonic motion having a total amplitude of 1.5mm, the frequency being varied uniformly between the approximate limits of 10 and 55Hz. The frequency range, from 10 to 55Hz and return to 10Hz, shall be traversed in approximately 1 min. This motion shall be applied for a period of 2 h in each 3 mutually perpendicular directions (total of 6 h). 
		Capacitance	Within the specified tolerance.		
		Q/D.F.	30pF min. : Q≧1,000 30pF max. : Q≧400+20C C : Nominal Capacitance (pF)	D.F.≦0.01	

"Room condition" Temperature : 15 to 35℃, Relative humidity : 45 to 75%, Atmosphere pressure : 86 to 106kPa

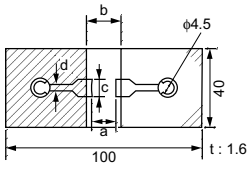
Continued on the following page.

13

Specifications and Test Methods

Continued from the preceding page.

No.	Item		Specification: Temperature Compensating Type (SL Char.)	Specification: High Dielectric Constant Type (R Char.)	Test Method
11	Deflection		No cracking or marking defects shall occur.		Solder the capacitor to the testing jig (glass epoxy board) shown in Fig.2 using a eutectic solder. Then apply a force in the direction shown in Fig.3. The soldering shall be done either with an iron or using the reflow method and shall be conducted with care so that the soldering is uniform and free of defects such as heat shock.
12	Solderability of Termination		75% of the terminations are to be soldered evenly and continuously.		Immerse the capacitor in a solution of ethanol (JIS-K-8101) and rosin (JIS-K-5902) (25% rosin in weight proportion). Immerse in eutectic solder solution for 2±0.5 s at 235±5℃. Immersing speed : 25±2.5mm/s
13	Resistance to Soldering Heat	Appearance	No marking defects.		Preheat the capacitor at 120 to 150℃* for 1 min. Immerse the capacitor in eutectic solder solution at 260±5℃ for 10±1 s. Let sit at room condition for 24±2 h, then measure. •Immersing speed : 25±2.5mm/s •Pretreatment for high dielectric constant type Perform a heat treatment at 150 $^{+0}_{-10}$℃ for 60±5 min and then let sit for 24±2 h at room condition.
		Capacitance Change	Within ±2.5% or ±0.25pF (Whichever is larger)	Within ±10%	
		Q/D.F.	C≧30pF : Q≧1,000 C<30pF : Q≧400+20C C : Nominal Capacitance (pF)	D.F.≦0.01	
		I.R.	More than 10,000MΩ		
		Dielectric Strength	Pass the item No.4.		
14	Temperature Cycle	Appearance	No marking defects.		Fix the capacitor to the supporting jig (glass epoxy board) shown in Fig.4 using a eutectic solder. Perform the five cycles according to the four heat treatments listed in the following table. Let sit for 24±2 h at room condition, then measure. •Pretreatment for high dielectric constant type Perform a heat treatment at 150 $^{+0}_{-10}$℃ for 60±5 min and then let sit for 24±2 h at room condition.
		Capacitance Change	Within ±2.5% or ±0.25pF (Whichever is larger)	Within ±10%	
		Q/D.F.	C≧30pF : Q≧1,000 C<30pF : Q≧400+20C C : Nominal Capacitance (pF)	D.F.≦0.01	
		I.R.	More than 10,000MΩ		
		Dielectric Strength	Pass the item No.4.		
15	Humidity (Steady State)	Appearance	No marking defects.		Sit the capacitor at 40±2℃ and relative humidity 90 to 95% for 500 $^{+24}_{-0}$ h. Remove and let sit for 24±2 h at room condition, then measure. •Pretreatment for high dielectric constant type Perform a heat treatment at 150 $^{+0}_{-10}$℃ for 60±5 min and then let sit for 24±2 h at room condition.
		Capacitance Change	Within ±5.0% or ±0.5pF (Whichever is larger)	Within ±10%	
		Q/D.F.	C≧30pF : Q≧350 C<30pF : Q≧275+$\frac{5}{2}$C C : Nominal Capacitance (pF)	D.F.≦0.01	
		I.R.	More than 1,000MΩ		
		Dielectric Strength	Pass the item No.4.		



L×W (mm)	Dimension (mm) a	b	c	d
3.2×1.6	2.2	5.0	2.0	1.0
3.2×2.5	2.2	5.0	2.9	
4.5×2.0	3.5	7.0	2.4	
4.5×3.2	3.5	7.0	3.7	

Fig.2

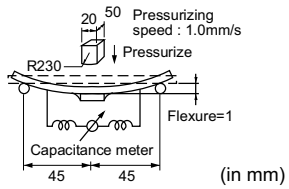


Fig.3

*Preheating for more than 3.2×2.5mm

Step	Temperature	Time
1	100℃ to 120℃	1 min.
2	170℃ to 200℃	1 min.

Step	Temperature (℃)	Time (min)
1	Min. Operating Temp.±3	30±3
2	Room Temp.	2 to 3
3	Max. Operating Temp.±2	30±3
4	Room Temp.	2 to 3

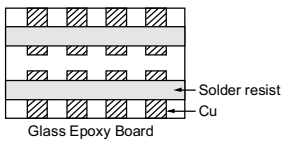


Fig.4

"Room condition" Temperature : 15 to 35℃, Relative humidity : 45 to 75%, Atmosphere pressure : 86 to 106kPa

Continued on the following page.

Specifications and Test Methods

Continued from the preceding page.

No.	Item		Specification: Temperature Compensating Type (SL Char.)	Specification: High Dielectric Constant Type (R Char.)	Test Method
16	Life	Appearance	No marking defects.		Apply the voltage in following table for 1,000 $^{+48}_{0}$ at maximum operating temperature±3℃. Remove and let sit for 24±2 h at room condition, then measure. The charge/discharge current is less than 50mA. •Pretreatment for high dielectric constant type Apply test voltage for 60±5 min at test temperature. Remove and let sit for 24±2 h at room condition.
		Capacitance Change	Within ±3.0% or ±0.3pF (Whichever is larger)	Within ±10%	
		Q/D.F.	C≧30pF : Q≧350 C<30pF : Q≧275+$\frac{5}{2}$C C : Nominal Capacitance (pF)	D.F.≦0.02	
		I.R.	More than 1,000MΩ		
		Dielectric Strength	Pass the item No.4.		

Rated voltage	Test voltage
More than DC 1kV	Rated voltage
Less than DC 1kV	120% of the rated voltage

"Room condition" Temperature : 15 to 35℃, Relative humidity : 45 to 75%, Atmosphere pressure : 86 to 106kPa

13

CHIP MONOLITHIC CERAMIC CAPACITOR

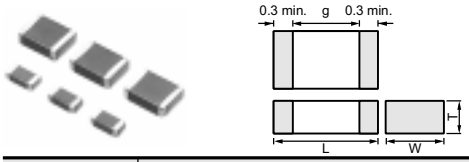
for High-voltage High-capacitance Type GHM1500 Series

■ Features

1. A new monolithic structure for small, high-capacitance capable of operating at high-voltage levels.
2. Sn-plated external electrodes allow mounting without silver compound solder.
3. The GHM1525 and GHM1530 type for flow and reflow soldering, and other types for reflow soldering.

■ Application

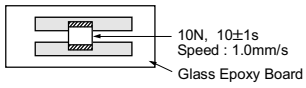
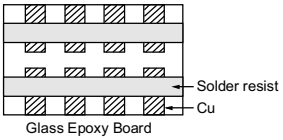
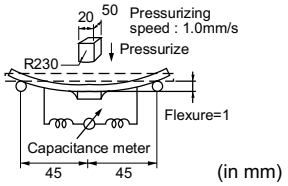
1. Ideal use as hot-cold coupling for DC-DC converter.
2. Ideal use on line filter and ringer detector for telephone, facsimile and modem.
3. Ideal use on diode-snubber circuit for switching power supply.

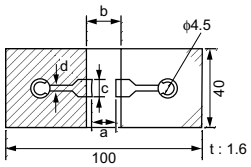


Part Number	Dimensions (mm)			
	L	W	T	g min.
GHM1525	2.0 ±0.2	1.25 ±0.2	1.0 +0,-0.3	0.7
			1.25 ±0.2	
GHM1530	3.2 ±0.2	1.6 ±0.2	1.0 +0,-0.3	1.5
			1.25 +0,-0.3	
			1.6 ±0.2	
GHM1535	3.2 ±0.3	2.5 ±0.2	1.5 +0,-0.3	
			2.0 +0,-0.3	
GHM1540	4.5 ±0.4	3.2 ±0.3	1.5 +0,-0.3	2.5
			2.0 +0,-0.3	
			2.5 +0,-0.3	
			2.6 +0,-0.3	
GHM1545	5.7 ±0.4	5.0 ±0.4	2.0 +0,-0.3	3.5
			2.7 +0,-0.3	

Part Number	Rated Voltage (V)	TC Code	Capacitance	Length L (mm)	Width W (mm)	Thickness T (mm)	Electrode g (mm)	Electrode e (mm)
GHM1525B102K250	DC250	B	1000pF +10,-10%	2.0	1.25	1.0	0.7 min.	0.3 min.
GHM1525B152K250	DC250	B	1500pF +10,-10%	2.0	1.25	1.0	0.7 min.	0.3 min.
GHM1525B222K250	DC250	B	2200pF +10,-10%	2.0	1.25	1.0	0.7 min.	0.3 min.
GHM1525B332K250	DC250	B	3300pF +10,-10%	2.0	1.25	1.0	0.7 min.	0.3 min.
GHM1525B472K250	DC250	B	4700pF +10,-10%	2.0	1.25	1.0	0.7 min.	0.3 min.
GHM1525B682K250	DC250	B	6800pF +10,-10%	2.0	1.25	1.0	0.7 min.	0.3 min.
GHM1525B103K250	DC250	B	10000pF +10,-10%	2.0	1.25	1.25	0.7 min.	0.3 min.
GHM1530B153K250	DC250	B	15000pF +10,-10%	3.2	1.6	1.0	1.5 min.	0.3 min.
GHM1530B223K250	DC250	B	22000pF +10,-10%	3.2	1.6	1.0	1.5 min.	0.3 min.
GHM1530B333K250	DC250	B	33000pF +10,-10%	3.2	1.6	1.25	1.5 min.	0.3 min.
GHM1530B473K250	DC250	B	47000pF +10,-10%	3.2	1.6	1.6	1.5 min.	0.3 min.
GHM1535B683K250	DC250	B	68000pF +10,-10%	3.2	2.5	1.5	1.5 min.	0.3 min.
GHM1535B104K250	DC250	B	0.1µF +10,-10%	3.2	2.5	2.0	1.5 min.	0.3 min.
GHM1540B154K250	DC250	B	0.15µF +10,-10%	4.5	3.2	2.0	2.9 min.	0.3 min.
GHM1540B224K250	DC250	B	0.22µF +10,-10%	4.5	3.2	2.5	2.9 min.	0.3 min.
GHM1545B334K250	DC250	B	0.33µF +10,-10%	5.7	5.0	2.0	3.5 min.	0.3 min.
GHM1545B474K250	DC250	B	0.47µF +10,-10%	5.7	5.0	2.0	3.5 min.	0.3 min.
GHM1530B102K630	DC630	B	1000pF +10,-10%	3.2	1.6	1.25	1.5 min.	0.3 min.
GHM1530B152K630	DC630	B	1500pF +10,-10%	3.2	1.6	1.25	1.5 min.	0.3 min.
GHM1530B222K630	DC630	B	2200pF +10,-10%	3.2	1.6	1.25	1.5 min.	0.3 min.
GHM1530B332K630	DC630	B	3300pF +10,-10%	3.2	1.6	1.25	1.5 min.	0.3 min.
GHM1530B472K630	DC630	B	4700pF +10,-10%	3.2	1.6	1.25	1.5 min.	0.3 min.
GHM1530B682K630	DC630	B	6800pF +10,-10%	3.2	1.6	1.25	1.5 min.	0.3 min.
GHM1530B103K630	DC630	B	10000pF +10,-10%	3.2	1.6	1.25	1.5 min.	0.3 min.
GHM1535B153K630	DC630	B	15000pF +10,-10%	3.2	2.5	1.5	1.5 min.	0.3 min.
GHM1535B223K630	DC630	B	22000pF +10,-10%	3.2	2.5	1.5	1.5 min.	0.3 min.
GHM1540B333K630	DC630	B	33000pF +10,-10%	4.5	3.2	1.5	2.5 min.	0.3 min.
GHM1540B473K630	DC630	B	47000pF +10,-10%	4.5	3.2	1.5	2.5 min.	0.3 min.
GHM1540B683K630	DC630	B	68000pF +10,-10%	4.5	3.2	2.0	2.5 min.	0.3 min.
GHM1540B104K630	DC630	B	0.1µF +10,-10%	4.5	3.2	2.6	2.5 min.	0.3 min.
GHM1545B154K630	DC630	B	0.15µF +10,-10%	5.7	5.0	2.0	3.5 min.	0.3 min.
GHM1545B224K630	DC630	B	0.22µF +10,-10%	5.7	5.0	2.7	3.5 min.	0.3 min.

Specifications and Test Methods

No.	Item	Specification	Test Method
1	Operating Temperature Range	−55 to +125℃	−
2	Appearance	No defects or abnormalities.	Visual inspection.
3	Dimensions	Within the specified dimensions.	Using calipers.
4	Dielectric Strength	No defects or abnormalities.	No failure shall be observed when 150% of the rated voltage (200% of the rated voltage in case of rated voltage: DC 250V) is applied between the terminations for 1 to 5 s, provided the charge/discharge current is less than 50mA.
5	Insulation Resistance (I.R.)	C≧0.01μF : More than 100MΩ • μF C<0.01μF : More than 10,000MΩ	The insulation resistance shall be measured with 500±50V (250±50V in case of rated voltage: DC 250V) and within 60±5 s of charging.
6	Capacitance	Within the specified tolerance.	The capacitance/D.F. shall be measured at 20℃ at a frequency of 1±0.2kHz and a voltage of 1±0.2V (r.m.s.)
7	Dissipation Factor (D.F.)	0.025 max.	
8	Capacitance Temperature Characteristics	Cap. Change Within ±10% (Temp. Range : −25 to +85℃)	The range of capacitance change compared with the 20℃ value within −25 to +85℃ shall be within the specified range. •Pretreatment Perform a heat treatment at 150 $^{+0}_{-10}$ ℃ for 60±5 min and then let sit for 24±2 h at room condition.
9	Adhesive Strength of Termination	No removal of the terminations or other defect shall occur.	Solder the capacitor to the testing jig (glass epoxy board) shown in Fig.1 using a eutectic solder. Then apply 10N force in the direction of the arrow. The soldering shall be done either with an iron or using the reflow method and shall be conducted with care so that the soldering is uniform and free of defects such as heat shock.  Fig.1
10	Vibration Resistance	Appearance: No defects or abnormalities. Capacitance: Within the specified tolerance. D.F.: 0.025 max.	Solder the capacitor to the test jig (glass epoxy board). The capacitor shall be subjected to a simple harmonic motion having a total amplitude of 1.5mm, the frequency being varied uniformly between the approximate limits of 10 and 55Hz. The frequency range, from 10 to 55Hz and return to 10Hz, shall be traversed in approximately 1 min. This motion shall be applied for a period of 2 h in each 3 mutually perpendicular directions (total of 6 h). 
11	Deflection	No cracking or marking defects shall occur.	Solder the capacitor to the testing jig (glass epoxy board) shown in Fig.2 using a eutectic solder. Then apply a force in the direction shown in Fig.3. The soldering shall be done either with an iron or using the reflow method and shall be conducted with care so that the soldering is uniform and free of defects such as heat shock.  Fig.3



L×W (mm)	Dimension (mm) a	b	c	d
2.0×1.25	1.2	4.0	1.65	1.0
3.2×1.6	2.2	5.0	2.0	
3.2×2.5	2.2	5.0	2.9	
4.5×3.2	3.5	7.0	3.7	
5.7×5.0	4.5	8.0	5.6	

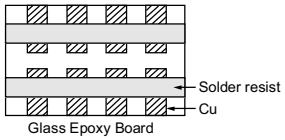
Fig.2

"Room condition" Temperature : 15 to 35℃, Relative humidity : 45 to 75%, Atmosphere pressure : 86 to 106kPa

Continued on the following page.

Specifications and Test Methods

Continued from the preceding page.

No.	Item		Specification	Test Method
12	Solderability of Termination		75% of the terminations is to be soldered evenly and continuously.	Immerse the capacitor in a solution of ethanol (JIS-K-8101) and rosin (JIS-K-5902) (25% rosin in weight proportion). Immerse in eutectic solder solution for 2±0.5 s at 235±5℃. Immersing speed : 25±2.5mm/s
13	Resistance to Soldering Heat	Appearance	No marking defects.	Preheat the capacitor at 120 to 150℃* for 1 min. Immerse the capacitor in eutectic solder solution at 260±5℃ for 10±1 s. Let sit at room condition for 24±2 h, then measure. •**Immersing speed** : 25±2.5mm/s •**Pretreatment** Perform a heat treatment at 150 $^{+0}_{-10}$℃ for 60±5 min and then let sit for 24±2 h at room condition. *Preheating for more than 3.2×2.5mm Step / Temperature / Time 1 / 100℃ to 120℃ / 1 min. 2 / 170℃ to 200℃ / 1 min.
		Capacitance Change	Within ±10%	
		D.F.	0.025 max.	
		I.R.	C≧0.01μF : More than 100MΩ • μF C<0.01μF : More than 10,000MΩ	
		Dielectric Strength	Pass the item No.4.	
14	Temperature Cycle	Appearance	No marking defects.	Fix the capacitor to the supporting jig (glass epoxy board) shown in Fig.4 using a eutectic solder. Perform the five cycles according to the four heat treatments listed in the following table. Let sit for 24±2 h at room condition, then measure. Step / Temperature (℃) / Time (min) 1 / Min. Operating Temp.±3 / 30±3 2 / Room Temp. / 2 to 3 3 / Max. Operating Temp.±2 / 30±3 4 / Room Temp. / 2 to 3 •**Pretreatment** Perform a heat treatment at 150 $^{+0}_{-10}$℃ for 60±5 min and then let sit for 24±2 h at room condition.  Fig.4
		Capacitance Change	Within ±7.5%	
		D.F.	0.025 max.	
		I.R.	C≧0.01μF : More than 100MΩ • μF C<0.01μF : More than 10,000MΩ	
		Dielectric Strength	Pass the item No.4.	
15	Humidity (Steady State)	Appearance	No marking defects.	Sit the capacitor at 40±2℃ and relative humidity 90 to 95% for 500 $^{+24}_{0}$ h. Remove and let sit for 24±2 h at room condition, then measure. •**Pretreatment** Perform a heat treatment at 150 $^{+0}_{-10}$℃ for 60±5 min and then let sit for 24±2 h at room condition.
		Capacitance Change	Within ±15%	
		D.F.	0.05 max.	
		I.R.	C≧0.01μF : More than 10MΩ • μF C<0.01μF : More than 1,000MΩ	
		Dielectric Strength	Pass the item No.4.	
16	Life	Appearance	No marking defects.	Apply 120% of the rated voltage (150% of the rated voltage in case of rated voltage: DC250V) for 1,000 $^{+48}_{0}$ h at maximum operating temperature±3℃. Remove and let sit for 24 ±2 h at room condition, then measure. The charge/discharge current is less than 50mA. •**Pretreatment** Apply test voltage for 60±5 min at test temperature. Remove and let sit for 24±2 h at room condition.
		Capacitance Change	Within ±15%	
		D.F.	0.05 max.	
		I.R.	C≧0.01μF : More than 10MΩ • μF C<0.01μF : More than 1,000MΩ	
		Dielectric Strength	Pass the item No.4.	
17	Humidity Loading	Appearance	No marking defects.	Apply the rated voltage at 40±2℃ and relative humidity 90 to 95% for 500 $^{+24}_{0}$ h. Remove and let sit for 24±2 h at room condition, then measure. •**Pretreatment** Apply test voltage for 60±5 min at test temperature. Remove and let sit for 24±2 h at room condition.
		Capacitance Change	Within ±15%	
		D.F.	0.05 max.	
		I.R.	C≧0.01μF : More than 10MΩ • μF C<0.01μF : More than 1,000MΩ	
		Dielectric Strength	Pass the item No.4.	

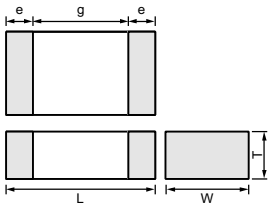
"Room condition" Temperature : 15 to 35℃, Relative humidity : 45 to 75%, Atmosphere pressure : 86 to 106kPa

CHIP MONOLITHIC CERAMIC CAPACITOR

for High-voltage GHM2000 Series AC250V r.m.s.

■ Features

1. Chip monolitic ceramic capacitor for AC line.
2. A new monolithic structure for small, high-capacitance capable of operating at high-voltage levels.
3. Sn-plated external electrodes allow mounting without silver compound solder.
4. Only for Reflow soldering.
5. Capacitance 0.01 to 0.1 uF for connecting lines and 470 to 4700 pF for connecting line to earth.



Part Number	Dimensions (mm)				
	L	W	T	e min.	g min.
GHM2143	5.7 ±0.4	2.8 ±0.3	2.0 ±0.3	0.3	3.5
GHM2145		5.0 ±0.4			
GHM2243		2.8 ±0.3			

■ Application

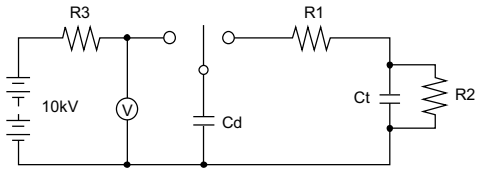
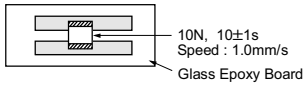
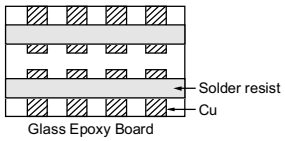
Noise suppression filters for switching power supplies, telephones, facsimiles, modems.

■ Reference Standard

JIS C 5102
JIS C 5150
The standards of the electrical appliance and material control law of Japan, separated table 4.

Part Number	Rated Voltage (V)	TC Code	Capacitance	Length L (mm)	Width W (mm)	Thickness T (mm)	Electrode g (mm)	Electrode e (mm)
GHM2243B471MAC250	AC250 (r.m.s.)	B	470pF +20,-20%	5.7	2.8	2.0	3.5 min.	0.3 min.
GHM2243B102MAC250	AC250 (r.m.s.)	B	1000pF +20,-20%	5.7	2.8	2.0	3.5 min.	0.3 min.
GHM2243B222MAC250	AC250 (r.m.s.)	B	2200pF +20,-20%	5.7	2.8	2.0	3.5 min.	0.3 min.
GHM2243B472MAC250	AC250 (r.m.s.)	B	4700pF +20,-20%	5.7	2.8	2.0	3.5 min.	0.3 min.
GHM2143B103MAC250	AC250 (r.m.s.)	B	10000pF +20,-20%	5.7	2.8	2.0	3.5 min.	0.3 min.
GHM2143B223MAC250	AC250 (r.m.s.)	B	22000pF +20,-20%	5.7	2.8	2.0	3.5 min.	0.3 min.
GHM2143B473MAC250	AC250 (r.m.s.)	B	47000pF +20,-20%	5.7	2.8	2.0	3.5 min.	0.3 min.
GHM2145B104MAC250	AC250 (r.m.s.)	B	0.1µF +20,-20%	5.7	5.0	2.0	3.5 min.	0.3 min.

Specifications and Test Methods

No.	Item		Specification	Test Method
1	Operating Temperature Range		−25 to +85℃	−
2	Appearance		No defects or abnormalities.	Visual inspection.
3	Dimensions		Within the specified dimensions.	Using calipers.
4	Dielectric Strength		No defects or abnormalities.	No failure shall be observed when voltage as table is applied between the terminations for 60±1 s, provided the charge/discharge current is less than 50mA. GHM21xx: AC575V (r.m.s.) GHM22xx: AC1500V (r.m.s.)
5	Insulation Resistance (I.R.)		More than 2,000MΩ	The insulation resistance shall be measured with 500±50V and within 60±5 s of charging.
6	Capacitance		Within the specified tolerance.	The capacitance/D.F. shall be measured at 20℃ at a frequency of 1±0.2kHz and a voltage of 1±0.2V (r.m.s.)
7	Dissipation Factor (D.F.)		0.025 max.	
8	Capacitance Temperature Characteristics		Cap. Change Within ±10%	The range of capacitance change compared with the 20℃ value within −25 to +85℃ shall be within the specified range. •Pretreatment Perform a heat treatment at 150 $^{+0}_{-10}$℃ for 60±5 min and then let sit for 24±2 h at room condition.
9	Discharge Test (Application: GHM22xx)	Appearance	No defects or abnormalities.	As in Fig., discharge is made 50 times at 5 s intervals from the capacitor(Cd) charged at DC voltage of specified.  Ct : Capacitor under test Cd : 0.001μF R1 : 1,000Ω R2 : 100MΩ R3 : Surge resistance
10	Adhesive Strength of Termination		No removal of the terminations or other defect shall occur.	Solder the capacitor to the testing jig (glass epoxy board) shown in Fig.1 using a eutectic solder. Then apply 10N force in the direction of the arrow. The soldering shall be done either with an iron or using the reflow method and shall be conducted with care so that the soldering is uniform and free of defects such as heat shock.  Fig.1
11	Vibration Resistance	Appearance	No defects or abnormalities.	Solder the capacitor to the test jig (glass epoxy board). The capacitor shall be subjected to a simple harmonic motion having a total amplitude of 1.5mm, the frequency being varied uniformly between the approximate limits of 10 and 55Hz. The frequency range, from 10 to 55Hz and return to 10Hz, shall be traversed in approximately 1 min. This motion shall be applied for a period of 2 h in each 3 mutually perpendicular directions (total of 6 h). 
		Capacitance	Within the specified tolerance.	
		D.F.	0.025 max.	

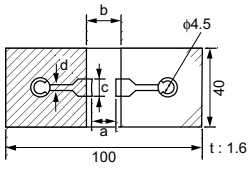
"Room condition" Temperature : 15 to 35℃, Relative humidity : 45 to 75%, Atmosphere pressure : 86 to 106kPa

Continued on the following page.

Specifications and Test Methods

Continued from the preceding page.

No.	Item		Specification	Test Method
12	Deflection		No cracking or marking defects shall occur.	Solder the capacitor to the testing jig (glass epoxy board) shown in Fig.2 using a eutectic solder. Then apply a force in the direction shown in Fig. 3. The soldering shall be done either with an iron or using the reflow method and shall be conducted with care so that the soldering is uniform and free of defects such as heat shock.
13	Solderability of Termination		75% of the terminations is to be soldered evenly and continuously.	Immerse the capacitor in a solution of ethanol (JIS-K-8101) and rosin (JIS-K-5902) (25% rosin in weight proportion). Immerse in eutectic solder solution for 2±0.5 s at 235±5℃. Immersing speed : 25±2.5mm/s
14	Humidity Insulation	Appearance	No marking defects.	The capacitor shall be subjected to 40±2℃, relative humidity of 90 to 98% for 8 h, and then removed in room condition for 16 h until 5 cycles.
		Capacitance Change	Within ±15%	
		D.F.	0.05 max.	
		I.R.	More than 1,000MΩ	
		Dielectric Strength	Pass the item No.4.	
15	Resistance to Soldering Heat	Appearance	No marking defects.	Preheat the capacitor as table. Immerse the capacitor in eutectic solder solution at 260±5℃ for 10±1 s. Let sit at room condition for 24±2 h, then measure. •Immersing speed : 25±2.5mm/s •Pretreatment Perform a heat treatment at 150 $^{+0}_{-10}$℃ for 60±5 min and then let sit for 24±2 h at room condition.
		Capacitance Change	Within ±10%	
		D.F.	0.025 max.	
		I.R.	More than 2,000MΩ	
		Dielectric Strength	Pass the item No.4.	
16	Temperature Cycle	Appearance	No marking defects.	Fix the capacitor to the supporting jig (glass epoxy board) shown in Fig.4 using a eutectic solder. Perform the five cycles according to the four heat treatments listed in the following table. Let sit for 24±2 h at room condition, then measure. •Pretreatment Perform a heat treatment at 150 $^{+0}_{-10}$℃ for 60±5 min and then let sit for 24±2 h at room condition.
		Capacitance Change	Within ±7.5%	
		D.F.	0.025 max.	
		I.R.	More than 2,000MΩ	
		Dielectric Strength	Pass the item No.4.	



L×W (mm)	Dimension (mm) a	b	c	d
5.7×2.8	4.5	8.0	3.2	1.0
5.7×5.0	4.5	8.0	5.6	

Fig.2

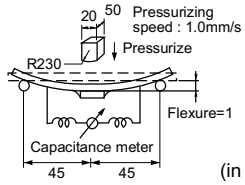


Fig.3

*Preheating

Step	Temperature	Time
1	100℃ to 120℃	1 min.
2	170℃ to 200℃	1 min.

Step	Temperature (℃)	Time (min)
1	Min. Operating Temp.±3	30±3
2	Room Temp.	2 to 3
3	Max. Operating Temp.±2	30±3
4	Room Temp.	2 to 3

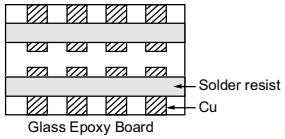


Fig.4

"Room condition" Temperature : 15 to 35℃, Relative humidity : 45 to 75%, Atmosphere pressure : 86 to 106kPa

Continued on the following page.

Specifications and Test Methods

Continued from the preceding page.

No.	Item		Specification	Test Method
17	Humidity (Steady State)	Appearance	No marking defects.	Sit the capacitor at 40±2℃ and relative humidity 90 to 95% for 500^{+24}_{0} h. Remove and let sit for 24±2 h at room condition, then measure. •Pretreatment Perform a heat treatment at 150^{+}_{-10}℃ for 60±5 min and then let sit for 24±2 h at room condition.
		Capacitance Change	Within ±15%	
		D.F.	0.05 max.	
		I.R.	More than 1,000MΩ	
		Dielectric Strength	Pass the item No.4.	
18	Life	Appearance	No marking defects.	Apply voltage and time as Table at 85±2℃. Remove and let sit for 24 ±2 h at room condition, then measure. The charge / discharge current is less than 50mA. ✻ Except that once each hour the voltage is increased to AC1,000V (r.m.s.) for 0.1 s •Pretreatment Apply test voltage for 60±5 min at test temperature. Remove and let sit for 24±2 h at room condition.
		Capacitance Change	Within ±15%	
		D.F.	0.05 max.	
		I.R.	More than 1,000MΩ	
		Dielectric Strength	Pass the item No.4.	
19	Humidity Loading	Appearance	No marking defects.	Apply the rated voltage at 40±2℃ and relative humidity 90 to 95% for 500^{+24}_{0} h. Remove and let sit for 24±2 h at room condition, then measure. •Pretreatment Apply test voltage for 60±5 min at test temperature. Remove and let sit for 24±2 h at room condition.
		Capacitance Change	Within ±15%	
		D.F.	0.05 max.	
		I.R.	More than 1,000MΩ	
		Dielectric Strength	Pass the item No.4.	

	Test Time	Test voltage
GHM21xx	$1,000^{+48}_{0}$ h	AC300V (r.m.s.)
GHM22xx	$1,500^{+48}_{0}$ h	AC500V (r.m.s.) ✻

"Room condition" Temperature : 15 to 35℃, Relative humidity : 45 to 75%, Atmosphere pressure : 86 to 106kPa

15

CHIP MONOLITHIC CERAMIC CAPACITOR

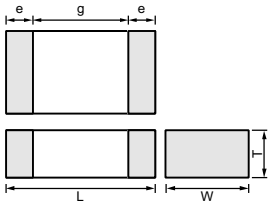
for High-voltage GHM3000 Series Safety Recognized

■ Features

1. Chip monolitic ceramic capacitor (certified as conforming to safety standards) for AC line.
2. A new monolithic structure for small, high-capacitance capable of operating at high-voltage levels.
3. Compared to lead type capacitors, this new capacitor is greatly downsized and low-profiled to 1/10 or less in volume, and 1/4 or less in height.
4. The type GB can be used as an X2-class capacitor.
5. The type GC can be used as an X1-class and Y2-class capacitor.
6. +125 degree C guaranteed.
7. Only for reflow soldering.

■ Application

1. Ideal use as Y capacitor or X capacitor for various switching power supply.
2. Ideal use as linefilter for MODEM.



Part Number	Dimensions (mm)				
	L	W	T	e min.	g min.
GHM3045	5.7 ±0.4	5.0 ±0.4	2.0 ±0.3	0.3	4.0
GHM3145			2.0 ±0.3		
			2.7 ±0.3		

■ Standard Recognition

	Standard No.	Status of Recognition		Rated Voltage
		Type GB	Type GC	
UL	UL1414	–	◎*	AC250V (r.m.s.)
BSI	EN132400	–	◎	
VDE		◎	◎	
SEV		◎	◎	
SEMKO		◎	◎	
EN132400 Class		X2	X1, Y2	

* : Line By Pass only

GC Type

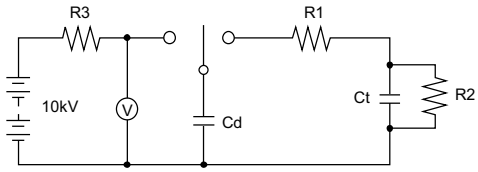
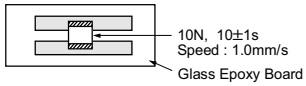
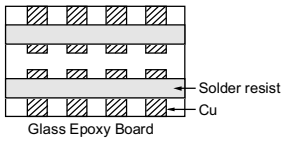
Part Number	Rated Voltage (V)	TC Code	Capacitance (pF)	Length L (mm)	Width W (mm)	Thickness T (mm)	Electrode g (mm)	Electrode e (mm)
GHM3045X7R101K-GC	AC250 (r.m.s.)	X7R	100 +10,-10%	5.7	5.0	2.0	4.0 min.	0.3 min.
GHM3045X7R151K-GC	AC250 (r.m.s.)	X7R	150 +10,-10%	5.7	5.0	2.0	4.0 min.	0.3 min.
GHM3045X7R221K-GC	AC250 (r.m.s.)	X7R	220 +10,-10%	5.7	5.0	2.0	4.0 min.	0.3 min.
GHM3045X7R331K-GC	AC250 (r.m.s.)	X7R	330 +10,-10%	5.7	5.0	2.0	4.0 min.	0.3 min.
GHM3045X7R471K-GC	AC250 (r.m.s.)	X7R	470 +10,-10%	5.7	5.0	2.0	4.0 min.	0.3 min.
GHM3045X7R681K-GC	AC250 (r.m.s.)	X7R	680 +10,-10%	5.7	5.0	2.0	4.0 min.	0.3 min.
GHM3045X7R102K-GC	AC250 (r.m.s.)	X7R	1000 +10,-10%	5.7	5.0	2.0	4.0 min.	0.3 min.
GHM3045X7R152K-GC	AC250 (r.m.s.)	X7R	1500 +10,-10%	5.7	5.0	2.0	4.0 min.	0.3 min.
GHM3045X7R222K-GC	AC250 (r.m.s.)	X7R	2200 +10,-10%	5.7	5.0	2.0	4.0 min.	0.3 min.
GHM3045X7R332K-GC	AC250 (r.m.s.)	X7R	3300 +10,-10%	5.7	5.0	2.0	4.0 min.	0.3 min.
GHM3045X7R472K-GC	AC250 (r.m.s.)	X7R	4700 +10,-10%	5.7	5.0	2.0	4.0 min.	0.3 min.

GB Type

Part Number	Rated Voltage (V)	TC Code	Capacitance (pF)	Length L (mm)	Width W (mm)	Thickness T (mm)	Electrode g (mm)	Electrode e (mm)
GHM3145X7R103K-GB	AC250 (r.m.s.)	X7R	10000 +10,-10%	5.7	5.0	2.0	4.0 min.	0.3 min.
GHM3145X7R153K-GB	AC250 (r.m.s.)	X7R	15000 +10,-10%	5.7	5.0	2.0	4.0 min.	0.3 min.
GHM3145X7R223K-GB	AC250 (r.m.s.)	X7R	22000 +10,-10%	5.7	5.0	2.0	4.0 min.	0.3 min.
GHM3145X7R333K-GB	AC250 (r.m.s.)	X7R	33000 +10,-10%	5.7	5.0	2.7	4.0 min.	0.3 min.

Dielectric Strength: DC1075V, 60+/- 1s.

Specifications and Test Methods

No.	Item		Specification	Test Method
1	Operating Temperature Range		−55 to +125℃	−
2	Appearance		No defects or abnormalities.	Visual inspection.
3	Dimensions		Within the specified dimensions.	Using calipers.
4	Dielectric Strength		No defects or abnormalities.	No failure shall be observed when voltage as table is applied between the terminations for 60±1 s, provided the charge/discharge current is less than 50mA. Type GB: DC1075V Type GC: AC1500V (r.m.s.)
5	Insulation Resistance (I.R.)		More than 6,000MΩ	The insulation resistance shall be measured with 500±50V and within 60±5 s of charging.
6	Capacitance		Within the specified tolerance.	The capacitance/D.F. shall be measured at 20℃ at a frequency of 1±0.2kHz and a voltage of 1±0.2V (r.m.s.)
7	Dissipation Factor (D.F.)		0.025 max.	
8	Capacitance Temperature Characteristics		Cap. Change Within ±15%	The range of capacitance change compared with the 25℃ value within −55 to +125℃ shall be within the specified range. •Pretreatment Perform a heat treatment at 150 $^{+0}_{-10}$℃ for 60±5 min and then let sit for 24±2 h at room condition.
9	Discharge Test (Application: Type GC)	Appearance	No defects or abnormalities.	As in Fig., discharge is made 50 times at 5 s intervals from the capacitor(Cd) charged at DC voltage of specified.  Ct : Capacitor under test Cd : 0.001μF R1 : 1,000Ω R2 : 100MΩ R3 : Surge resistance
		I.R.	More than 1,000MΩ	
		Dielectric Strength	Pass the item No.4.	
10	Adhesive Strength of Termination		No removal of the terminations or other defect shall occur.	Solder the capacitor to the testing jig (glass epoxy board) shown in Fig.1 using a eutectic solder. Then apply 10N force in the direction of the arrow. The soldering shall be done either with an iron or using the reflow method and shall be conducted with care so that the soldering is uniform and free of defects such as heat shock.  Fig.1
11	Vibration Resistance	Appearance	No defects or abnormalities.	Solder the capacitor to the test jig (glass epoxy board). The capacitor shall be subjected to a simple harmonic motion having a total amplitude of 1.5mm, the frequency being varied uniformly between the approximate limits of 10 and 55Hz. The frequency range, from 10 to 55Hz and return to 10Hz, shall be traversed in approximately 1 min. This motion shall be applied for a period of 2 h in each 3 mutually perpendicular directions (total of 6 h). 
		Capacitance	Within the specified tolerance.	
		D.F.	0.025 max.	

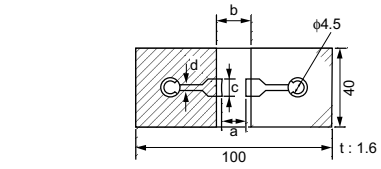
"Room condition" Temperature : 15 to 35℃, Relative humidity : 45 to 75%, Atmosphere pressure : 86 to 106kPa

Continued on the following page.

Specifications and Test Methods

Continued from the preceding page.

No.	Item		Specification	Test Method
12	Deflection		No cracking or marking defects shall occur.	Solder the capacitor to the testing jig (glass epoxy board) shown in Fig.2 using a eutectic solder. Then apply a force in the direction shown in Fig. 3. The soldering shall be done either with an iron or using the reflow method and shall be conducted with care so that the soldering is uniform and free of defects such as heat shock.
13	Solderability of Termination		75% of the terminations is to be soldered evenly and continuously.	Immerse the capacitor in a solution of ethanol (JIS-K-8101) and rosin (JIS-K-5902) (25% rosin in weight proportion). Immerse in eutectic solder solution for 2±0.5 s at 235±5℃. Immersing speed : 25±2.5mm/s
14	Resistance to Soldering Heat	Appearance	No marking defects.	Preheat the capacitor as table. Immerse the capacitor in eutectic solder solution at 260±5℃ for 10±1 s. Let sit at room condition for 24±2 h, then measure. •Immersing speed : 25±2.5mm/s •Pretreatment Perform a heat treatment at 150 $^{+0}_{-10}$℃ for 60±5 min and then let sit for 24±2 h at room condition.
		Capacitance Change	Within ±10%	
		I.R.	More than 1,000MΩ	
		Dielectric Strength	Pass the item No.4.	
15	Temperature Cycle	Appearance	No marking defects.	Fix the capacitor to the supporting jig (glass epoxy board) shown in Fig.4 using a eutectic solder. Perform the five cycles according to the four heat treatments listed in the following table. Let sit for 24±2 h at room condition, then measure. •Pretreatment Perform a heat treatment at 150 $^{+0}_{-10}$℃ for 60±5 min and then let sit for 24±2 h at room condition.
		Capacitance Change	Within ±15%	
		D.F.	0.05 max.	
		I.R.	More than 3,000MΩ	
		Dielectric Strength	Pass the item No.4.	
16	Humidity (Steady State)	Appearance	No marking defects.	Sit the capacitor at 40±2℃ and relative humidity 90 to 95% for 500±12 h. Remove and let sit for 24±2 h at room condition, then measure.
		Capacitance Change	Within ±15%	
		D.F.	0.05 max.	
		I.R.	More than 3,000MΩ	
		Dielectric Strength	Pass the item No.4.	



L×W (mm)	Dimension (mm)			
	a	b	c	d
5.7×5.0	4.5	8.0	5.6	1.0

Fig.2

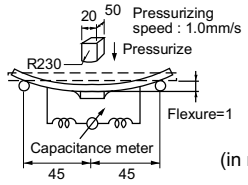


Fig.3

•Preheating

Step	Temperature	Time
1	100℃ to 120℃	1 min.
2	170℃ to 200℃	1 min.

Step	Temperature (℃)	Time (min)
1	Min. Operating Temp.±3	30±3
2	Room Temp.	2 to 3
3	Max. Operating Temp.±2	30±3
4	Room Temp.	2 to 3

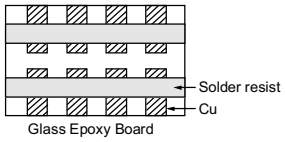


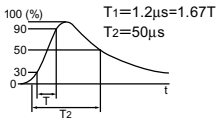
Fig.4

"Room condition" Temperature : 15 to 35℃, Relative humidity : 45 to 75%, Atmosphere pressure : 86 to 106kPa

Continued on the following page.

Specifications and Test Methods

Continued from the preceding page.

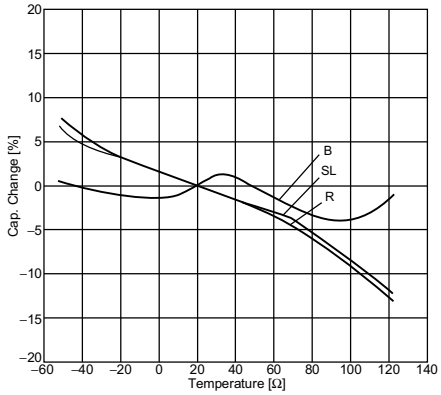
No.	Item		Specification	Test Method
17	Life	Appearance	No marking defects.	Impulse Voltage Each individual capacitor shall be subjected to a 2.5kV (Type GC:5kV) Impulses (the voltage value means zero to peak) for three times. Then the capacitors are applied to life test.  Apply voltage as Table for 1,000 h at 125$^{+2}_{0}$℃, relative humidity 50% max. Type / Applied voltage GB: AC312.5V (r.m.s.), except that once each hour the voltage is increased to AC1,000V (r.m.s.) for 0.1s. GC: AC425V (r.m.s.), except that once each hour the voltage is increased to AC1,000V (r.m.s.) for 0.1s.
		Capacitance Change	Within ±20%	
		D.F.	0.05 max.	
		I.R.	More than 3,000MΩ	
		Dielectric Strength	Pass the item No.4.	
18	Humidity Loading	Appearance	No marking defects.	Apply the rated voltage at 40±2℃ and relative humidity 90 to 95% for 500$^{+24}_{0}$ h. Remove and let sit for 24±2 h at room condition, then measure.
		Capacitance Change	Within ±15%	
		D.F.	0.05 max.	
		I.R.	More than 3,000MΩ	
		Dielectric Strength	Pass the item No.4.	

"Room condition" Temperature : 15 to 35℃, Relative humidity : 45 to 75%, Atmosphere pressure : 86 to 106kPa

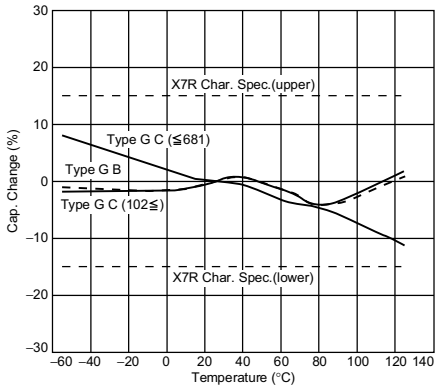
GHM Series Data

■ Capacitance-Temperature Characteristics

GHM1000/1500/2000 Series

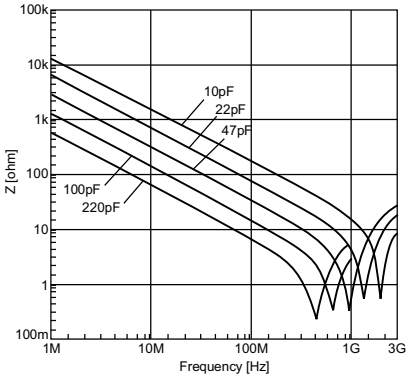


GHM3000 Series

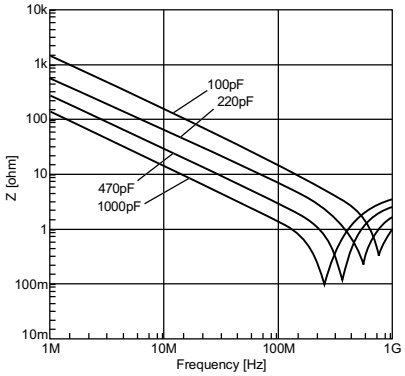


■ Impedance-Frequency Characteristics

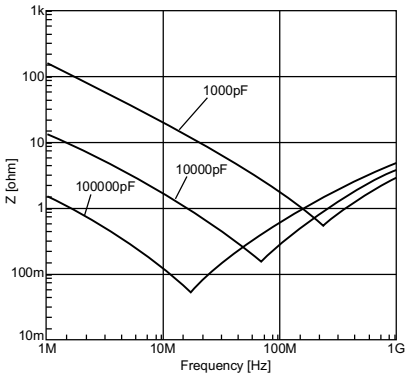
GHM1000 Series(SL)



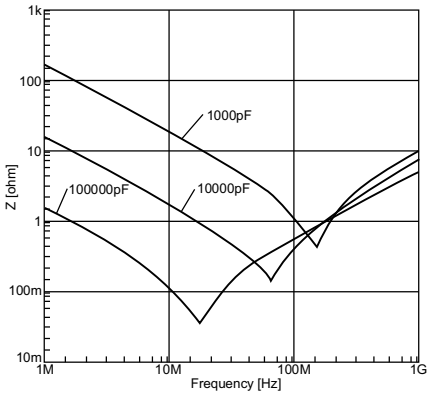
GHM1000 Series(R)



GHM1500 Series



GHM2000 Series



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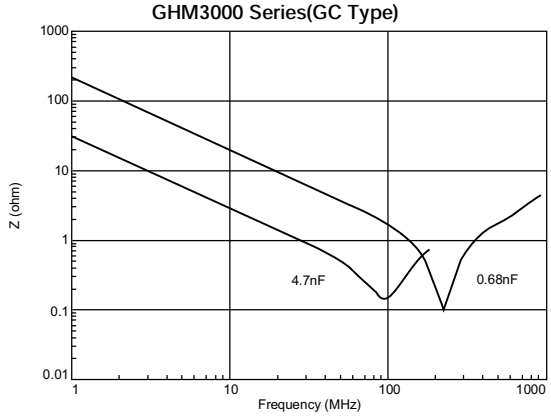
GHM Series Data

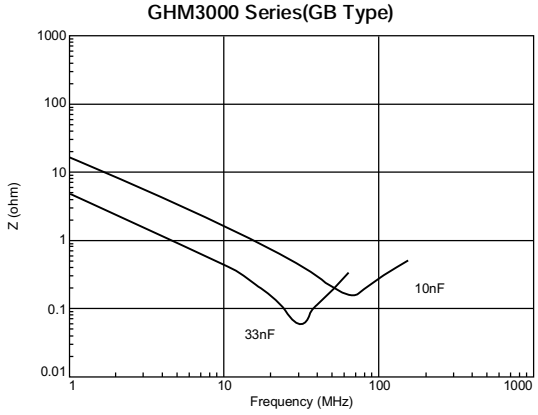
Continued from the preceding page.

■ Impedance-Frequency Characteristics

GHM3000 Series(GC Type)

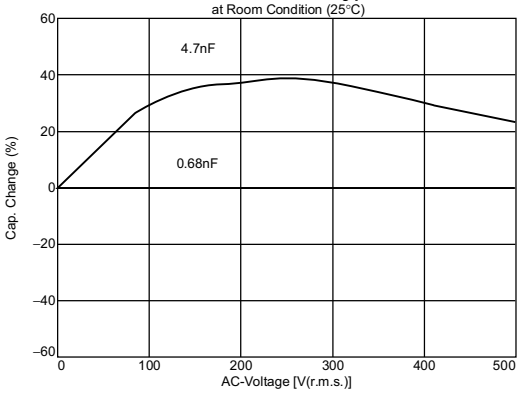


GHM3000 Series(GB Type)

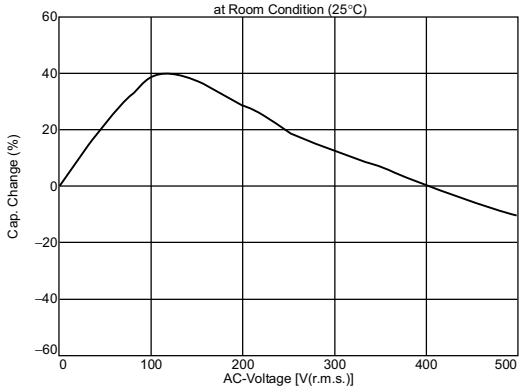


■ Capacitance-AC Voltage Characteristics

GHM3000 Series(GC Type)



GHM3000 Series(GB Type)



Taping is standard packaging method.

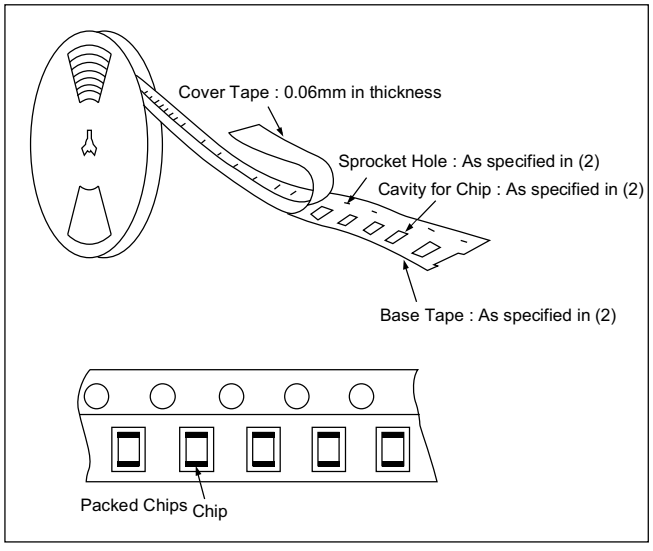
■ Minimum Quantity Guide

Part Number		Dimensions (mm)			Quantity (pcs.) ϕ180mm reel	
		L	W	T	Paper Tape	Plastic Tape
High-voltage	GHM1030	3.2	1.6	1.0	4,000	-
				1.25	-	3,000
	GHM1035	3.2	2.5	1.5	-	2,000
	GHM1038	4.5	2.0	2.0	-	2,000
	GHM1040	4.5	3.2	2.0	-	1,000
				2.5	-	500
	GHM1525	2.0	1.25	1.0	4,000	-
				1.25	-	3,000
	GHM1530	3.2	1.6	1.0	4,000	-
				1.25	-	3,000
				1.6	-	2,000
	GHM1535	3.2	2.5	1.5	-	2,000
				2.0	-	1,000
	GHM1540	4.5	3.2	1.5	-	1,000
				2.0	-	1,000
				2.5	-	500
				2.6	-	500
	GHM1545	5.7	5.0	2.0	-	1,000
				2.7	-	500
AC250V	GHM2143	5.7	2.8	2.0	-	1,000
	GHM2145	5.7	5.0	2.0	-	1,000
	GHM2243	5.7	2.8	2.0	-	1,000
Safty Std. Recognition	GHM3045	5.7	5.0	2.0	-	1,000
	GHM3145	5.7	5.0	2.0	-	1,000
				2.7	-	500

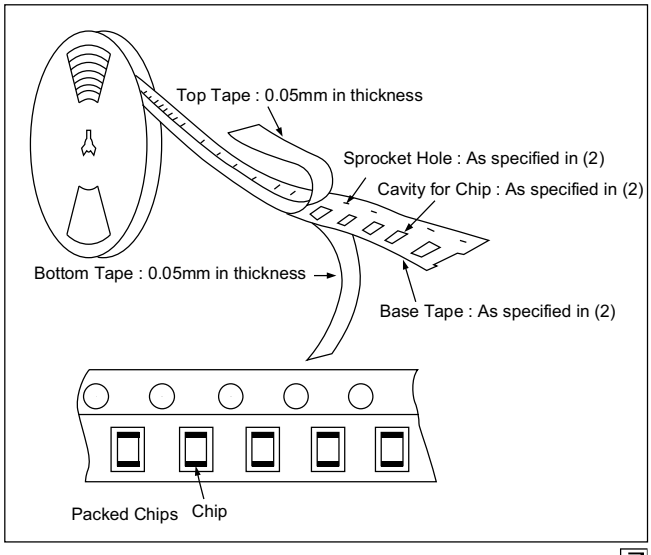
■ Tape Carrier Packaging

(1) Appearance of Taping

① Plastic Tape



② Paper Tape



Continued on the following page.

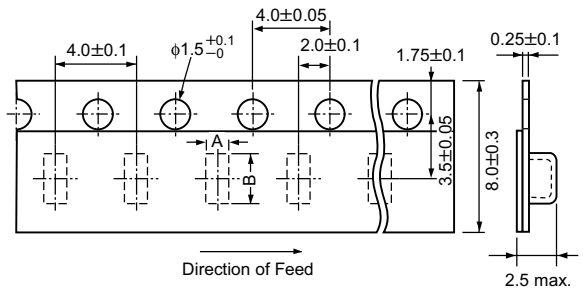
Package

Continued from the preceding page.

(2) Dimensions of Tape

① Plastic Tape

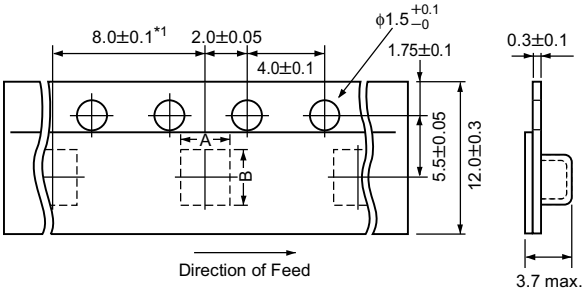
8mm width 4mm pitch Tape (T≧1.25 rank)



Part Number	A*	B*
GHMxx25	1.45	2.25
GHMxx30	2.0	3.6
GHMxx35	2.9	3.6

*Nominal Value

12mm width 8mm/4mm pitch Tape



Part Number	A*	B*
GHMxx38	2.5	5.1
GHMxx40	3.6	4.9
GHMxx43	3.2	6.1
GHMxx45	5.4	6.1

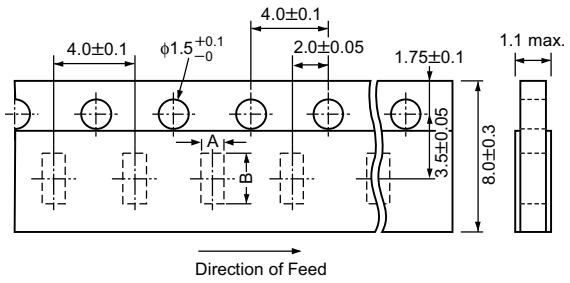
*1 4.0±0.1mm in case of GHM1038

*Nominal Value

(in mm)

② Paper Tape

8mm width 4mm pitch Tape (T=1.0 rank)

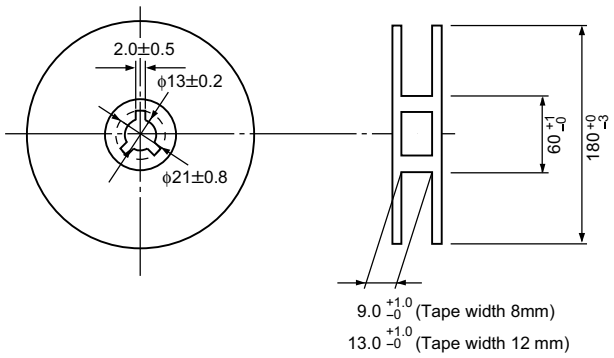


Part Number	A*	B*
GHMxx25	1.45	2.25
GHMxx30	2.0	3.6

*Nominal value

(in mm)

(3) Dimensions of Reel

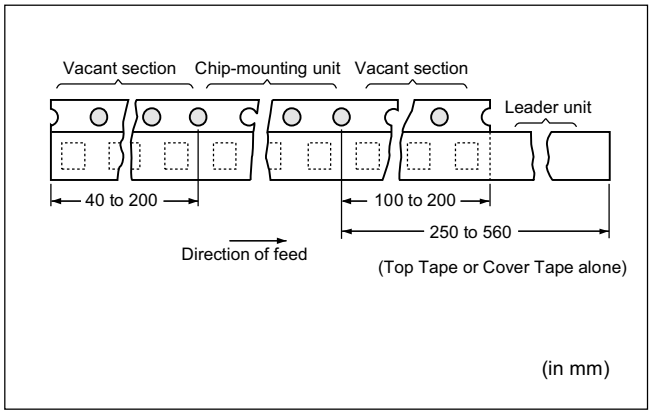


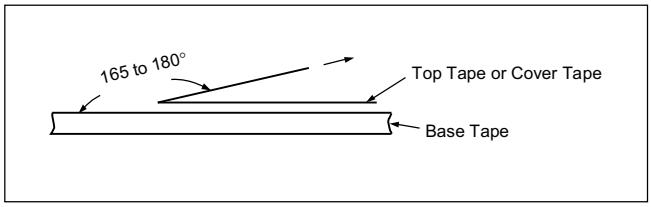
(in mm)

Package

(4) Taping Method

① Tapes for capacitors are wound clockwise. The sprocket holes are to the right as the tape is pulled toward the user.
② Part of the leader and part of the empty tape shall be attached to the end of the tape as follows.
③ The top tape or cover tape and base tape are not attached at the end of the tape for a minimum of 5 pitches.
④ Missing capacitors number within 0.1% of the number per reel or 1 pc, whichever is greater, and are not continuous.
⑤ The top tape or cover tape and bottom tape shall not protrude beyond the edges of the tape and shall not cover sprocket holes.
⑥ Cumulative tolerance of sprocket holes, 10 pitches : ±0.3mm.
⑦ Peeling off force : 0.1 to 0.7N in the direction shown on the right.





⚠ Caution

■ Storage and Operating Conditions

Do not use or store capacitorsin a corrosive atmosphere, especially where chloride gas, sulfide gas, acid, alkali, salt or the like are present and avoid exposure to moisture.
Before cleaning, bonding or molding this product,verify that these processes do not affect product quality by testing the performance of a cleaned, bonded or molded product in the intended equipment.
Store the capacitors where the temperature and relative humidity do not exceed 5 to 40 degrees centigrade and 20 to 70%. Use capacitors within 6 months.
Failure to follow the above cautions may result, worst case,in a short circuit and fuming when the product is used.

■ Handling

Vibration and impact
Do not expose a capacitor to excessive shock or vibration during use.
Failure to follow the above cautions may result, worst case,in a short circuit and fuming when the product is used.

■ Caution (Rating)

1. Operating Voltage

Be sure to use a capacitor only within its rated operating voltage range. When DC-rated capacitors are to be used in AC or ripple voltage circuits, be sure to maintain the Vp-p value of the applied voltage within the rated voltage range.

2. Operating Temperature and Self-generated Heat

Keep the surface temperature of a capacitor within the rated operating temperature range.
Be sure to take into account the heat produced by the capacitor itself. When a capacitor is used in a high-frequency circuit, pulse voltage circuit or the like, it may produce heat due to dielectric loss.
Keep such self-generated temperature below 20˚C in B(X7R) characteristic products.
Regarding R and SL characteristic products, the applied voltage should be limited in high frequency circuit.
Please contact our sales representatives or engineers for more details.

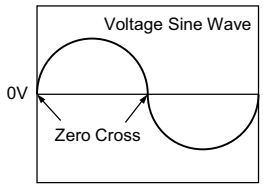
3. Test Condition for AC Withstanding Voltage

(1) Test Equipment

Test equipment for AC withstanding voltage shall be used with the performance of the wave similar to 50/60 Hz sine wave.
If the distorted sine wave or over load exceeding the specified voltage value is applied, the defective may be caused.

(2) Voltage Applied Method

When the withstanding voltage is applied, capacitor's lead or terminal shall be firmly connected to the out-put of the withstanding voltage test equipment, and then the voltage shall be raised from near zero to the test voltage.
If the test voltage without the raise from near zero voltage would be applied directly to capacitor, test voltage should be applied with the *zero cross. At the end of the test time, the test voltage shall be reduced to near zero, and then capacitor's lead or terminal shall be taken off the out-put of the withstanding voltage test equipment.
If the test voltage without the raise from near zero voltage would be applied directly to capacitor, the surge voltage may arise, and therefore, the defective may be caused.
*ZERO CROSS is the point where voltage sine wave pass 0V.
-See the right figure-



Failure to follow the above cautions may result, worst case, in a short circuit and fuming when the product is used.

■ Caution (Soldering and Mounting)

1. Vibration and Impact

Do not expose a capacitor to excessive shock or vibration during use.

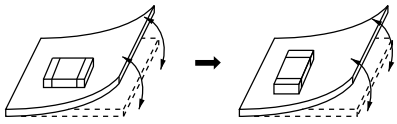
2. Circuit Board Material

Please contact our sales representatives or engineers in case that GHM products (size 4.5×3.2mm and over) are to be mounted upon a metal-board or metal-frame. Soldering heat causes the expansion and shrinkage of a board or frame. which may result in chip-cracking.

3. Land Layout for Cropping PC Board

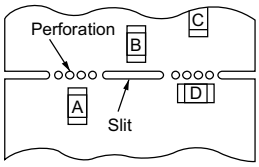
Choose a mounting position that minimizes the stress imposed on the chip during flexing or bending of the board.

[Component Direction]



Locate chip horizontal to the direction in which stress acts.

[Chip Mounting Close to Board Separation Point]



Chip arrangement
Worst A>C>B=D Best

Continued on the following page.

⚠ Caution

Continued from the preceding page.

4. Soldering (Prevention of the thermal shock)

If a chip component is heated or cooled abruptly during soldering, it may crack due to the thermal shock. To prevent this, adequate soldering condition should be taken following our recommendation below.

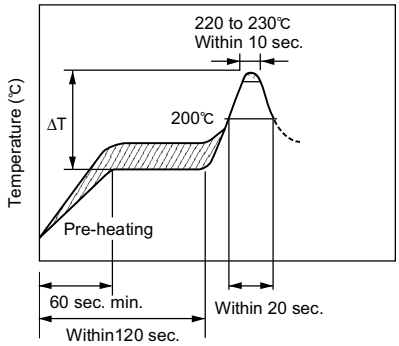
Carefully perform pre-heating so that temperature difference (ΔT) between the solder and component surface should be in the following range. When components are immersed in solvent after mounting, pay special attention to maintain the temperature difference within 100˚C.

Soldering Method \ Chip Size	3.2×1.6mm and under	3.2×2.5mm and over
Reflow Method or Soldering Iron Method	ΔT≦190˚C	ΔT≦130˚C
Flow Method or Dip Soldering Method	ΔT≦150˚C	——

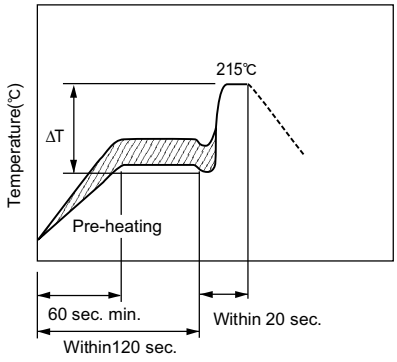
When soldering chips with a soldering iron, it should be performed in following conditions.

Item	Conditions	
Chip Size	≦2.0×1.25mm	3.2×1.6mm
Temperature of Iron-tip	300˚C max.	270˚C max.
Soldering Iron Wattage	20W max.	
Diameter of Iron-tip	ϕ 3.0mm max.	
Soldering Time	3 sec. max.	
Caution	Do not allow the iron-tip to directly touch the ceramic element.	

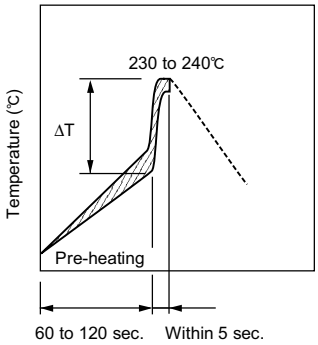
Infrared Reflow Soldering Conditions (Example)



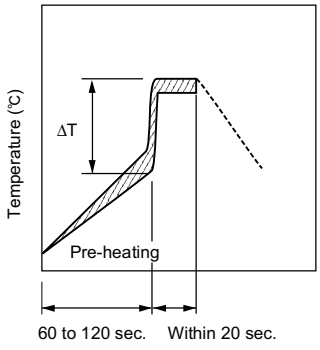
Vapor Reflow Soldering (VPS) Conditions (Example)



Flow Soldering Conditions (Example)



Dip Soldering/Soldering Iron Conditions (Example)



5. Soldering Method

GHM products whose sizes are 3.2×1.6mm and under for flow and reflow soldering, and other sizes for reflow soldering.

Be sure to contact our sales representatives or engineers in case that GHM products (size 3.2×2.5mm and over) are to be mounted with flow soldering. It may crack due to the thermal shock.

Failure to follow the above cautions may result, worst case, in a short circuit and fuming when the product is used.

1. Mounting of Chips

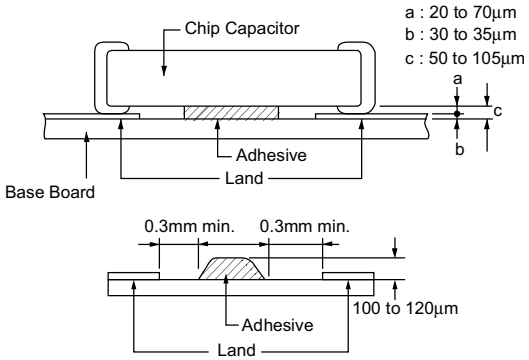
● Mechanical shock of the chip placer

When the positioning claws and pick up nozzle are worn, the load is applied to the chip while positioning is concentrated to one position, thus causing cracks, breakage, faulty positioning accuracy, etc.

Careful checking and maintenance are necessary to prevent unexpected trouble.

An excessively low bottom dead point of the suction nozzle imposes great force on the chip during mounting, causing cracked chips. Please set the suction nozzle's bottom dead point on the upper surface of the board.

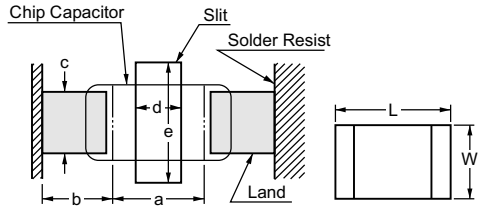
Termination Thickness of Chip Capacitor and Desirable Thickness of Adhesives Applied



2. Construction of Board Pattern

After installing chips, if solder is excessively applied to the circuit board, mechanical stress will cause destruction resistance characteristics to lower. To pre-vent this, be extremely careful in determining shape and dimension before designing the circuit board diagram.

Construction and Dimensions of Pattern (Example)



Preparing slit help flux cleaning and resin coating on the back of the capacitor.

Flow Soldering

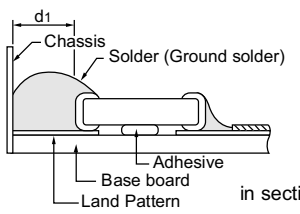
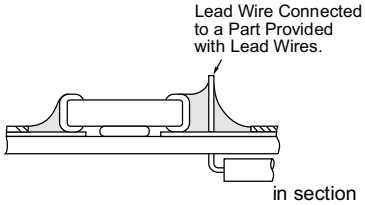
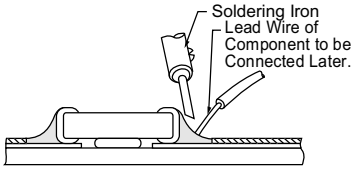
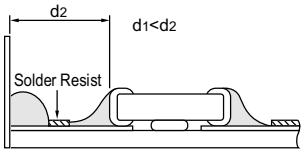
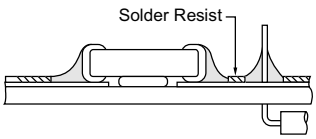
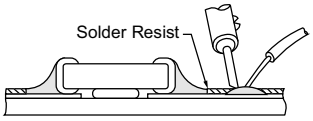
L×W	a	b	c
2.0×1.25	1.0-1.2	0.9-1.0	0.8-1.1
3.2×1.6	2.2-2.6	1.0-1.1	1.0-1.4

Reflow Soldering

L×W	a	b	c	d	e
2.0×1.25	1.0-1.2	0.9-1.0	0.8-1.1	-	-
3.2×1.6	2.2-2.4	0.8-0.9	1.0-1.4	1.0-2.0	3.2-3.7
3.2×2.5	2.0-2.4	1.0-1.2	1.8-2.3	1.0-2.0	4.1-4.6
4.5×2.0	2.8-3.4	1.2-1.4	1.4-1.8	1.0-2.8	3.6-4.1
4.5×3.2	2.8-3.4	1.2-1.4	2.3-3.0	1.0-2.8	4.8-5.3
5.7×2.8	4.0-4.6	1.4-1.6	2.1-2.6	1.0-4.0	4.4-4.9
5.7×5.0	4.0-4.6	1.4-1.6	3.5-4.8	1.0-4.0	6.6-7.1

(in mm)

Land Layout to Prevent Excessive Solder

	Mounting Close to a Chassis	Mounting with Leaded Components	Mounting Leaded Components Later
Examples of Arrangements to be Avoided	 in section	 in section	 in section
Examples of Improvements by the Land Division	 in section	 in section	 in section

Continued on the following page.

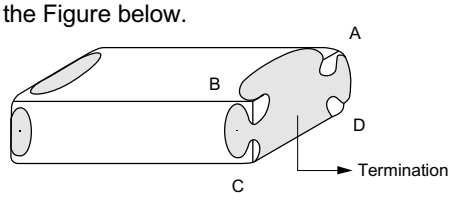
Notice

Continued from the preceding page.

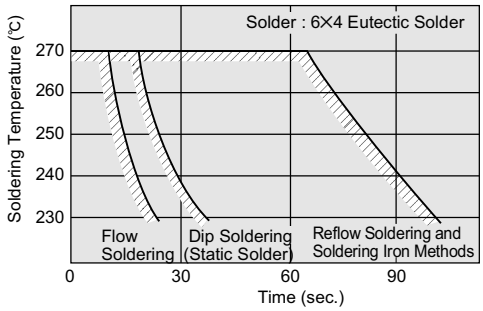
3. Soldering

(Care for minimizing loss of the terminations.)
Limit of losing effective area of the terminations and conditions needed for soldering.

Depending on the conditions of the soldering temperature and/or immersion (melting time), effective areas may be lost in some part of the terminations.
To prevent this, be careful in soldering so that any possible loss of the effective area on the terminations will securely remain minimum 25% on all edge length A-B-C-D of part with A, B, C, D, shown in the Figure below.



Soldering Allowance Time



In case of repeated soldering, the accumulated soldering time must be within the range shown above.

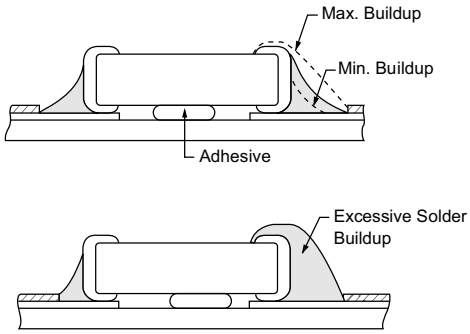
(2) Flux and Solder

- Use rosin-type flux and do not use a highly acidic flux (any containing a minimum of 0.2wt% chlorine).
- Please use 6Z4 eutectic solder, or 5Z5 solder. (Do not use solder with silver.)

(3) Solder Buildup

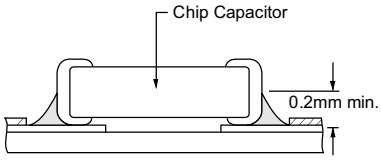
① Flow soldering and iron soldering
Use as little solder as possible, and confirm that the solder is securely placed.

[Solder Buildup by Flow Method and Soldering Iron Method]



② Reflow soldering
When soldering, confirm that the solder is placed over 0.2mm of the surface of the terminations.

[Solder Buildup by Reflow Method]



4. Cleaning

To perform ultrasonic cleaning, observe the following conditions on the right.

Rinse bath capacity : Output of 20 watts per liter or less.
Rinsing time : 5 minutes maximum.

5. Resin Coating

- When selecting resin materials, select those with low contraction and low moisture absorption coefficient (generally epoxy resin is used).
- Buffer coat can decrease the influence of the resin shrinking (generally silicone resin).

■ISO9000 CERTIFICATIONS

Manufacturing plants of these products in this catalog have obtained the ISO9001 or ISO9002 certificate.

Plant	Certified Date	Organization	Registration NO.
Fukui Murata Manufacturing Co.,Ltd.	Mar. 31, '95	RCJ★ ISO9001	RCJ-85M-01C
Izumo Murata Manufacturing Co.,Ltd.	May. 11, '95		RCJ-93M-05A
Murata Electronics Singapore (Pte.) Ltd.	Aug. 13, '92	SISIR★★ ISO9002	SG MES 91M001A
Murata Manufacturing (UK) Ltd.	Nov. 18, '92	BSI★★★ ISO9002	FM 22169
Murata Amazonia Industria Comercio Ltda.	Sep. '93	RCJ★ ISO9002	RCJ-(B)-93M-01
Murata Electronics North America State College Plant	Jun. '94	UL★★★★ ISO9002	A1734

★ RCJ : Reliability Center for Electronic Components of Japan
★★ SISIR : Singapore Institute of Standards and Industrial Research
★★★ BSI : British Standards Institution
★★★★ UL : Underwriters Laboratories Inc.

⚠Note:

1. Export Control
   〈For customers outside Japan〉
   Murata products should not be used or sold for use in the development, production, stockpiling or utilization of any conventional weapons or mass-destructive weapons (nuclear weapons, chemical or biological weapons, or missiles), or any other weapons.
   〈For customers in Japan〉
   For products which are controlled items subject to the “Foreign Exchange and Foreign Trade Law” of Japan, the export license specified by the law is required for export.
2. Please contact our sales representatives or product engineers before using our products listed in this catalog for the applications listed below which require especially high reliability for the prevention of defects which might directly cause damage to the third party's life, body or property, or when intending to use one of our products for other applications than specified in this catalog.
   ① Aircraft equipment
   ② Aerospace equipment
   ③ Undersea equipment
   ④ Power plant equipment
   ⑤ Medical equipment
   ⑥ Transportation equipment (vehicles, trains, ships, etc.)
   ⑦ Traffic signal equipment
   ⑧ Disaster prevention / crime prevention equipment
   ⑨ Data-processing equipment
   ⑩ Application of similar complexity and/or reliability requirements to the applications listed in the above
3. Product specifications in this catalog are as of July 2000. They are subject to change or our products in it may be discontinued without advance notice. Please check with our sales representatives or product engineers before your ordering. If there are any questions, please contact our sales representatives or product engineers.
4. The parts numbers and specifications listed in this catalog are for information only. You are requested to approve our product specification or to transact the approval sheet for product specification, before your ordering.
5. Please note that unless otherwise specified, we shall assume no responsibility whatsoever for any conflict or dispute that may occur in connection with the effect of our and/or third party's intellectual property rights and other related rights in consideration of your using our products and/or information described or contained in our catalogs. In this connection, no representation shall be made to the effect that any third parties are authorized to use the rights mentioned above under licenses without our consent.
6. None of ozone depleting substances (ODS) under the Montreal Protocol is used in manufacturing process of us.

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